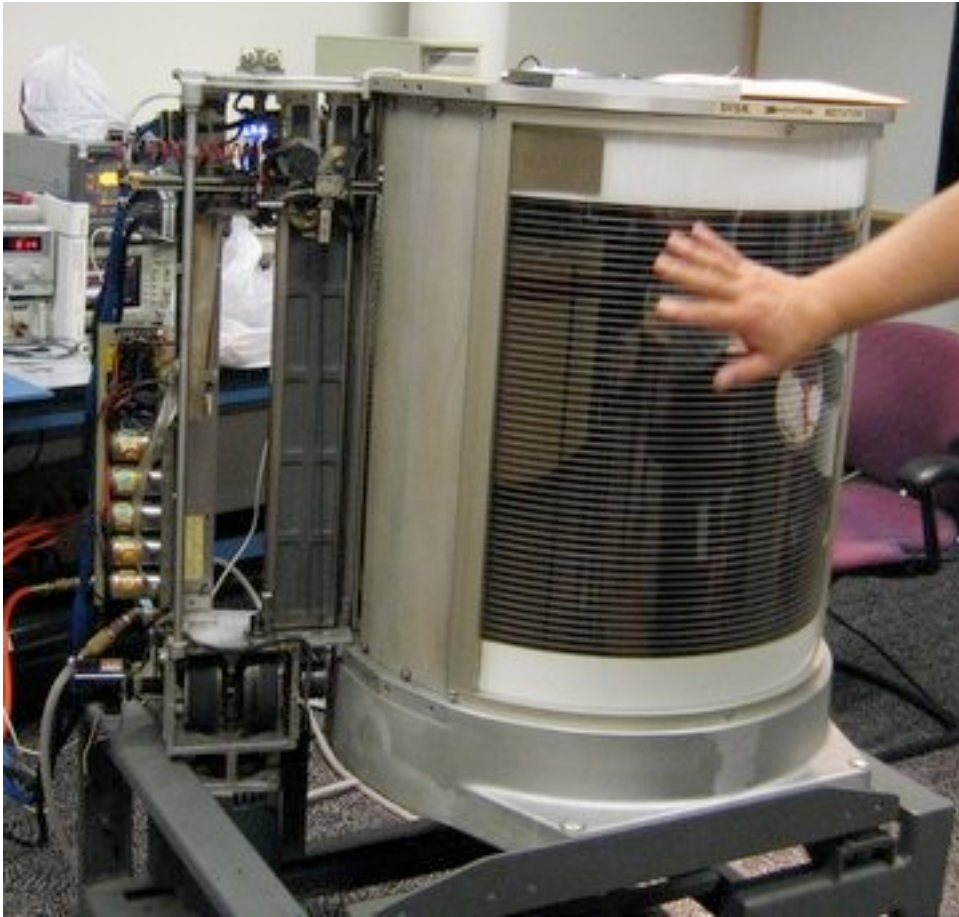


# magnetic information storage



IBM 350 RAMAC, the first hard disk  
it stored about 4.4Mb  
[wikipedia.org](https://en.wikipedia.org/wiki/RAMAC) - "RAMAC"

# what do I mean by magnetic recording?

---

# what do I mean by magnetic recording?

---



# what do I mean by magnetic recording?

---

hard disks.

mostly hard disks.





# why do we use hard disks?

---

what is their role in a computer?

benefits?

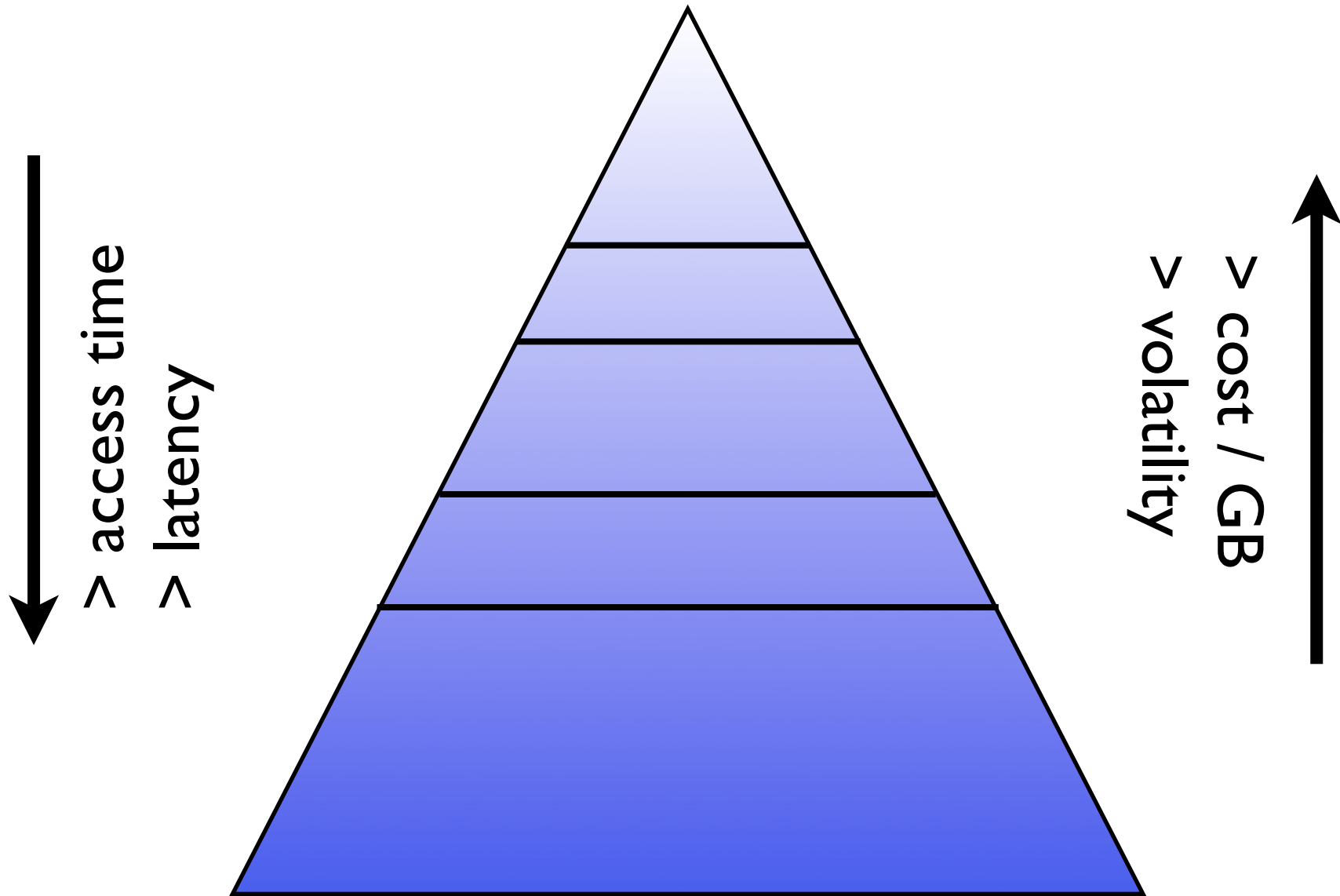
disadvantages?

and the real reason .. \$\$\$



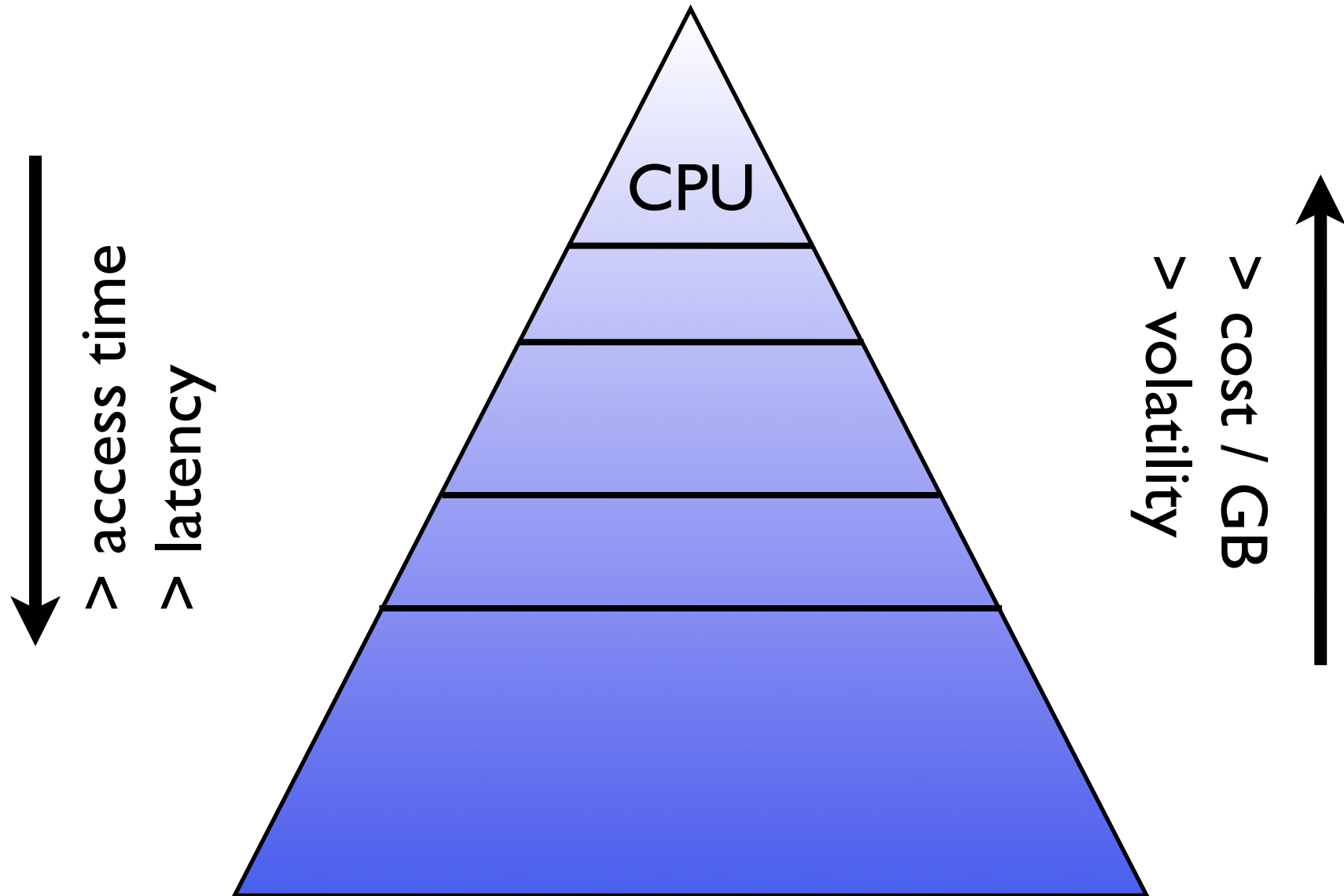
# basic PC architecture

---



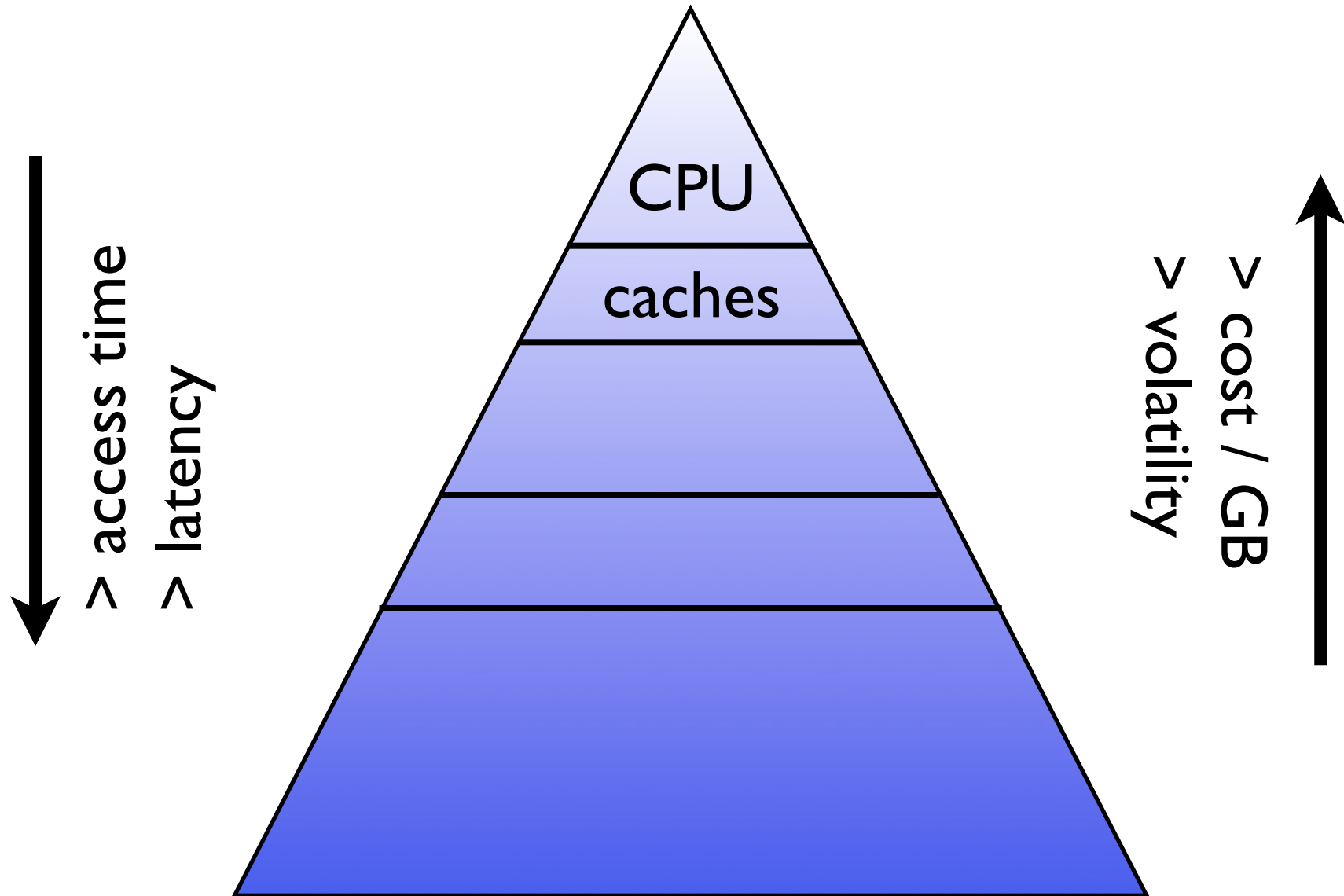
# basic PC architecture

---



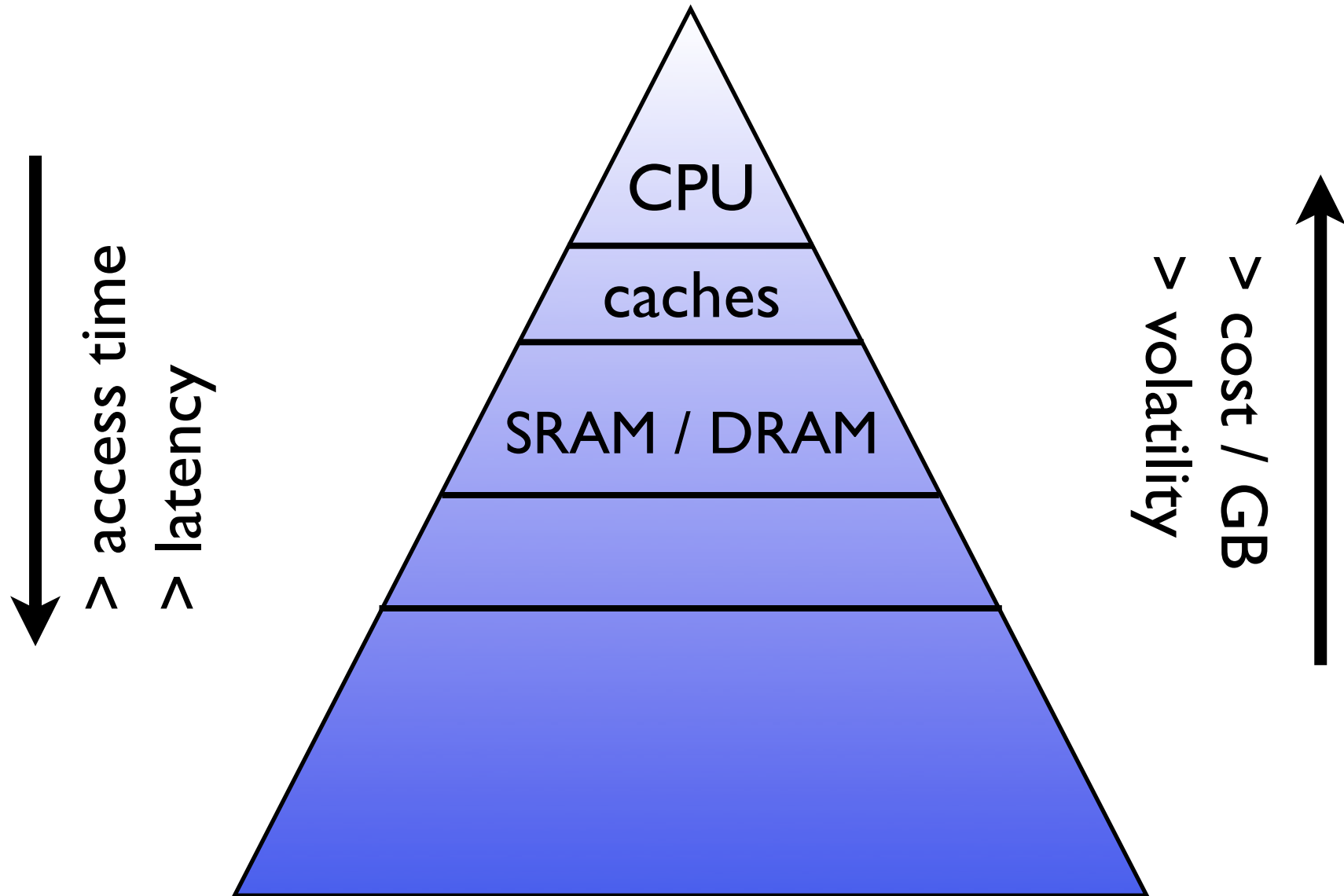
# basic PC architecture

---



# basic PC architecture

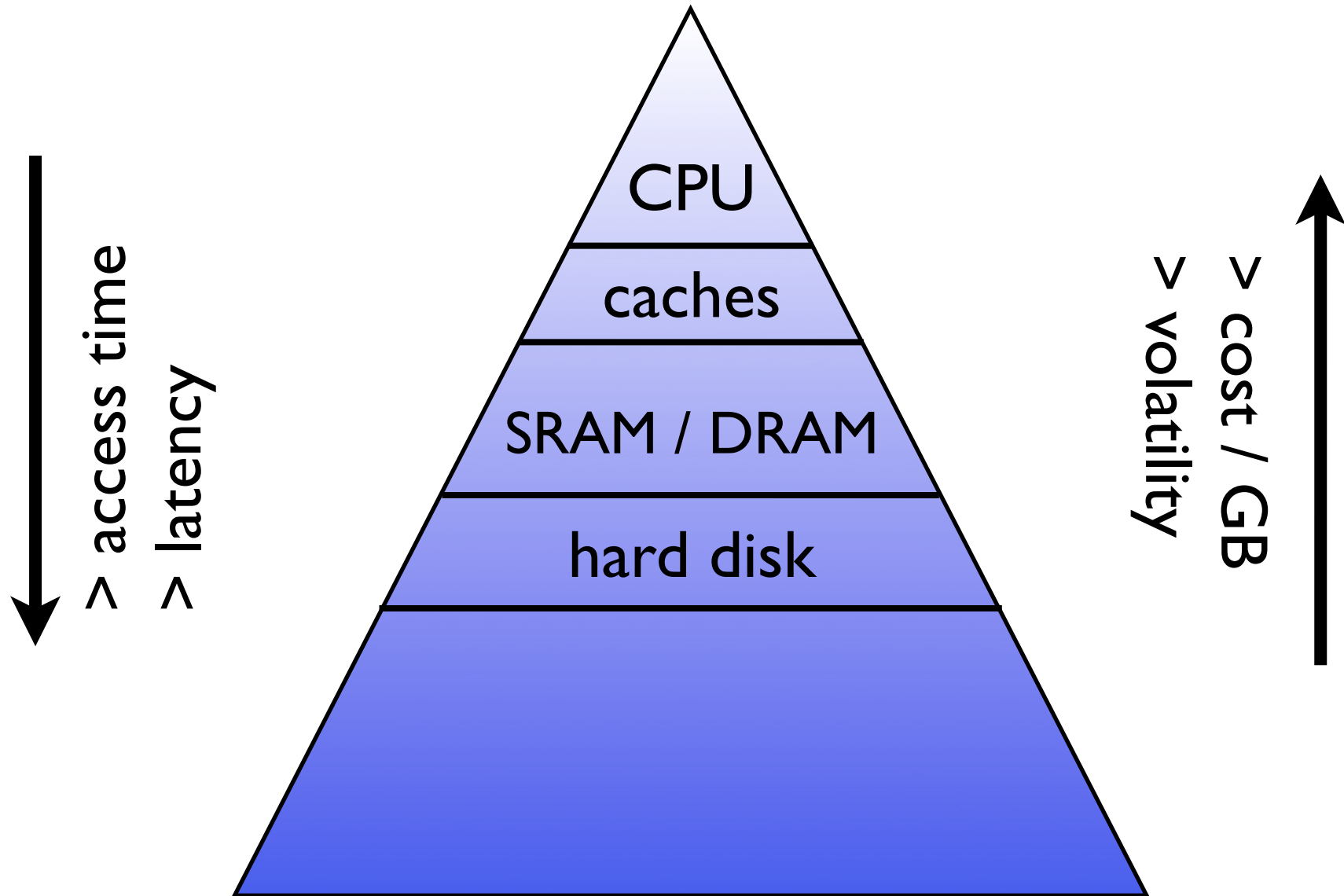
---





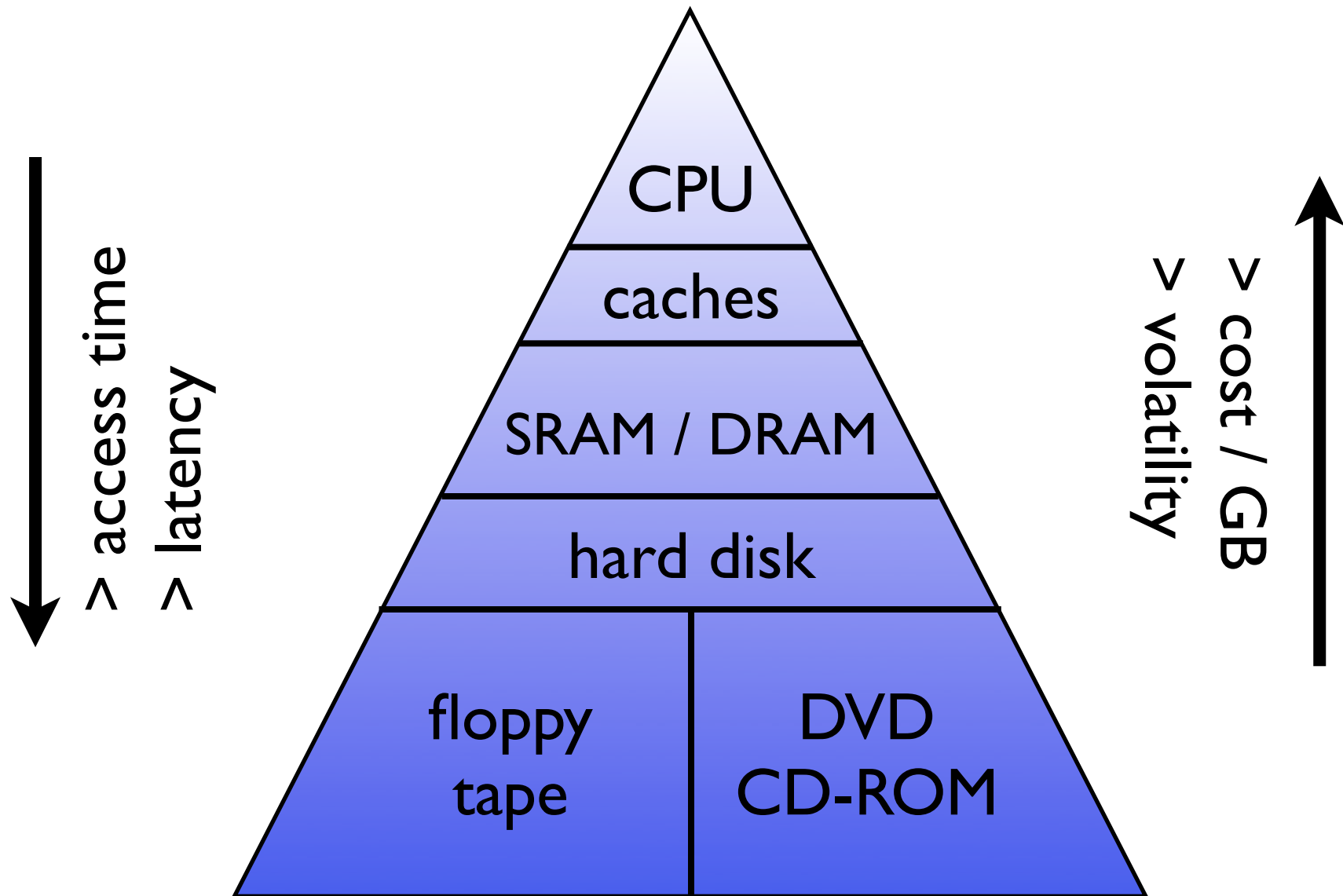
# basic PC architecture

---



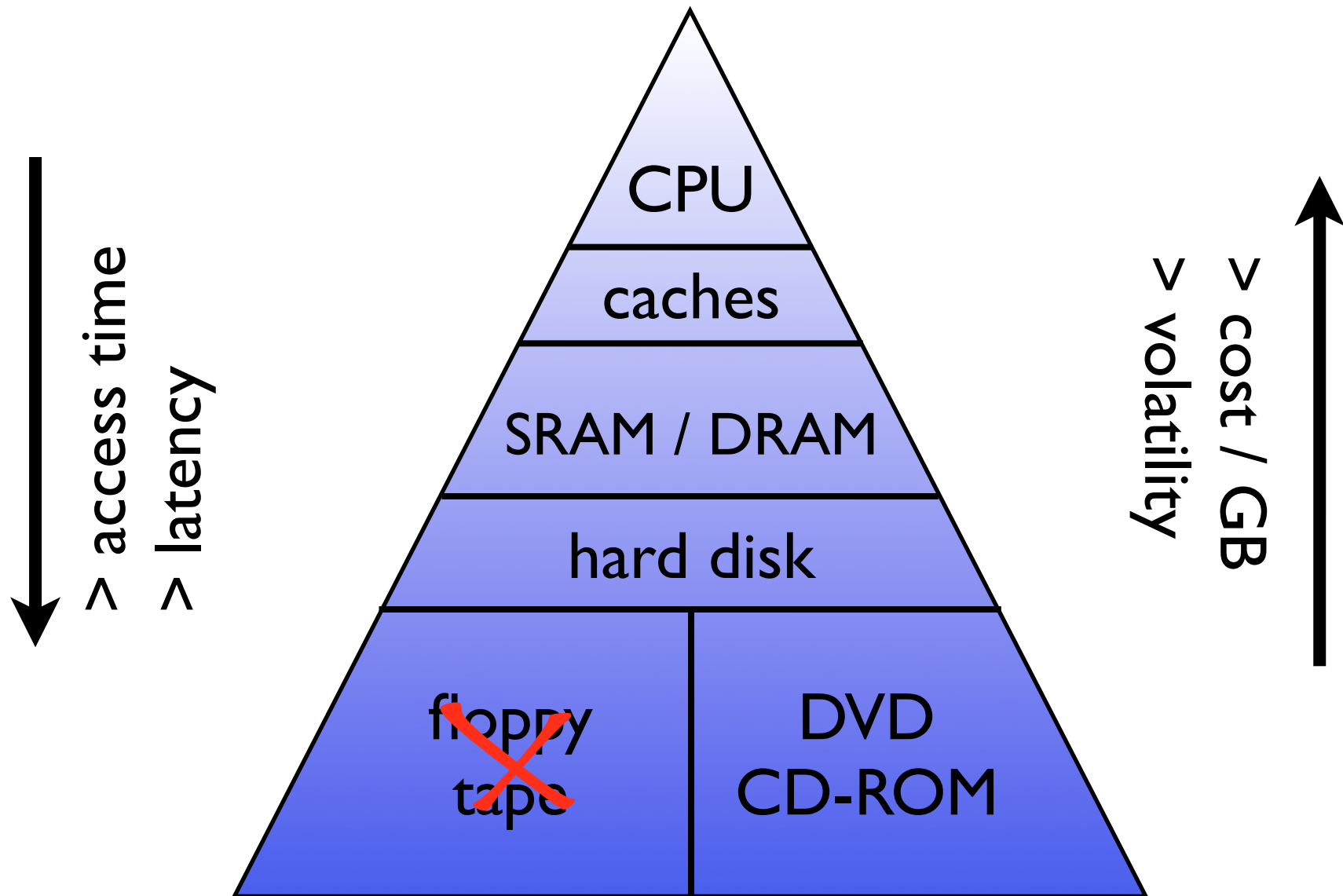
# basic PC architecture

---



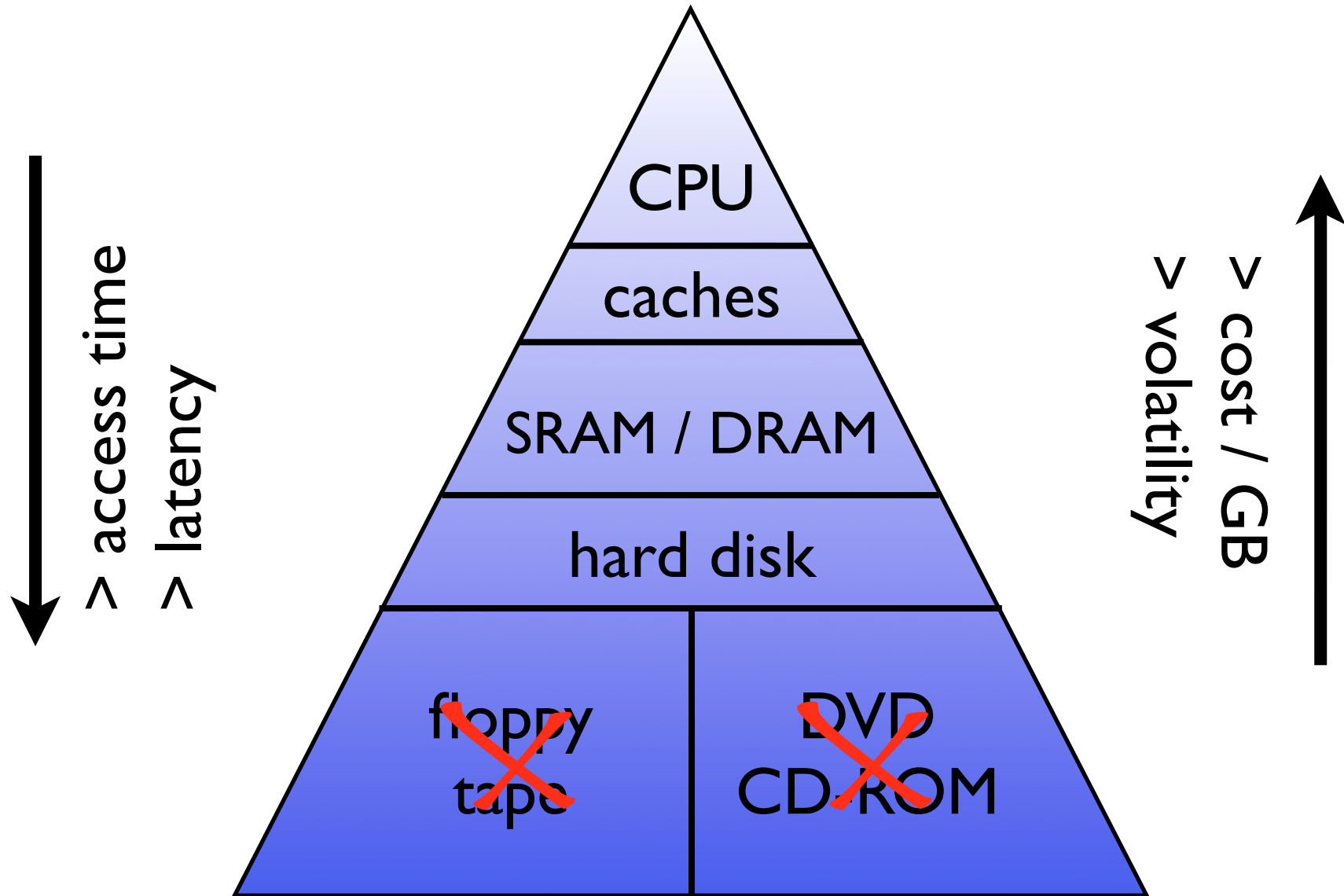
# basic PC architecture

---



# basic PC architecture

---



# terminology

---

## RAM

random access memory

## ROM

read-only memory

## access time & latency?

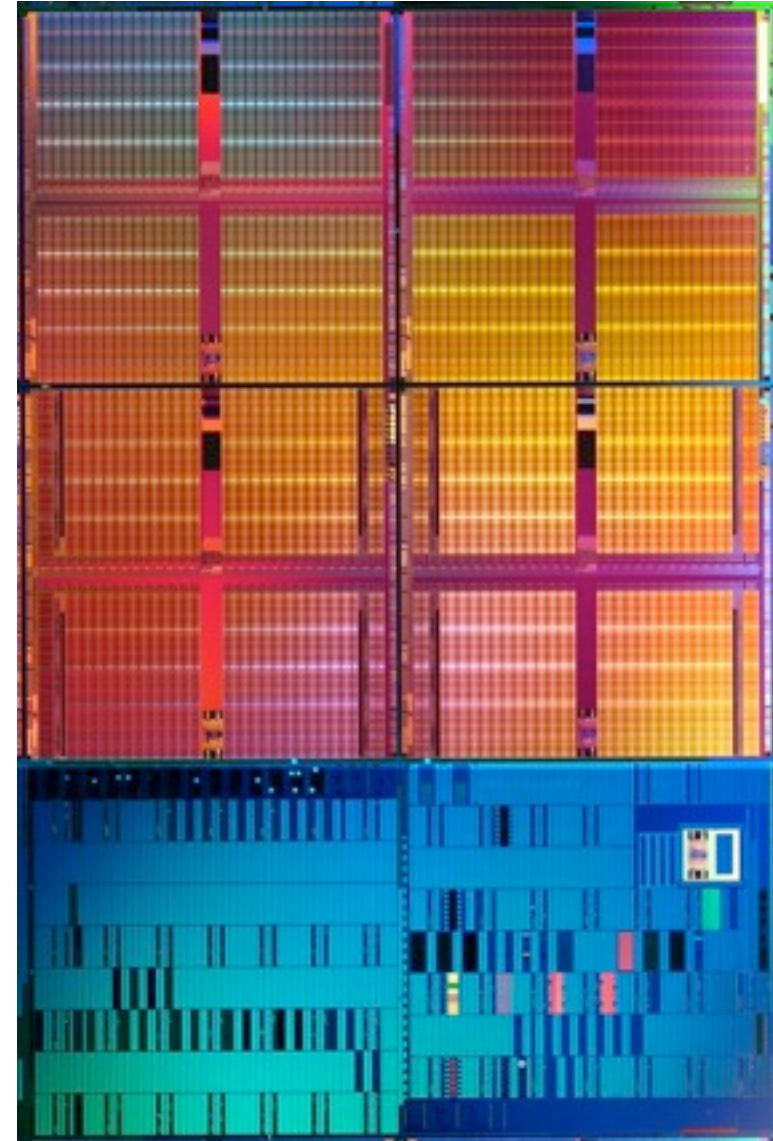
time between request for info & info returned

## \$ / GB

primary figure of merit.  
most other things can be worked around

## nonvolatility?

retains data without power



45nm SRAM die intel.com



# every bit has a role

---

## cache - *reduce latency to main memory*

*small* memories close to CPU  
even faster than main memory  
temp storage of frequently accessed items

## SRAM / DRAM - *main memory*

blazingly fast  
relatively large  
volatile!!

## HDD - *mass storage*

higher latency  
enormous capacity  
nonvolatile

## removable

portability  
backup  
large ROM

EDSAC / wikipedia.org



*future paradigm shifts? distributed net storage?*

---

# the need for hard disks (tech)

---

## volatility of semiconductor memories!

some sort of nonvolatile storage necessary  
why not just battery backup of SRAM?

## cost per GB

SRAM/DRAM are too expensive  
Flash is too expensive  
cache RAM is more expensive

## size & throughput

higher latency, but bandwidth is huge  
enormous sizes

## endurance

essentially unlimited cycling  
radiation hard

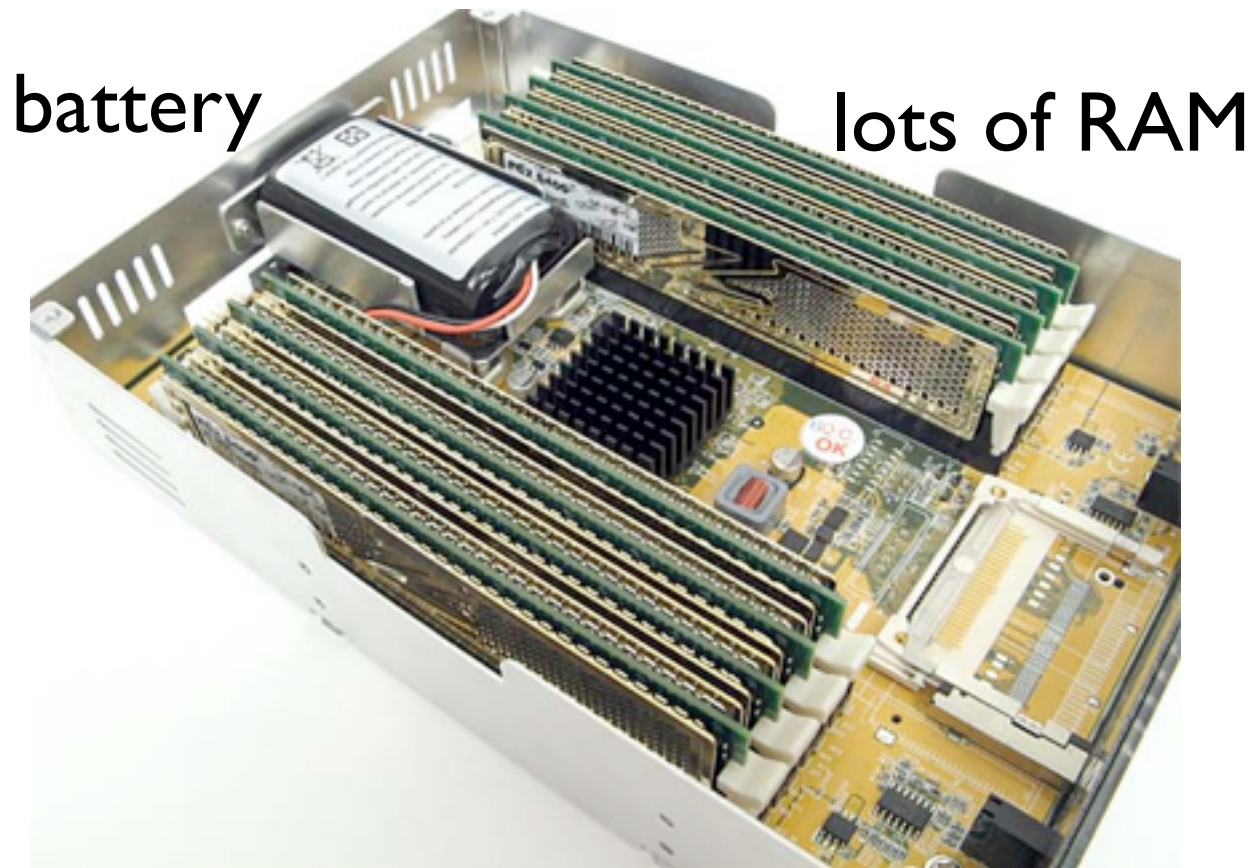
punched cards are nonvolatile



Back in the day, disks were expensive.

---

Sometimes, we would trick the system into using RAM as a disk to avoid swapping floppies.



now RAM disks make a comeback ...

---

# the need for mass storage (human)

---

## sound

several MB per minute / lossy  
tens of MB per minute / “lossless”

## pictures

several MB per image

## video

~ 1 MB per sec  
several GB per movie  
*with* lossy compression!

## data mining

enormous sizes



apple.com



# how do hard disks work, more or less?

---



wikipedia.org - "Hard\_Disk"

spinning ( $\sim 10^4$  rpm) part holds data.  
sliding part reads and writes data.

---



# hard disk drives

---

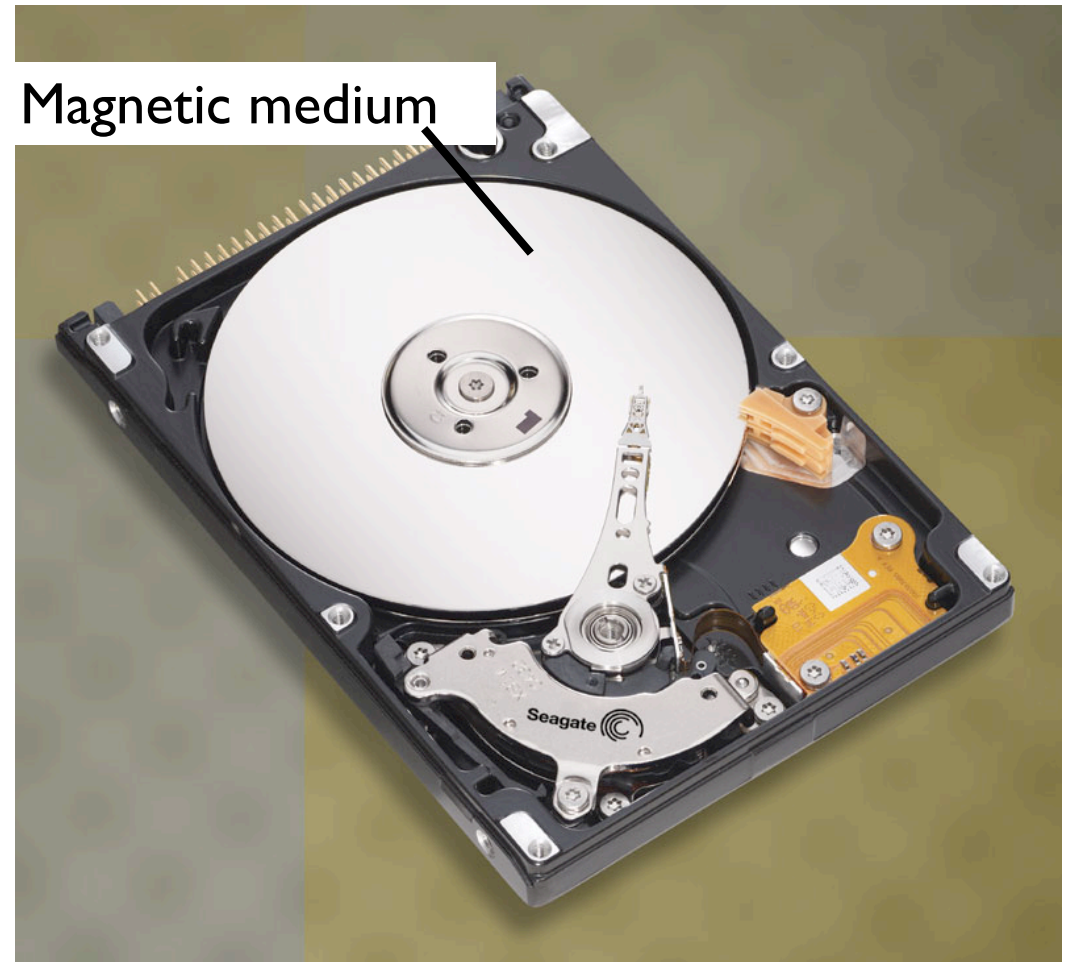


160 Gbit 2.5" perpendicular drive for laptops

images from M. Coey

# hard disk drives

---

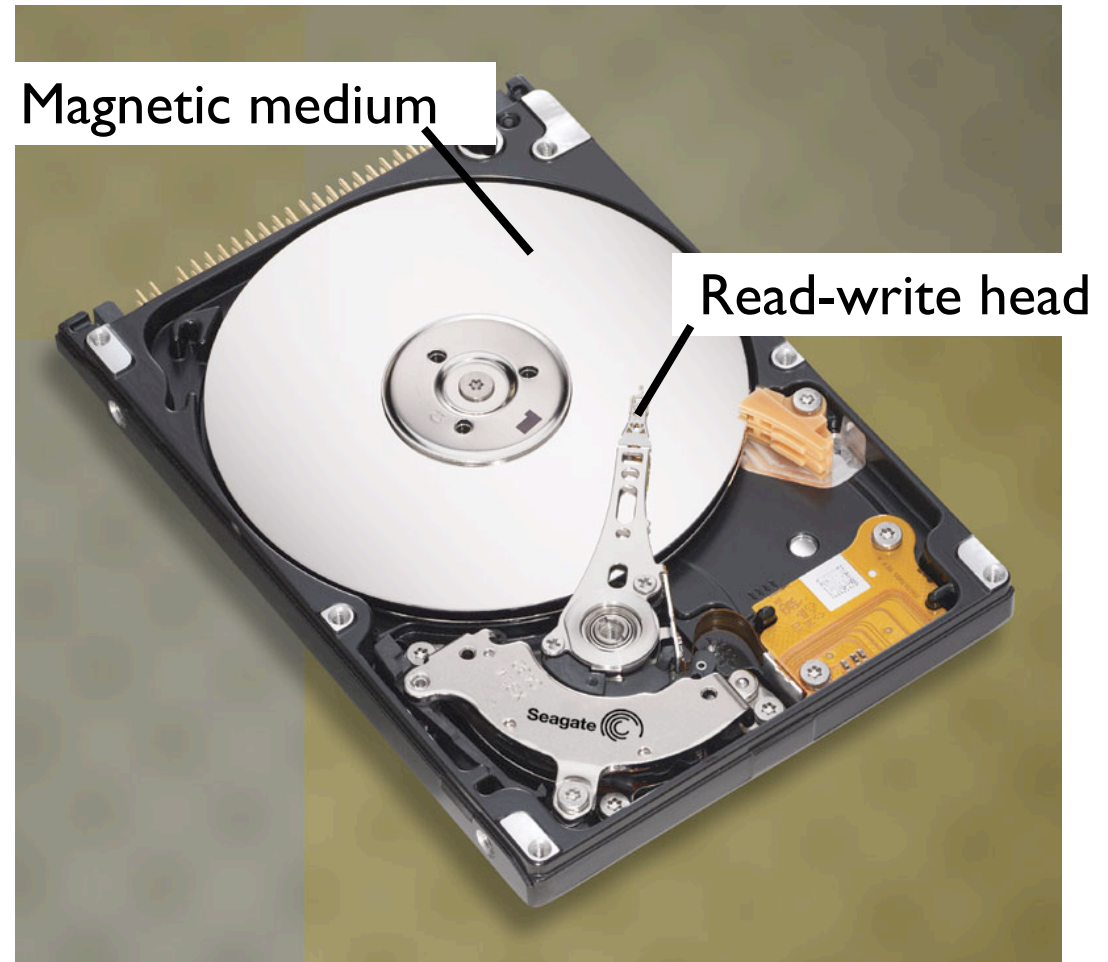


160 Gbit 2.5" perpendicular drive for laptops

images from M. Coey

# hard disk drives

---

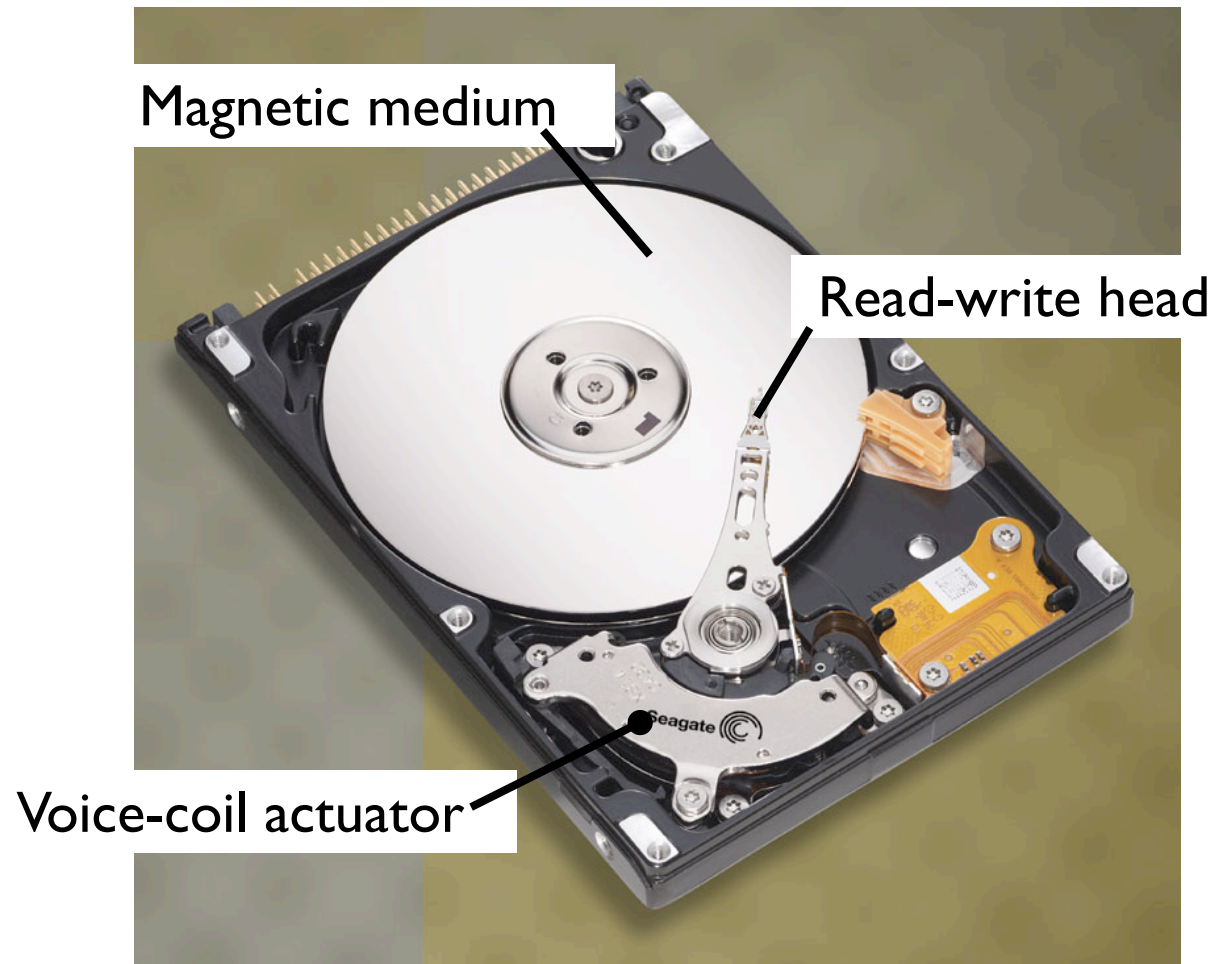


160 Gbit 2.5" perpendicular drive for laptops

images from M. Coey

# hard disk drives

---

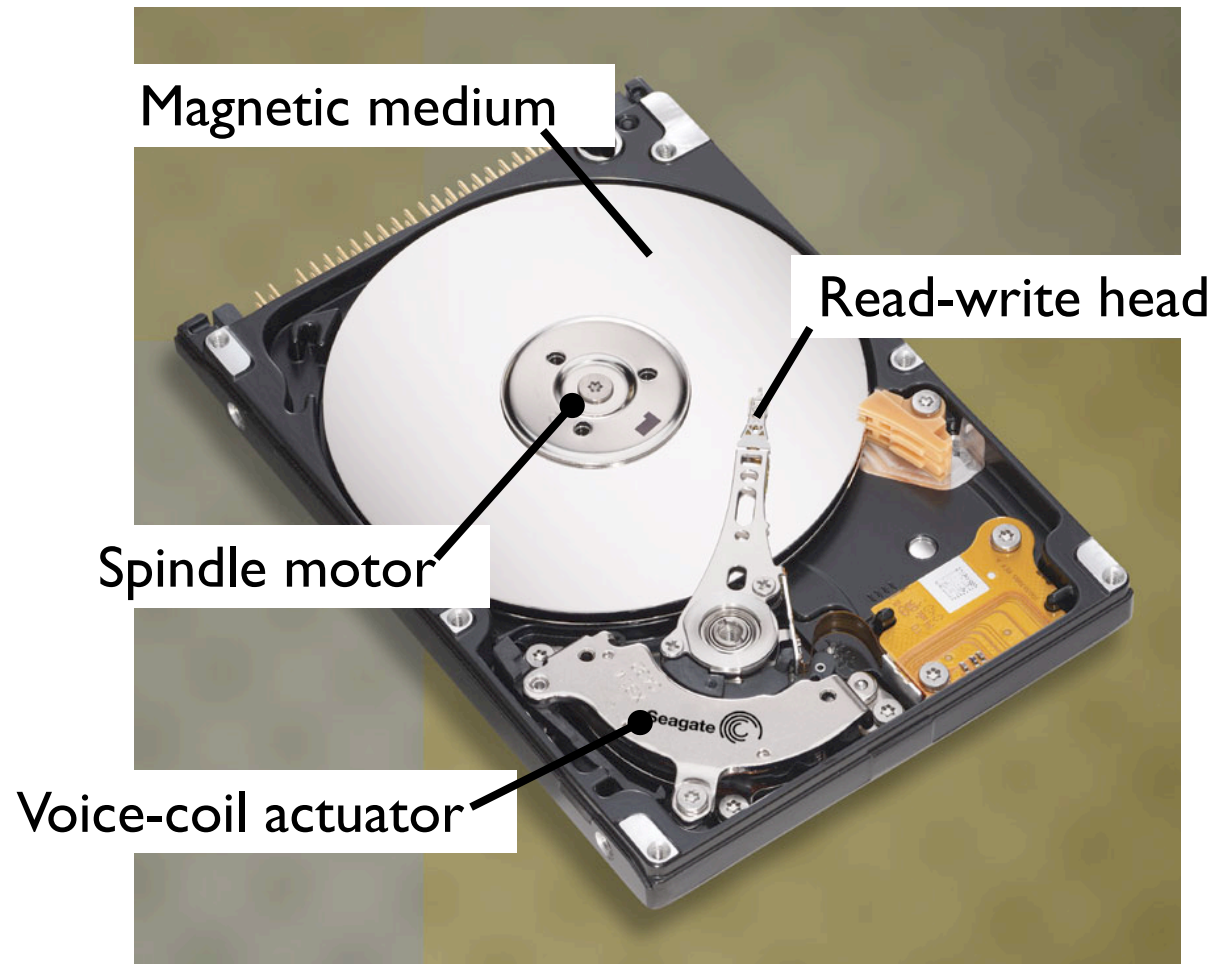


160 Gbit 2.5" perpendicular drive for laptops

images from M. Coey

# hard disk drives

---

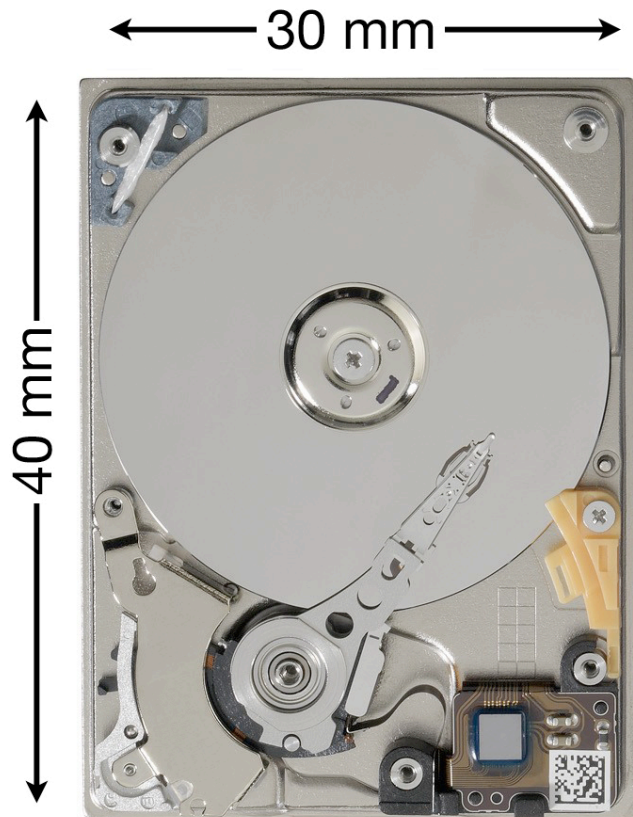


160 Gbit 2.5" perpendicular drive for laptops

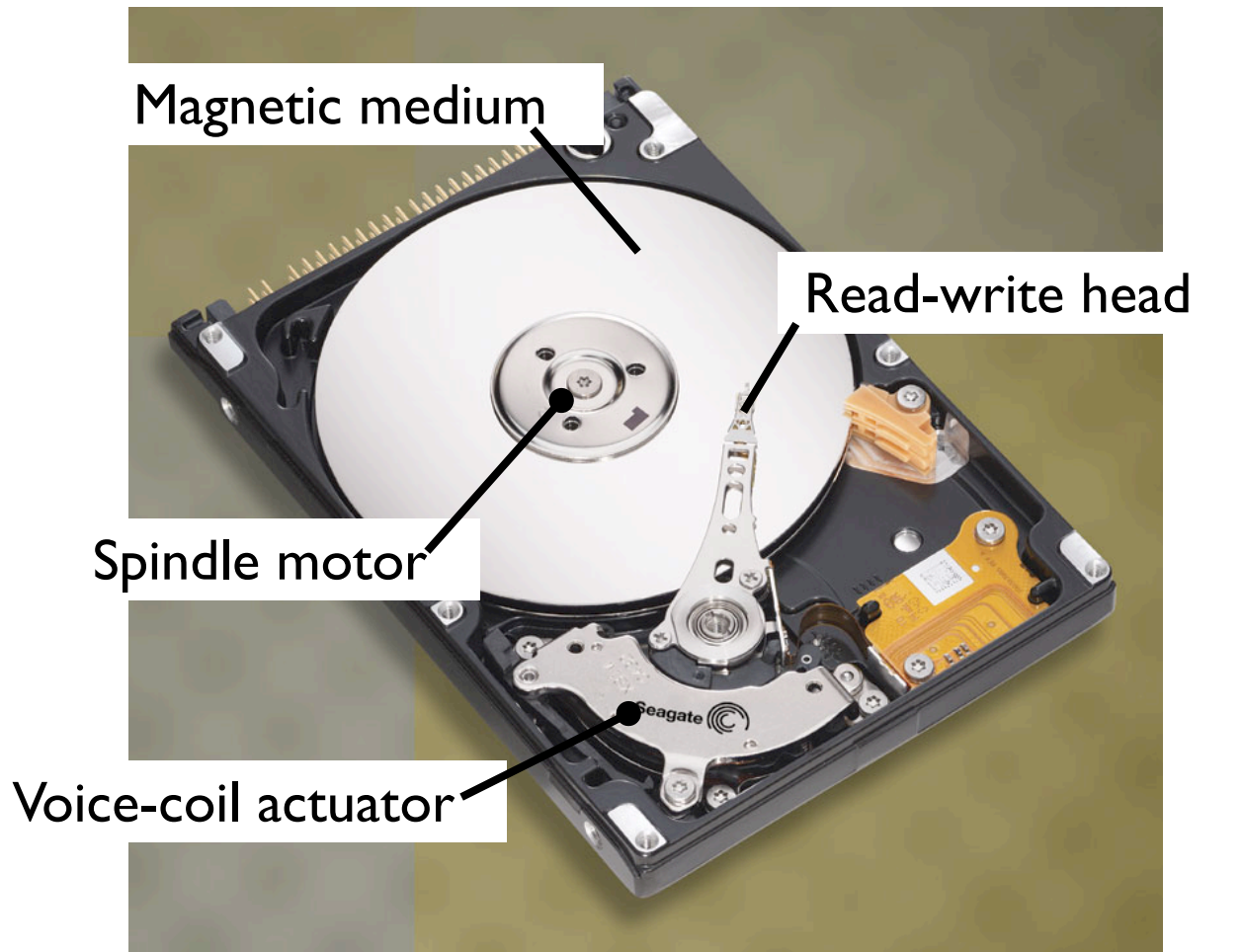
images from M. Coey



# hard disk drives



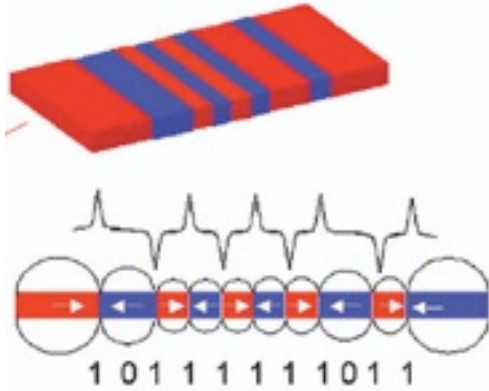
8 Gbit 1" drive for cameras



160 Gbit 2.5" perpendicular drive for laptops

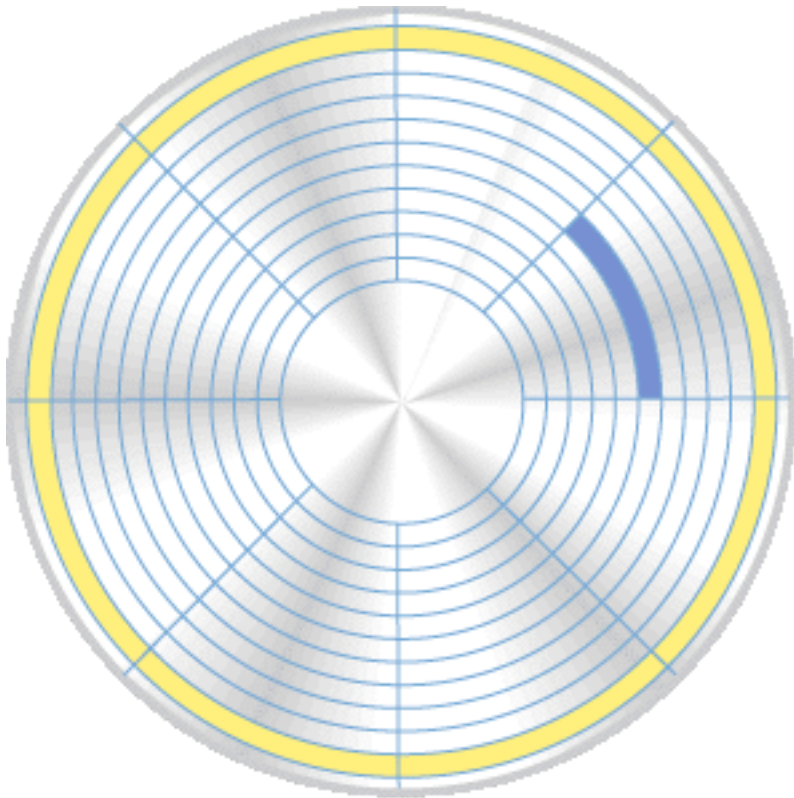
images from M. Coey

# media basics



## Hard disk

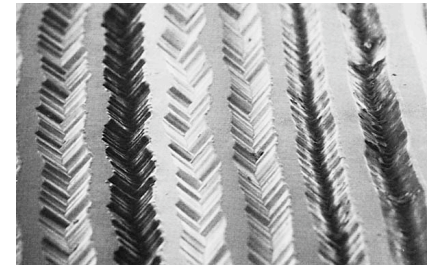
tiny magnetized regions  
direction (N/S) stores bit  
magnetic sensor reads bits



## LP records

tiny bumps  
needle moves

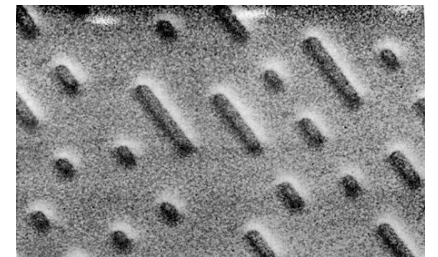
*actual record grooves*



## CDs

pits store bits  
optical reflectivity

*actual CD surface*



# media basics

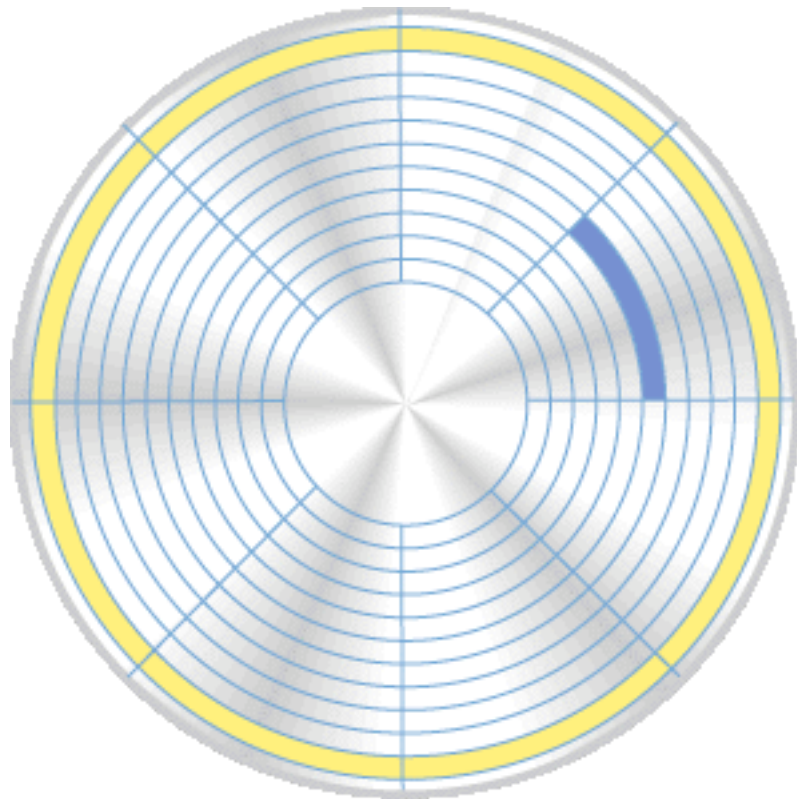
---

hard disk platters are round.

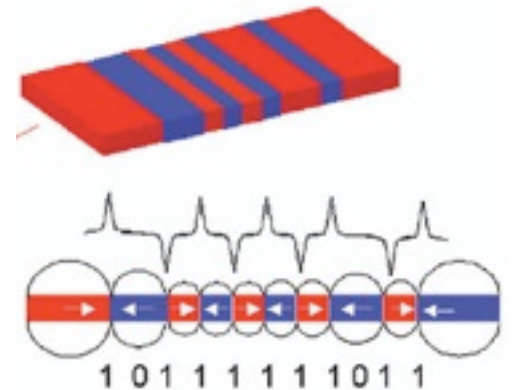
so how is data arranged?

*tracks* = concentric circles  
*sectors* = wedge of a track

sector has fixed # bytes



©2000 How Stuff Works

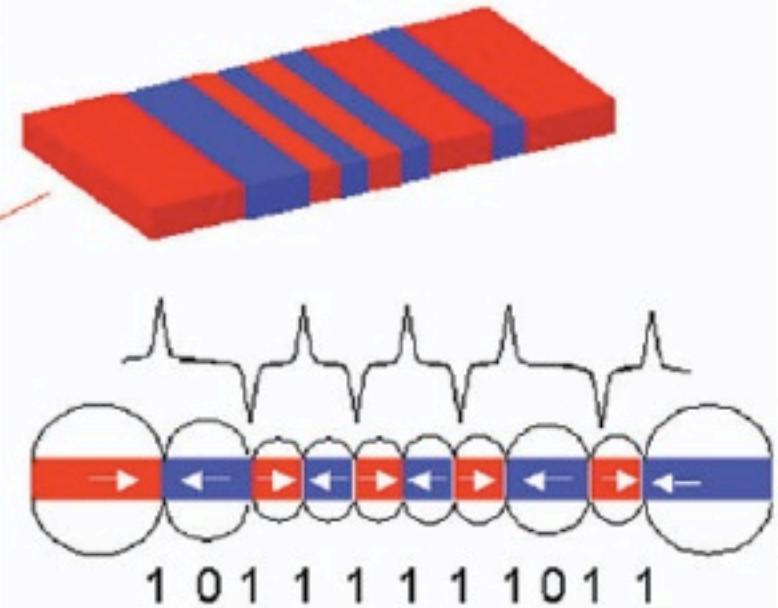
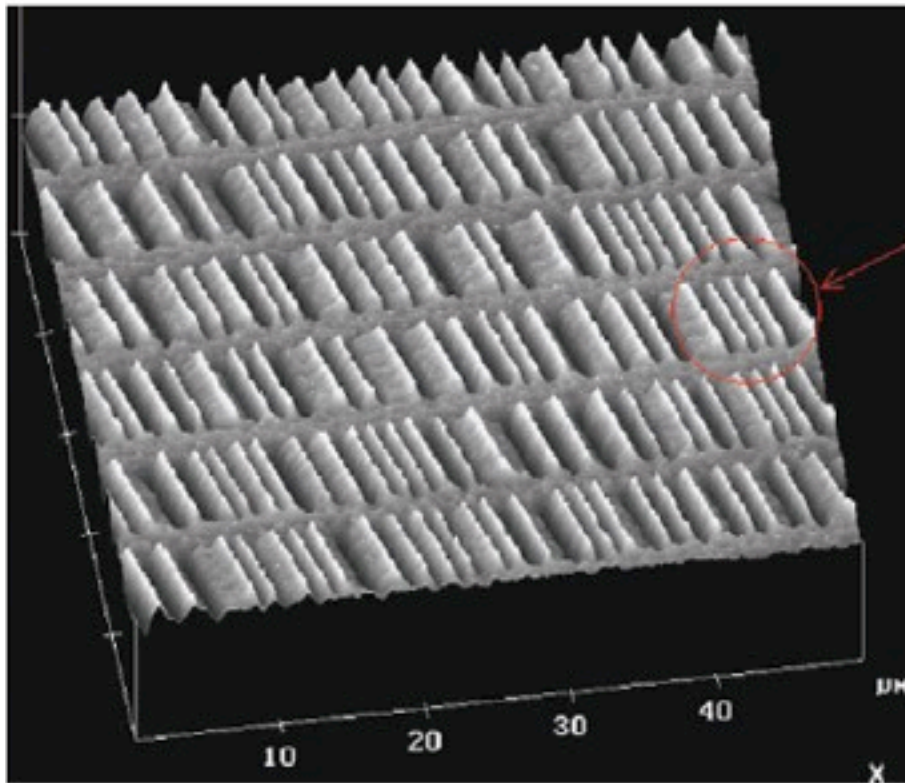




# media basics

mfm  
image

sees  
transition  
field



Jimmy Zhu, *Materials Today*, July/Aug 2003

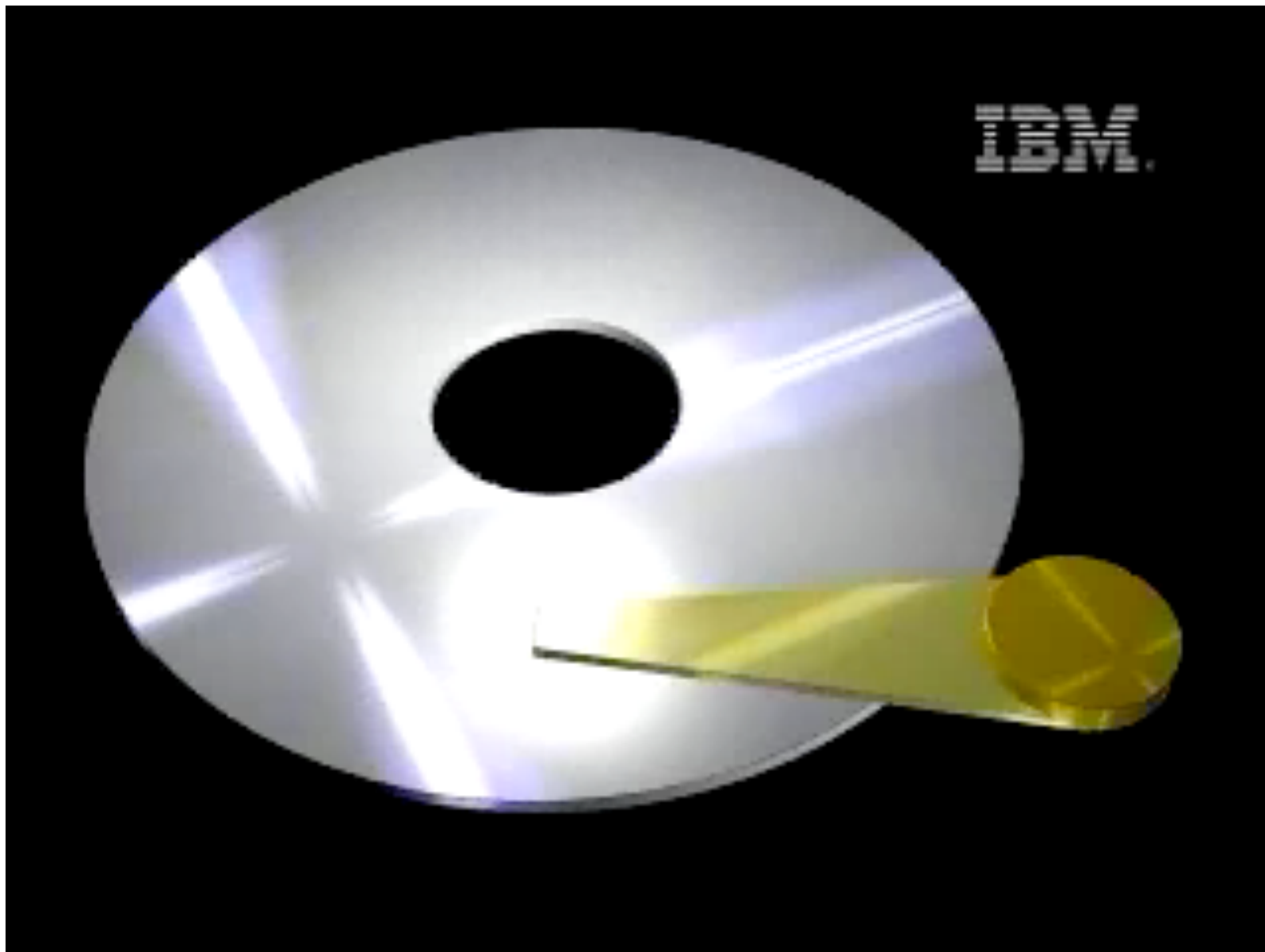
CoCrPt alloy

platters - Al or glass substrate

typical magnetic region

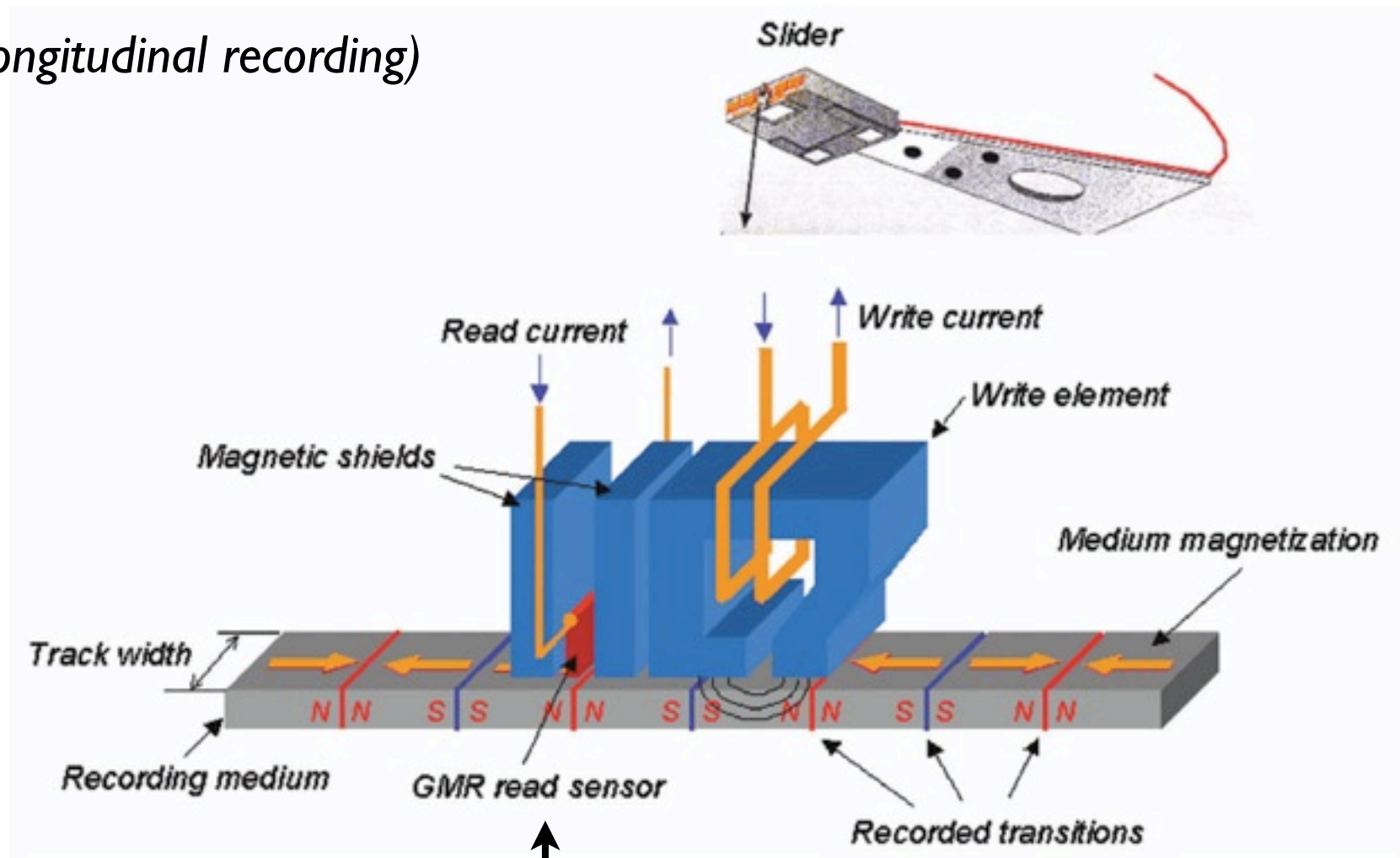
~200-250 nm wide,    ~25-30 nm down-track

100 billion bits (Gigabits) per in<sup>2</sup>



# reading and writing basics

(longitudinal recording)



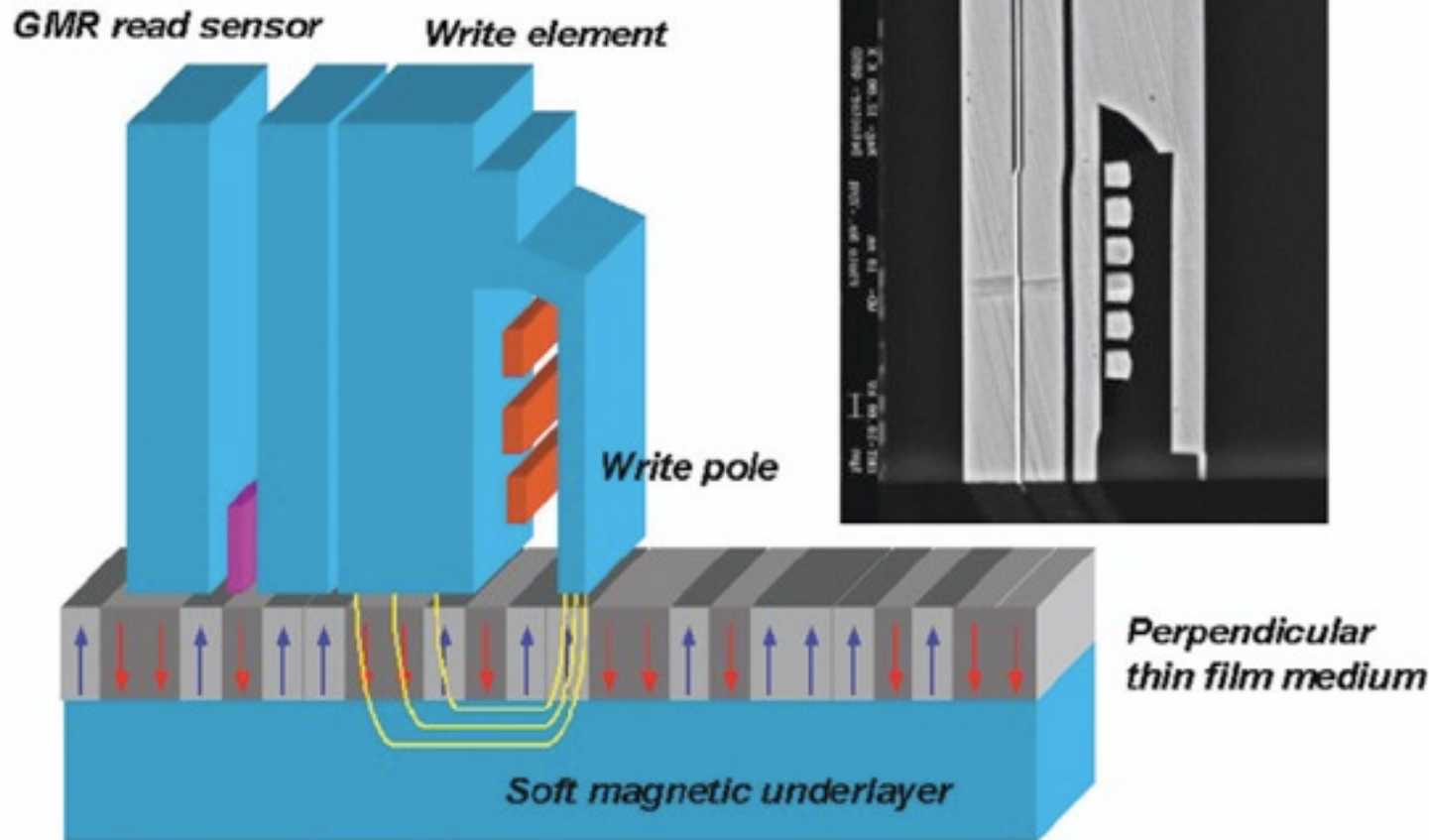
sensor - magnetoresistive

Jimmy Zhu, *Materials Today*, July/Aug 2003

# reading and writing basics

(perpendicular recording)

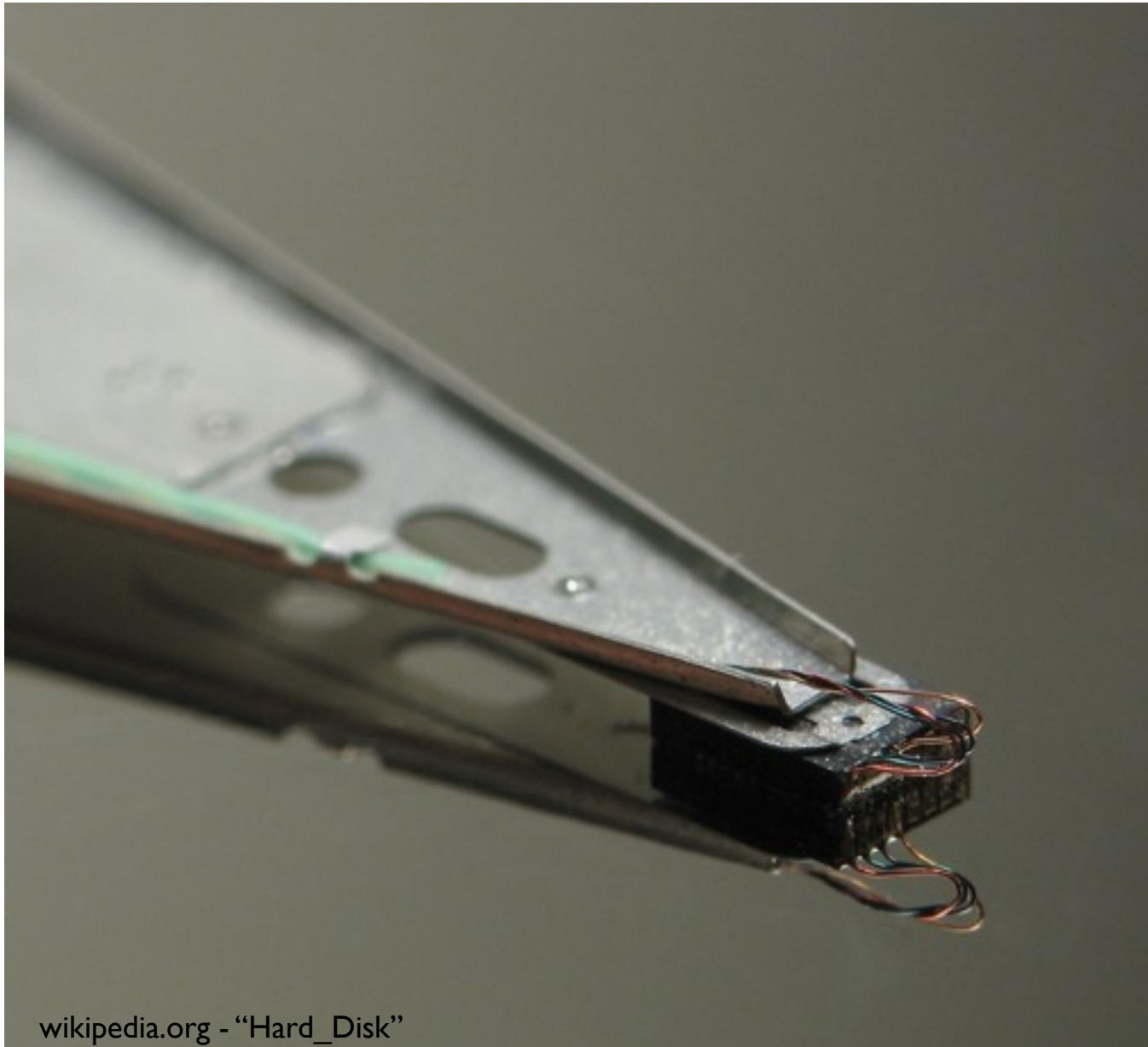
Jimmy Zhu, *Materials Today*, July/Aug 2003



soft underlayer becomes part of the flux guide  
... careful concentration of flux ...

# read head (and its reflection)

---



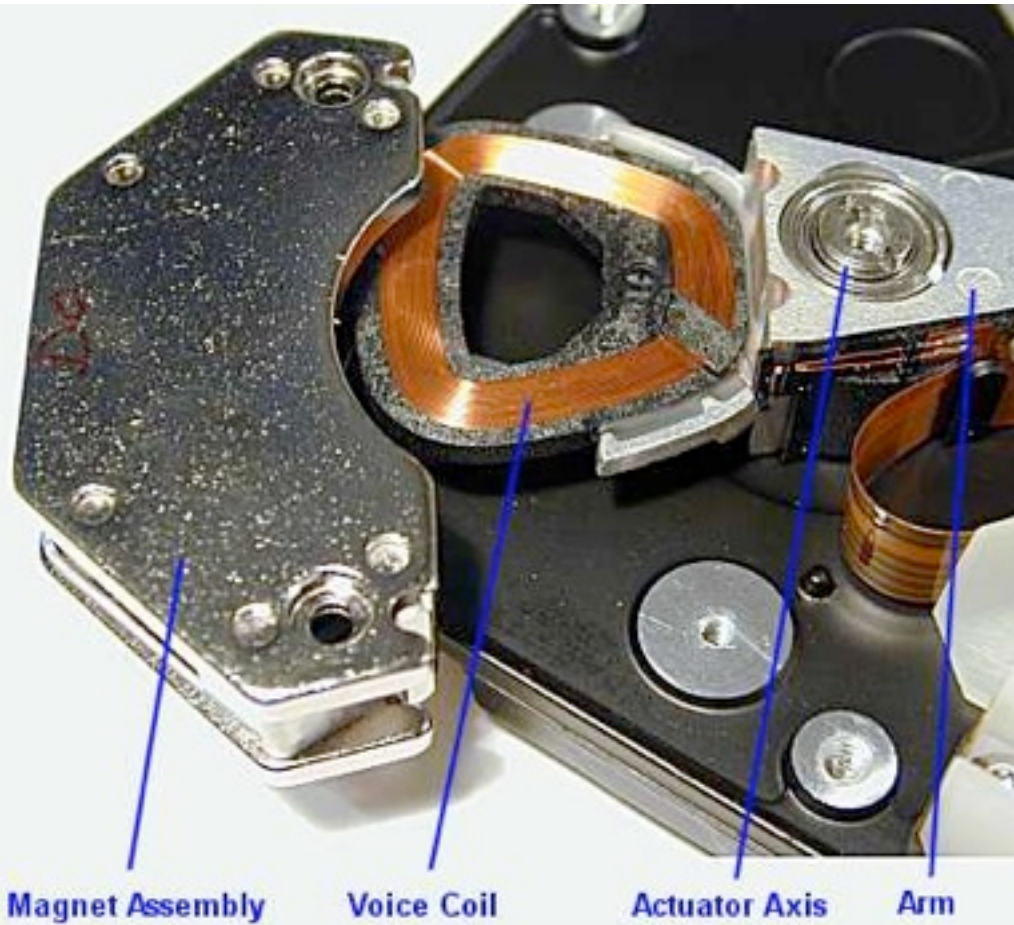
wikipedia.org - "Hard\_Disk"



# positioning basics

---

- current powers voice coil<sup>†</sup>
- field generated moves head L or R
- more precise than stepper motor

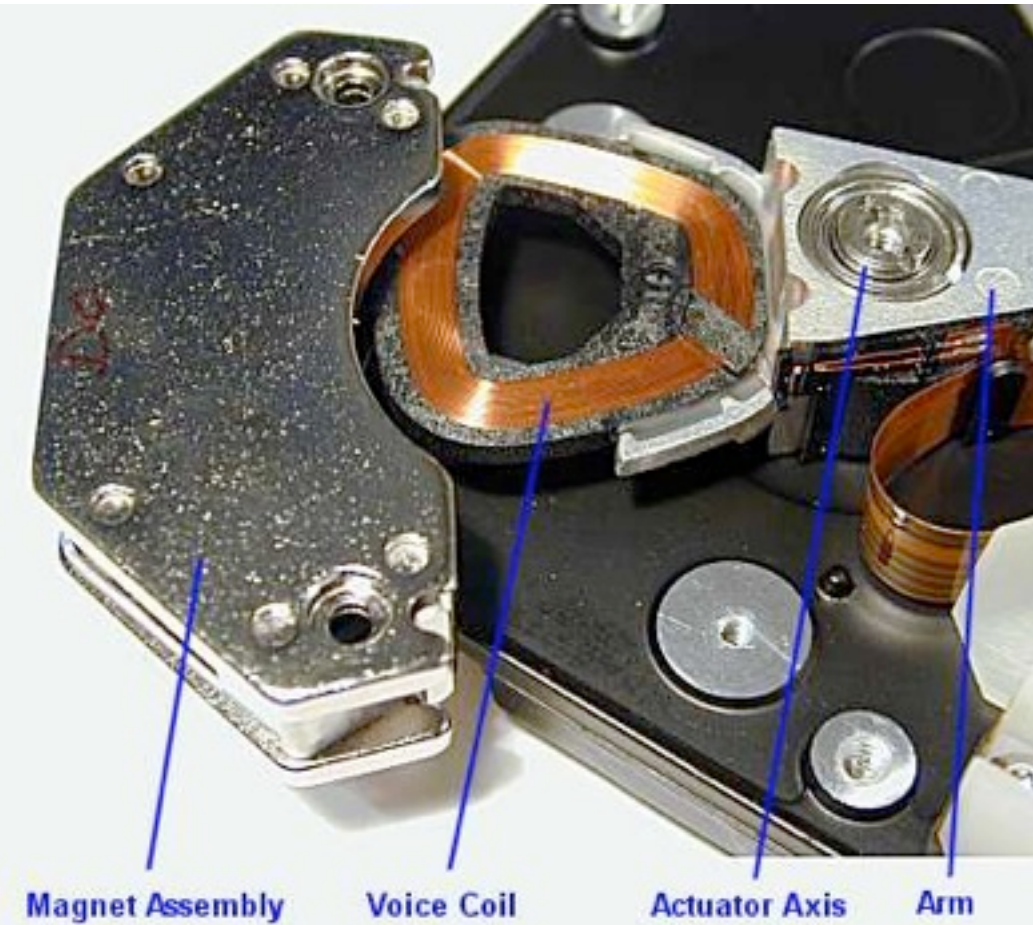


[www.pcguide.com/ref/hdd/op/actActuator-c.html](http://www.pcguide.com/ref/hdd/op/actActuator-c.html)

<sup>†</sup> this is the same way a speaker cone moves

# positioning basics

- current powers voice coil<sup>†</sup>
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[www.pcguide.com/ref/hdd/op/actActuator-c.html](http://www.pcguide.com/ref/hdd/op/actActuator-c.html)

IBM 62PC "Piccolo" HDD, ~1979 - an early 8" disk



wikipedia.org - "Hard\_Disk"

<sup>†</sup> this is the same way a speaker cone moves

# why magnets?

---

microscopic view



magnets remember their state

once magnetized, they stay that way

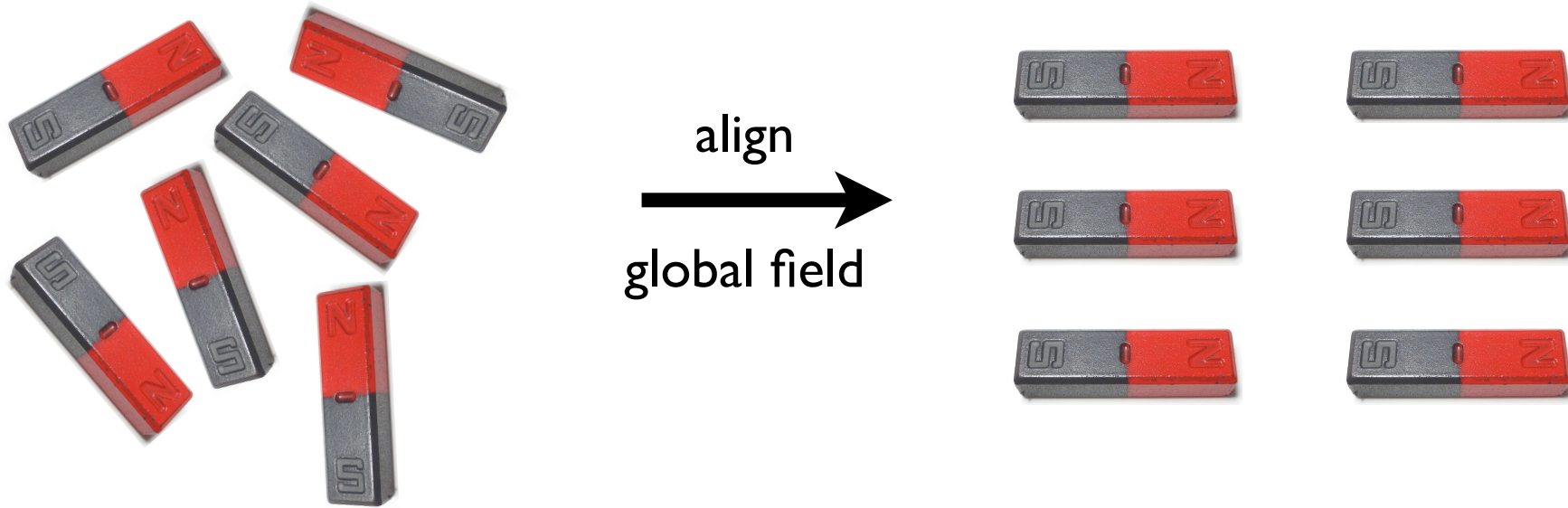
with a little bit of energy, we can control them

switch from N to S

# why magnets?

---

microscopic view



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switch from N to S



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---

microscopic view



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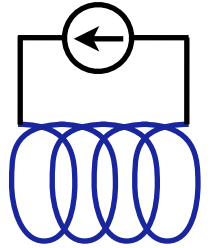
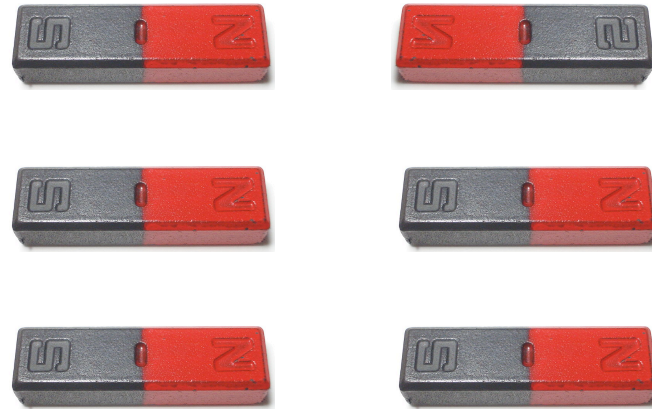
switch from N to S

# why magnets?

microscopic view



address  
→  
local field



magnets remember their state

once magnetized, they stay that way

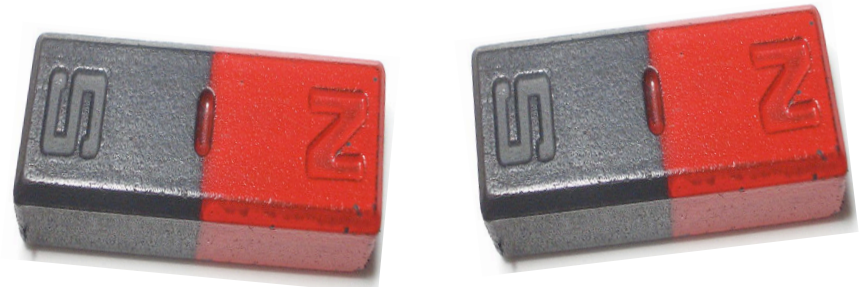
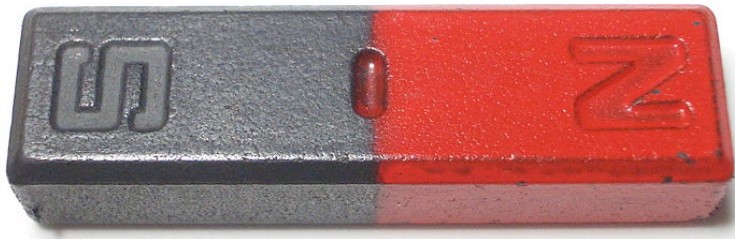
with a little bit of energy, we can control them  
switch from N to S

# why magnets?

---

what happens when  
you break a magnet?

you get two magnets



now: do this 25 more times

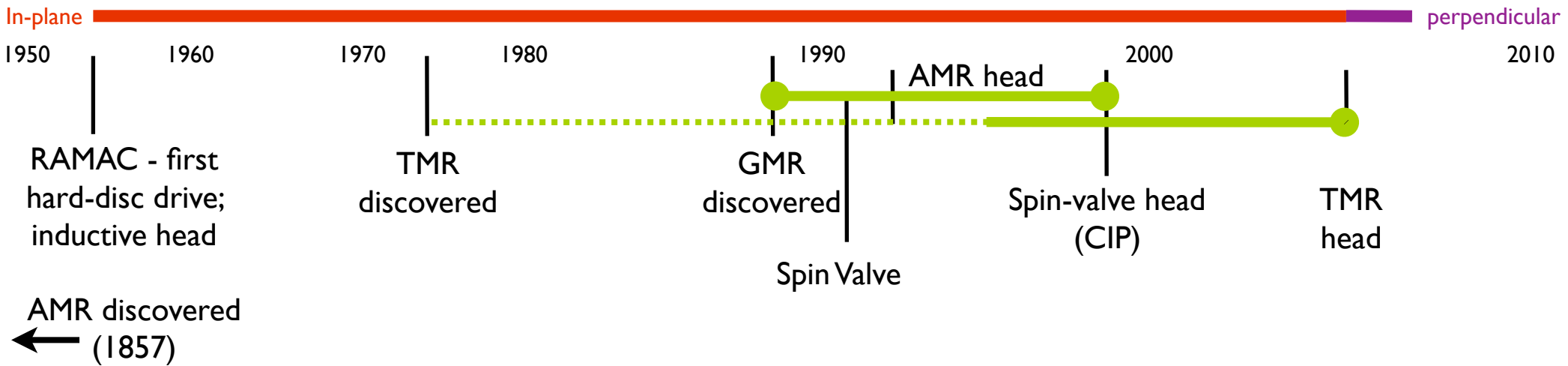
→ 33 million magnets, all 50nm across

about 1,000 times thinner than a hair

we can make *really tiny* magnets  
smaller is *better*, to a point

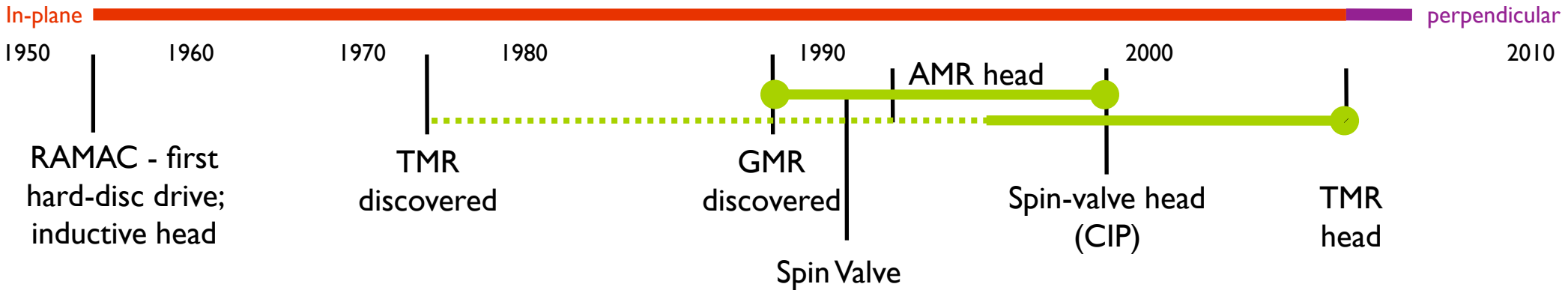


# technology timeline



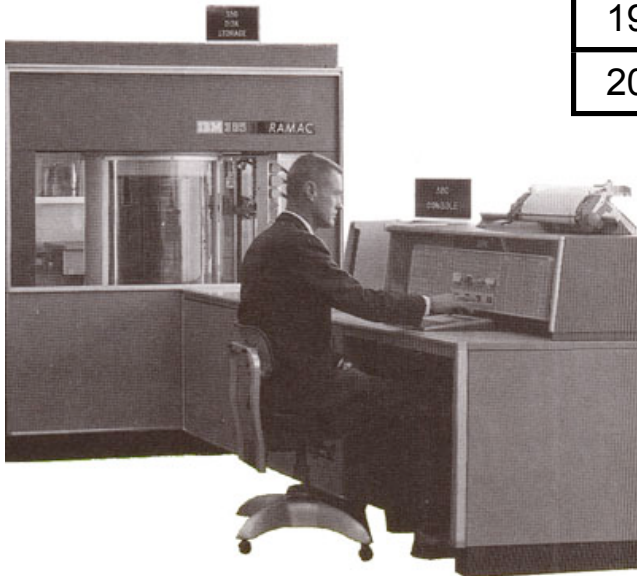
images and text from M. Coey

# technology timeline



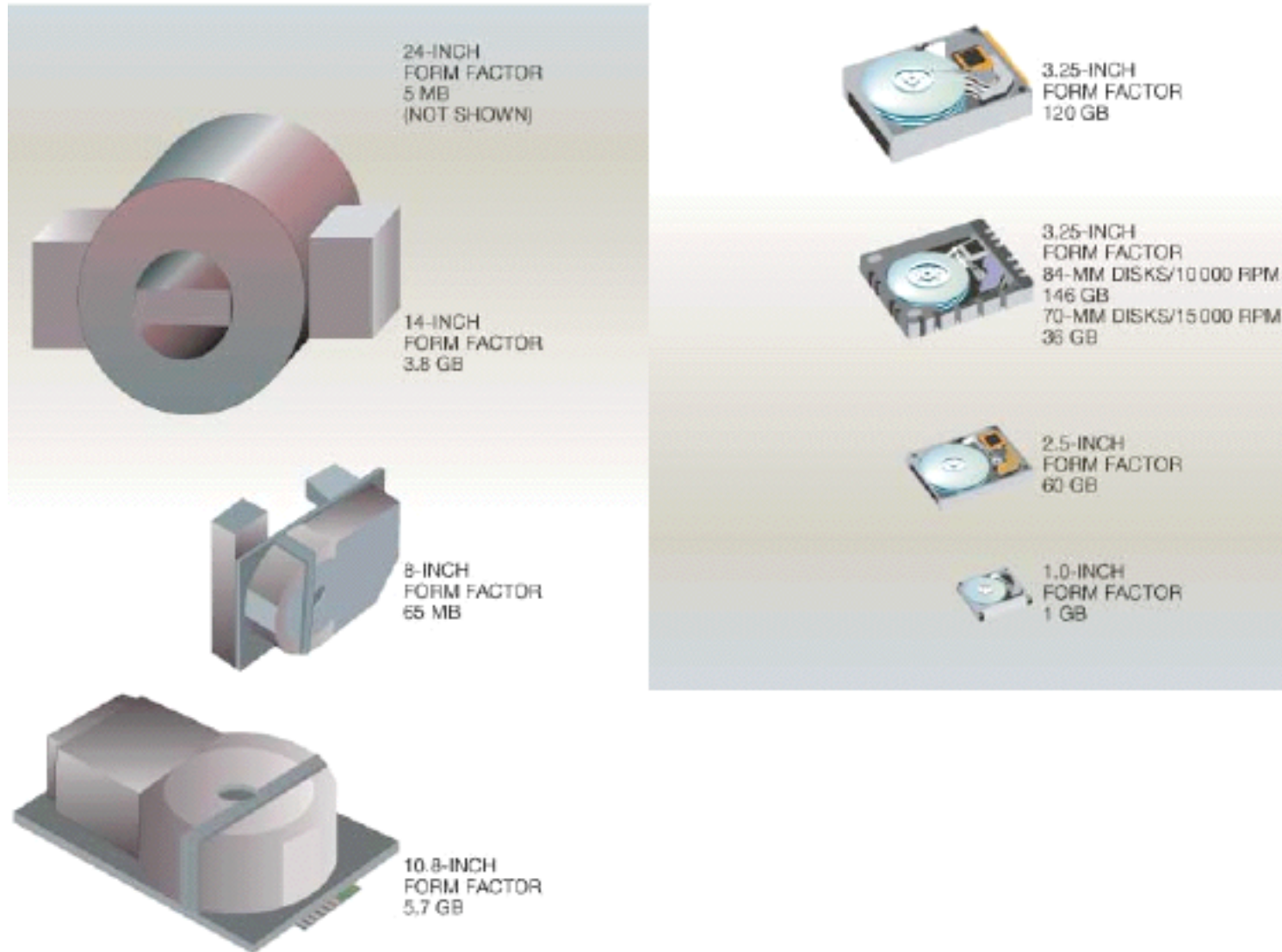
AMR discovered  
← (1857)

year	capacity	platters	size	rpm
1955	40 Mb	50x2	24"	1200
2005	160 Gb	1	2.5"	18000



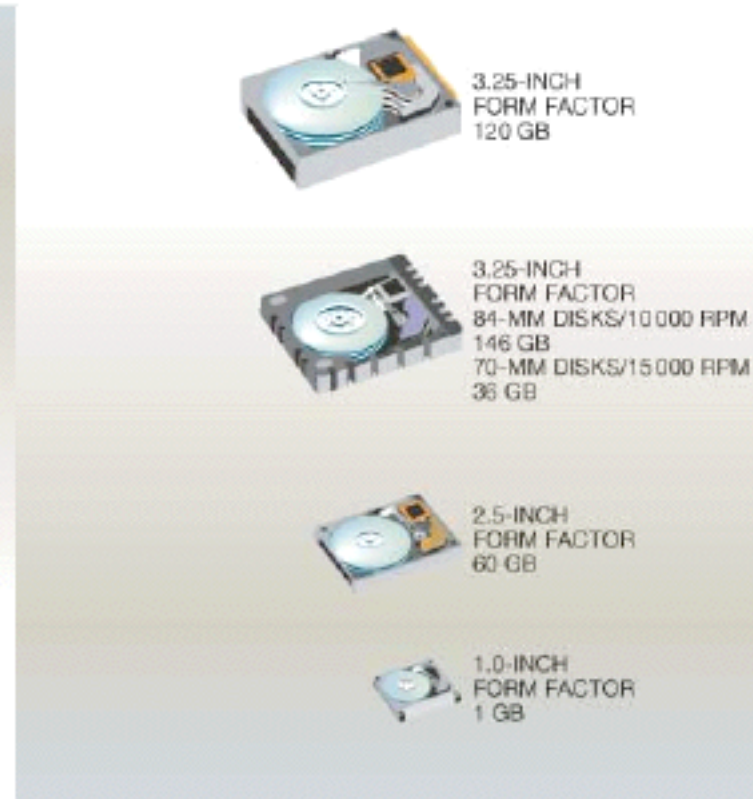
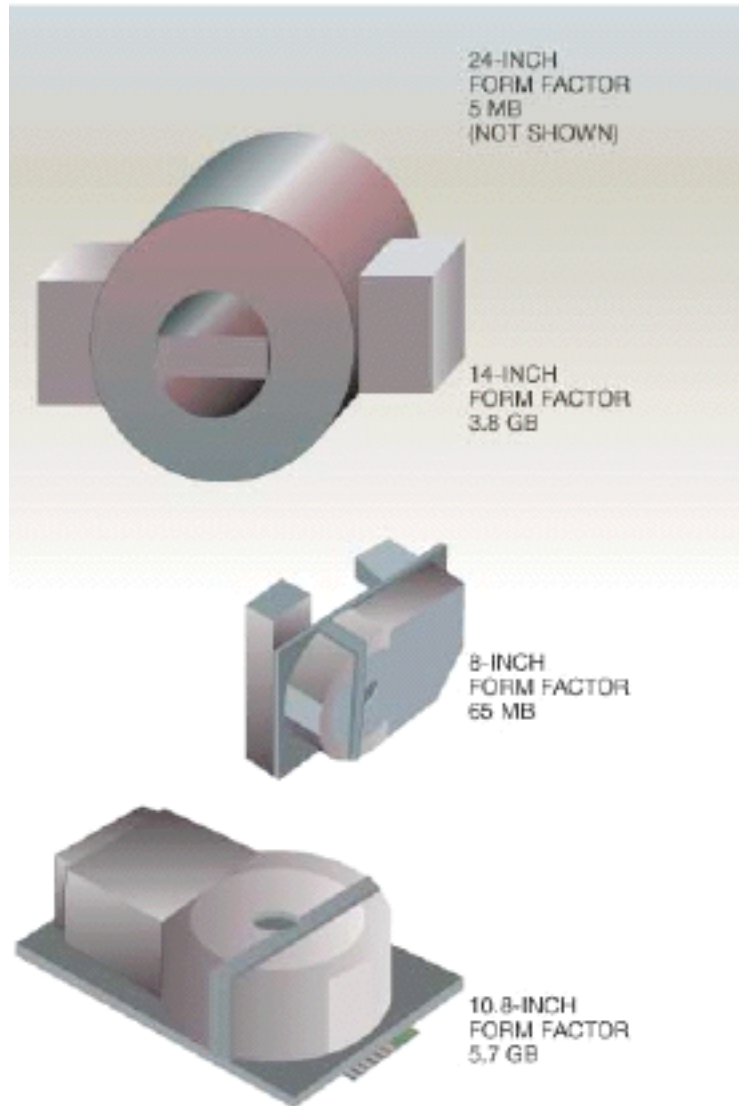
images and text from M. Coey

# the incredible shrinking hard disk



E. Grochowski and R.D. Halem  
*IBM Systems Journal*, **42** (2), 2003

# the incredible shrinking hard disk



E. Grochowski and R.D. Halem  
*IBM Systems Journal*, **42** (2), 2003

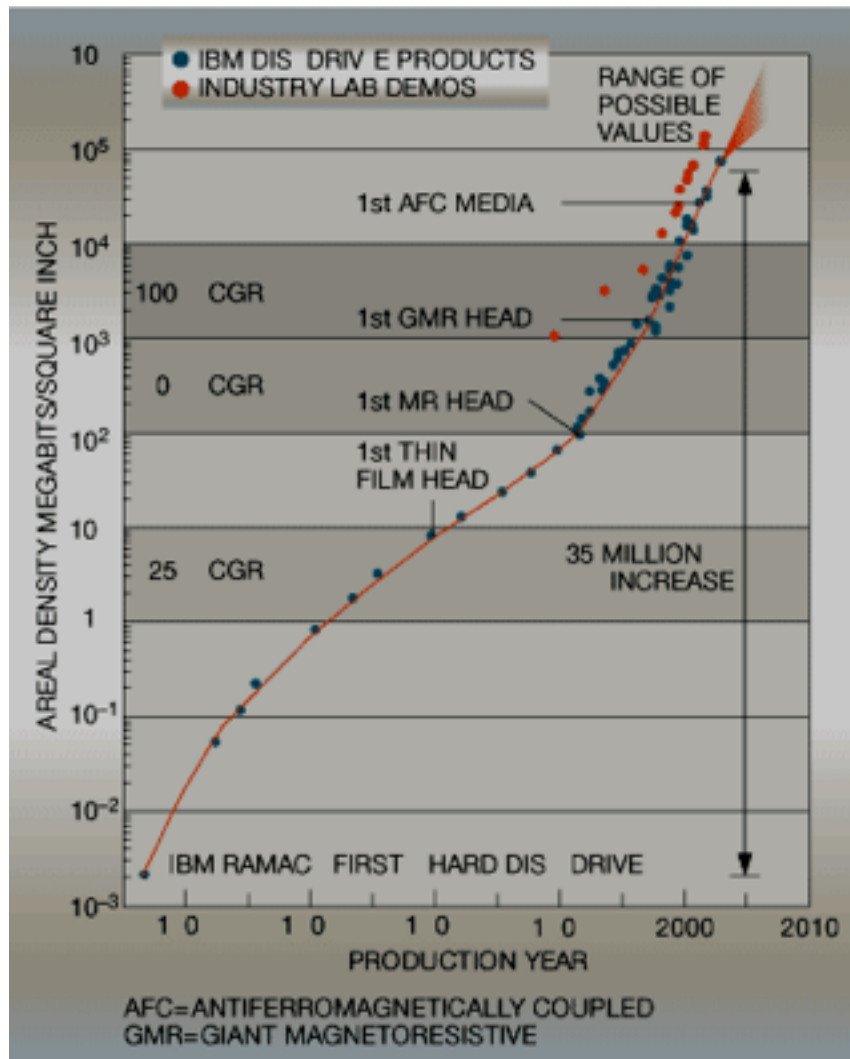
# growth of areal density

---

E. Grochowski and R.D. Halem  
*IBM Systems Journal*, **42** (2), 2003

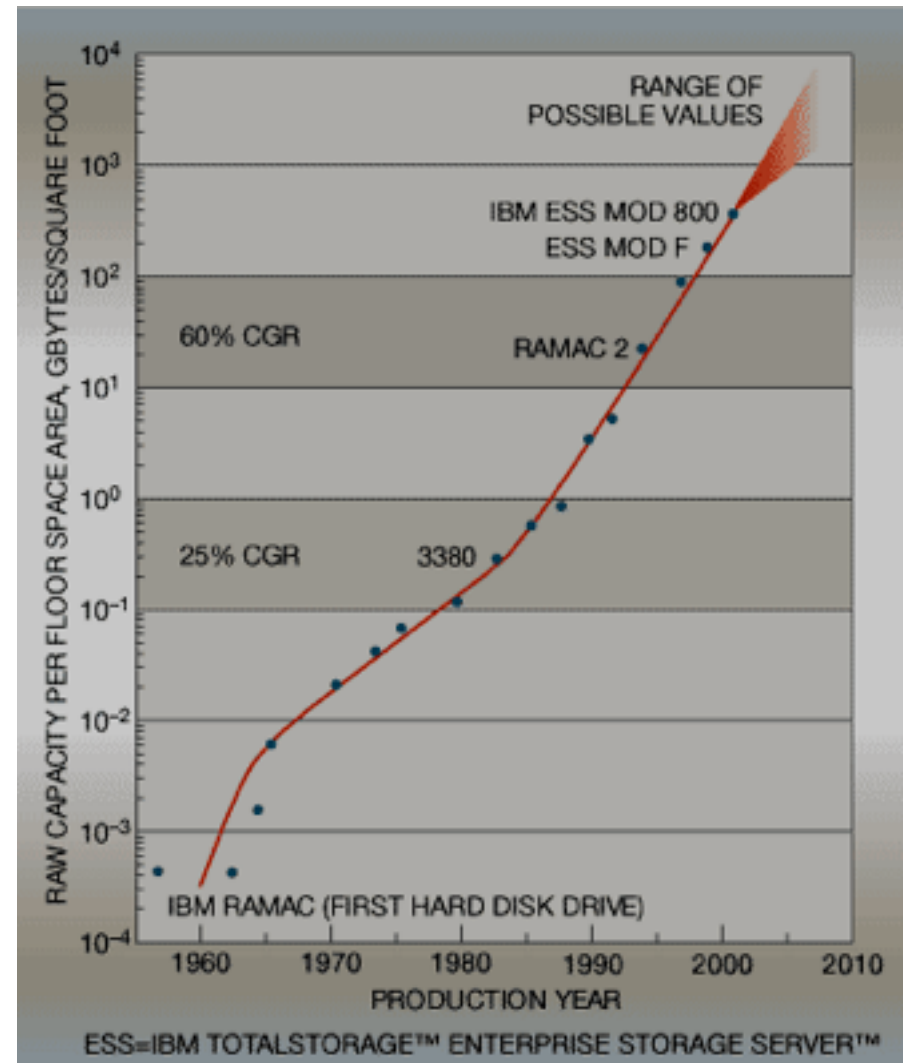
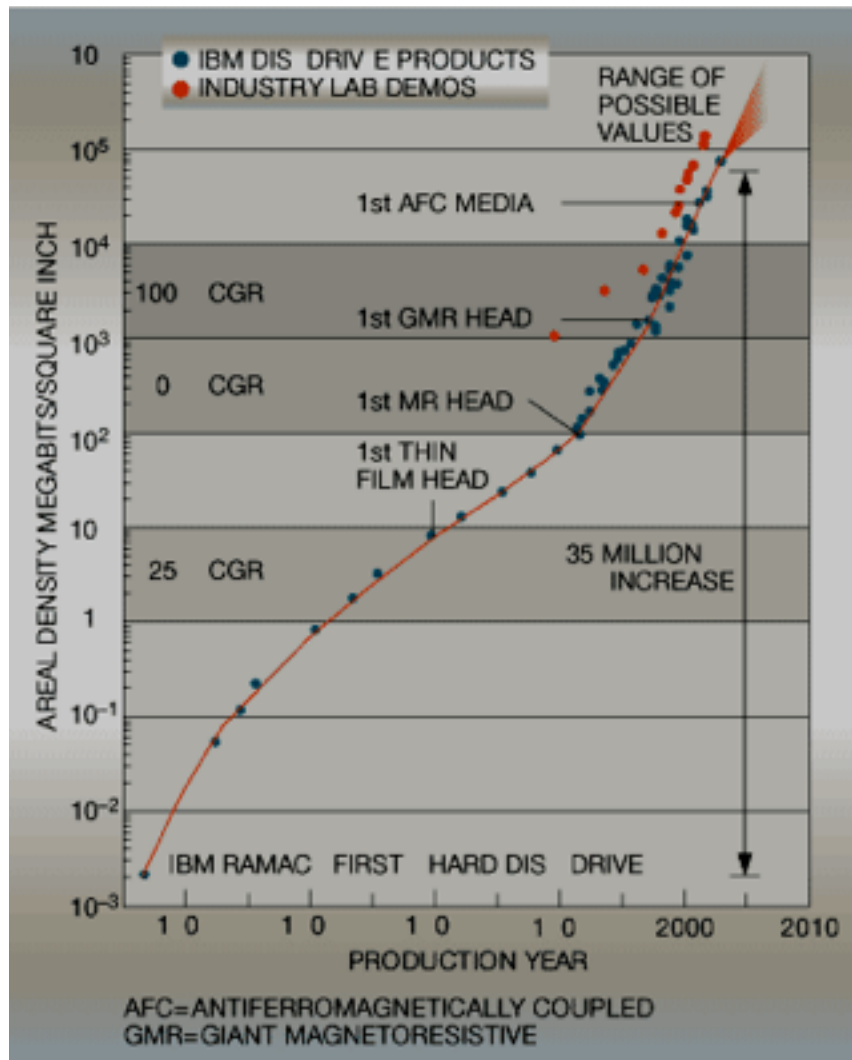


# growth of areal density



E. Grochowski and R.D. Halem  
*IBM Systems Journal*, **42** (2), 2003

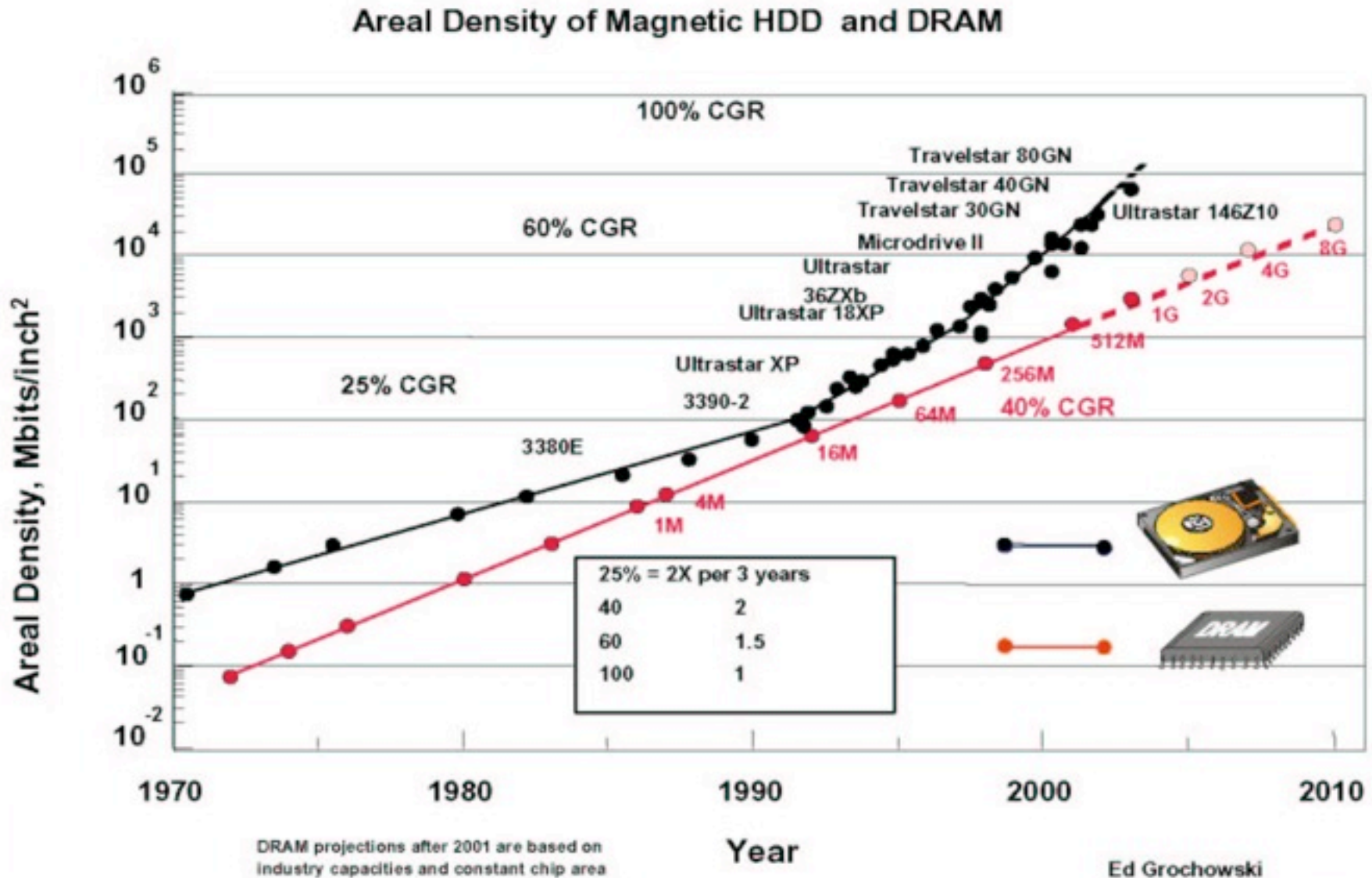
# growth of areal density



E. Grochowski and R.D. Halem  
*IBM Systems Journal*, **42** (2), 2003

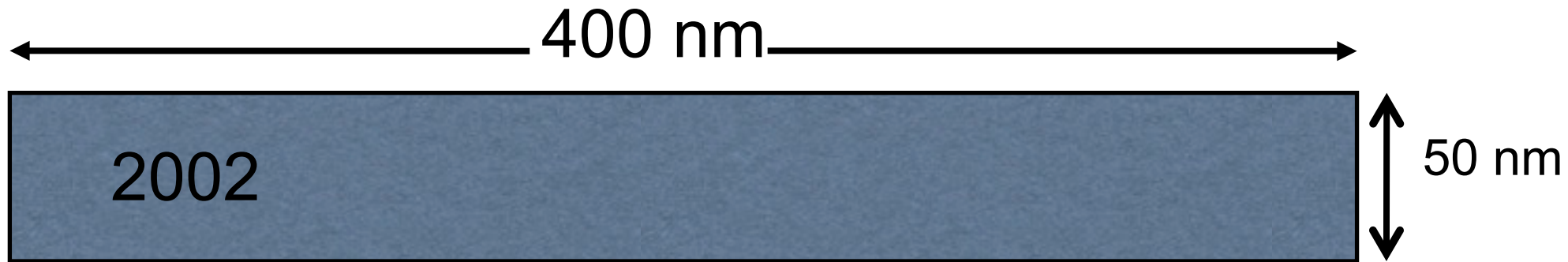


# areal density vs. DRAM



# The incredible shrinking bit!

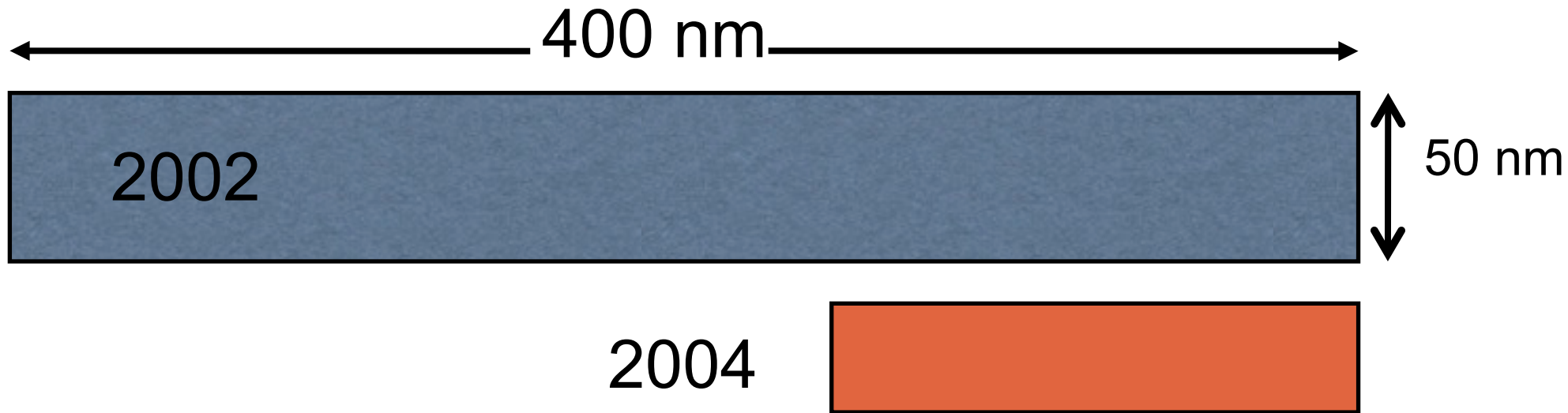
## Predicted relative sizes of HDD storage bits



(assumes areal densities continue to double yearly)

# The incredible shrinking bit!

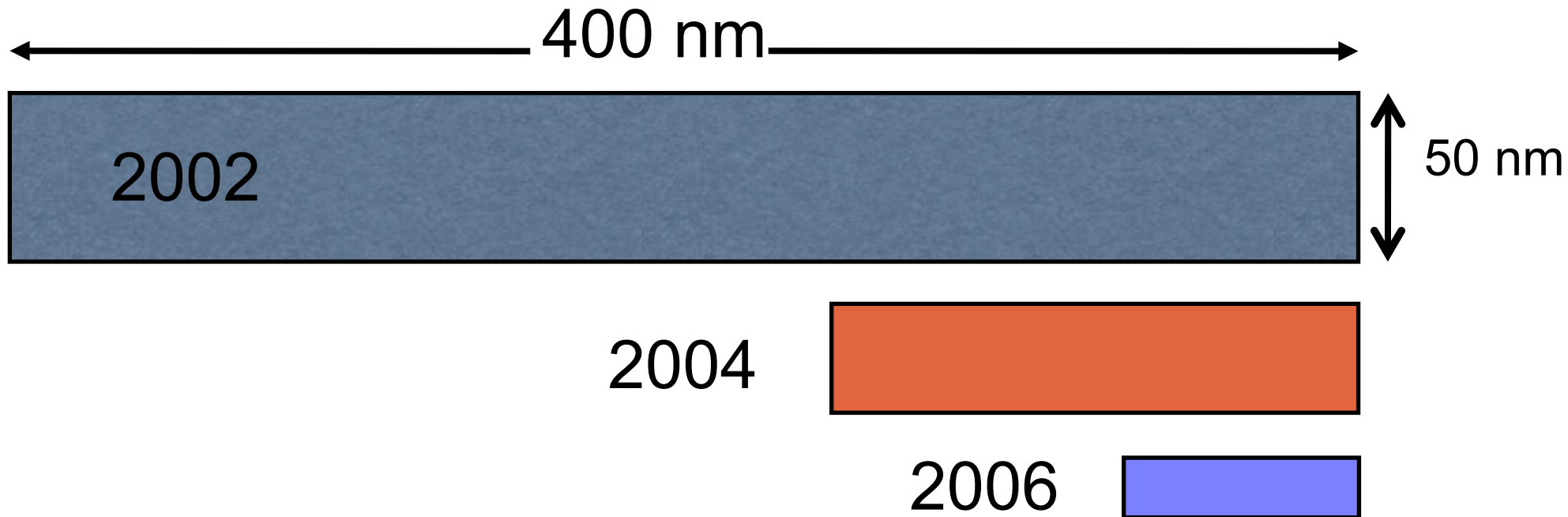
## Predicted relative sizes of HDD storage bits



(assumes areal densities continue to double yearly)

# The incredible shrinking bit!

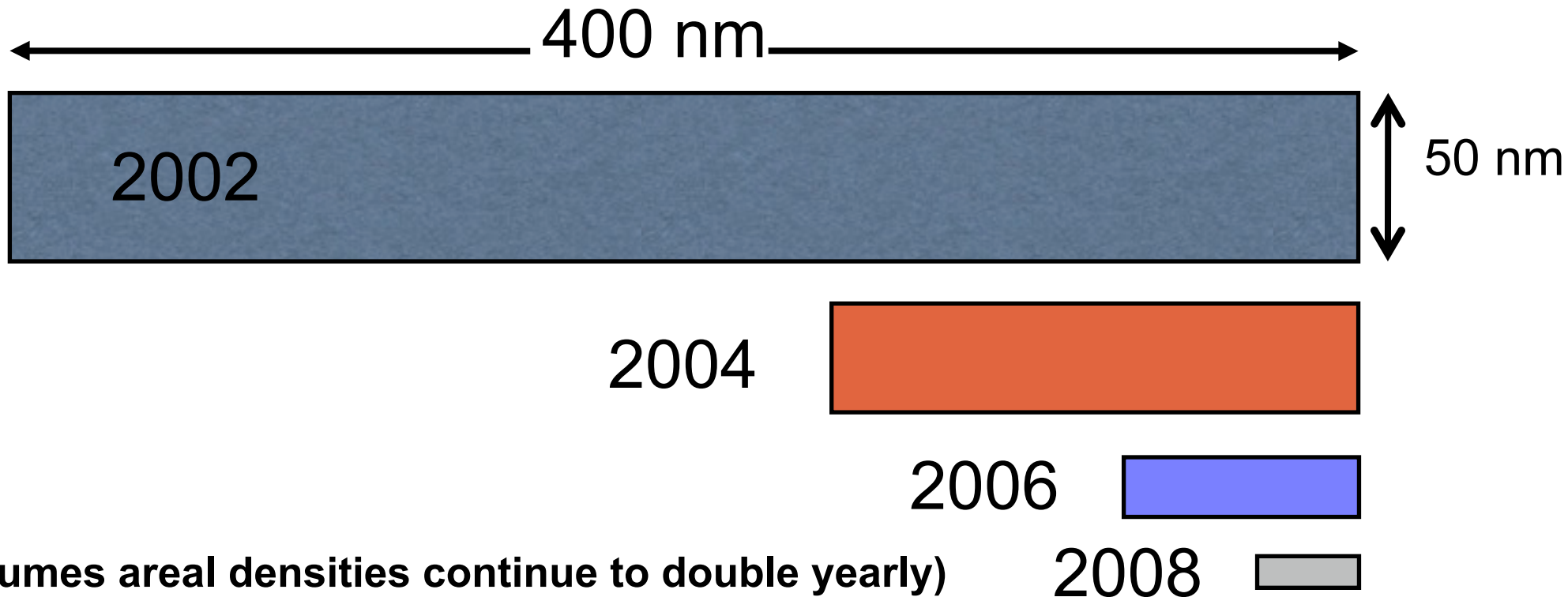
## Predicted relative sizes of HDD storage bits



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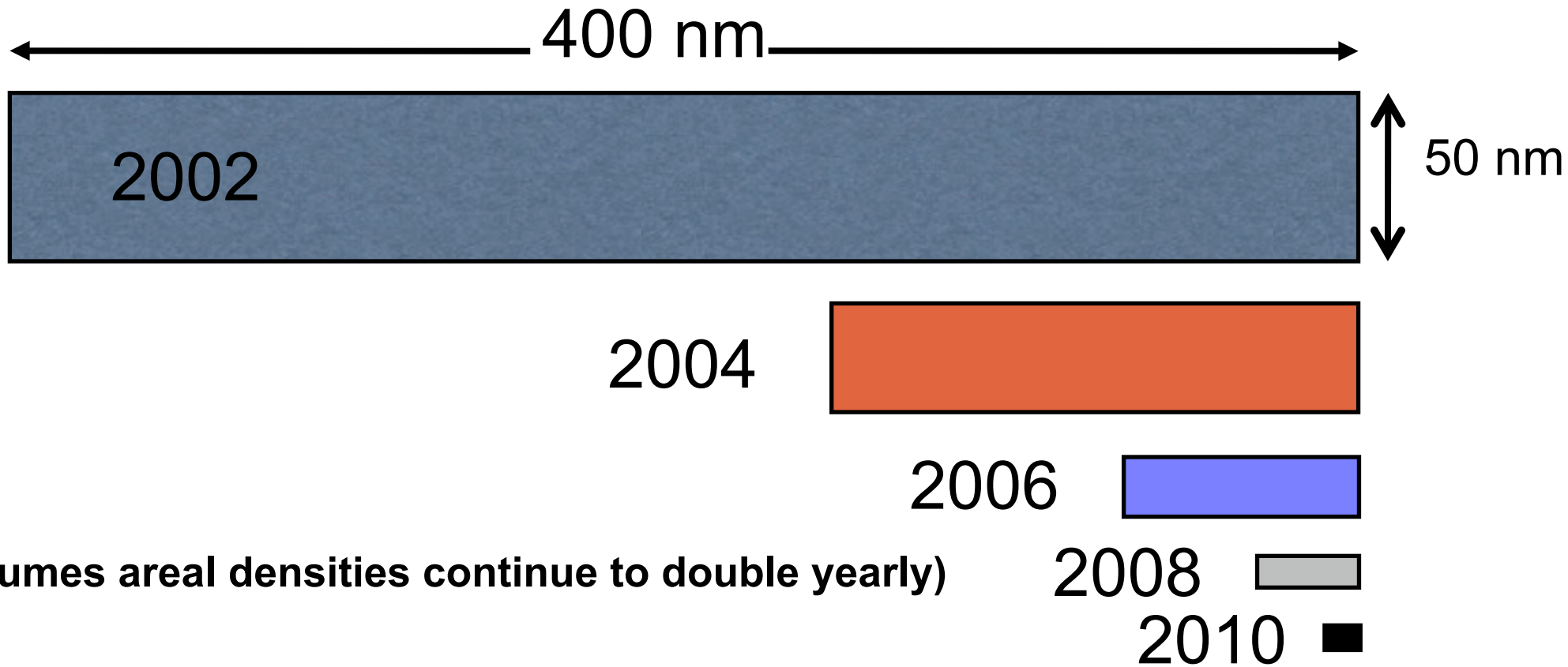
# The incredible shrinking bit!

## Predicted relative sizes of HDD storage bits



# The incredible shrinking bit!

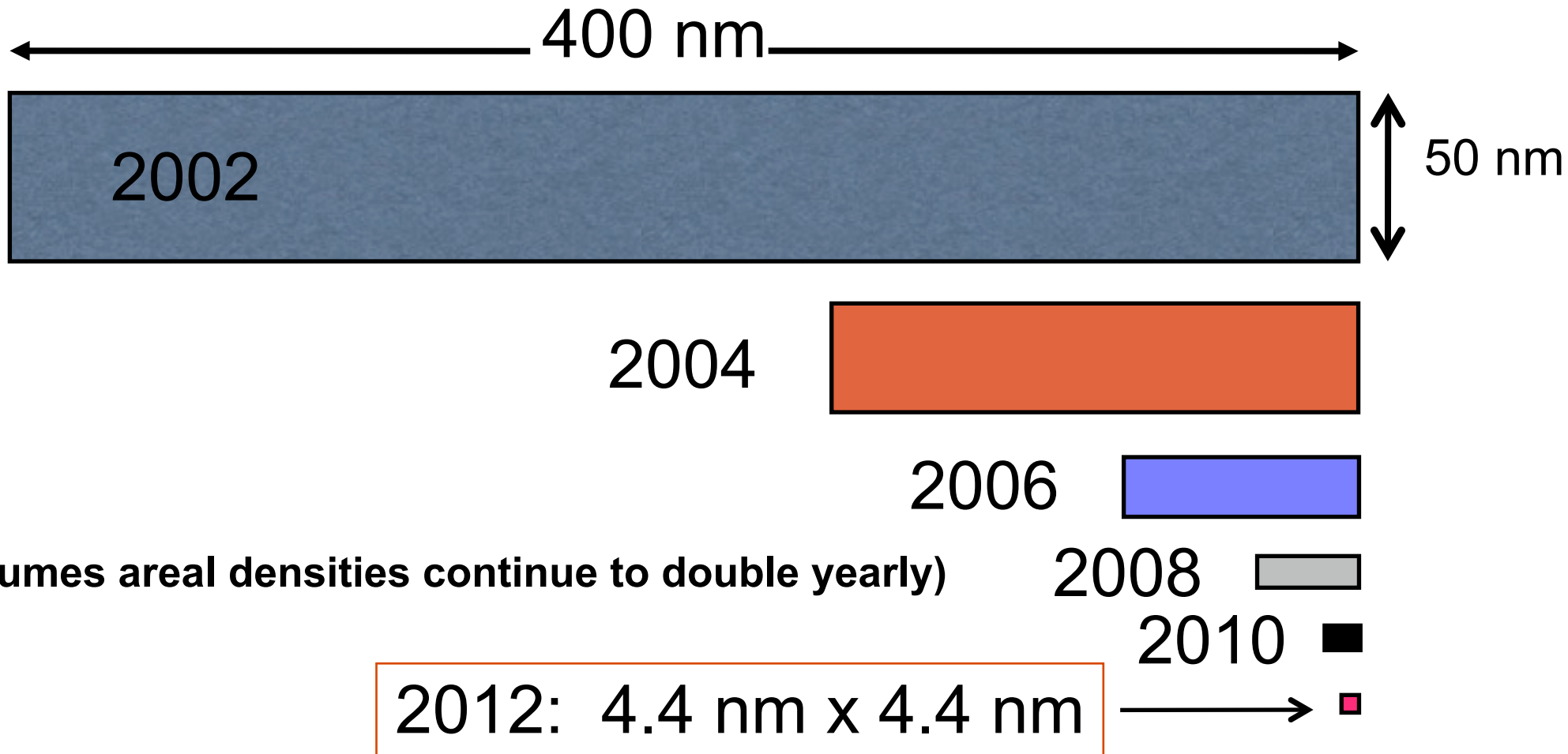
## Predicted relative sizes of HDD storage bits





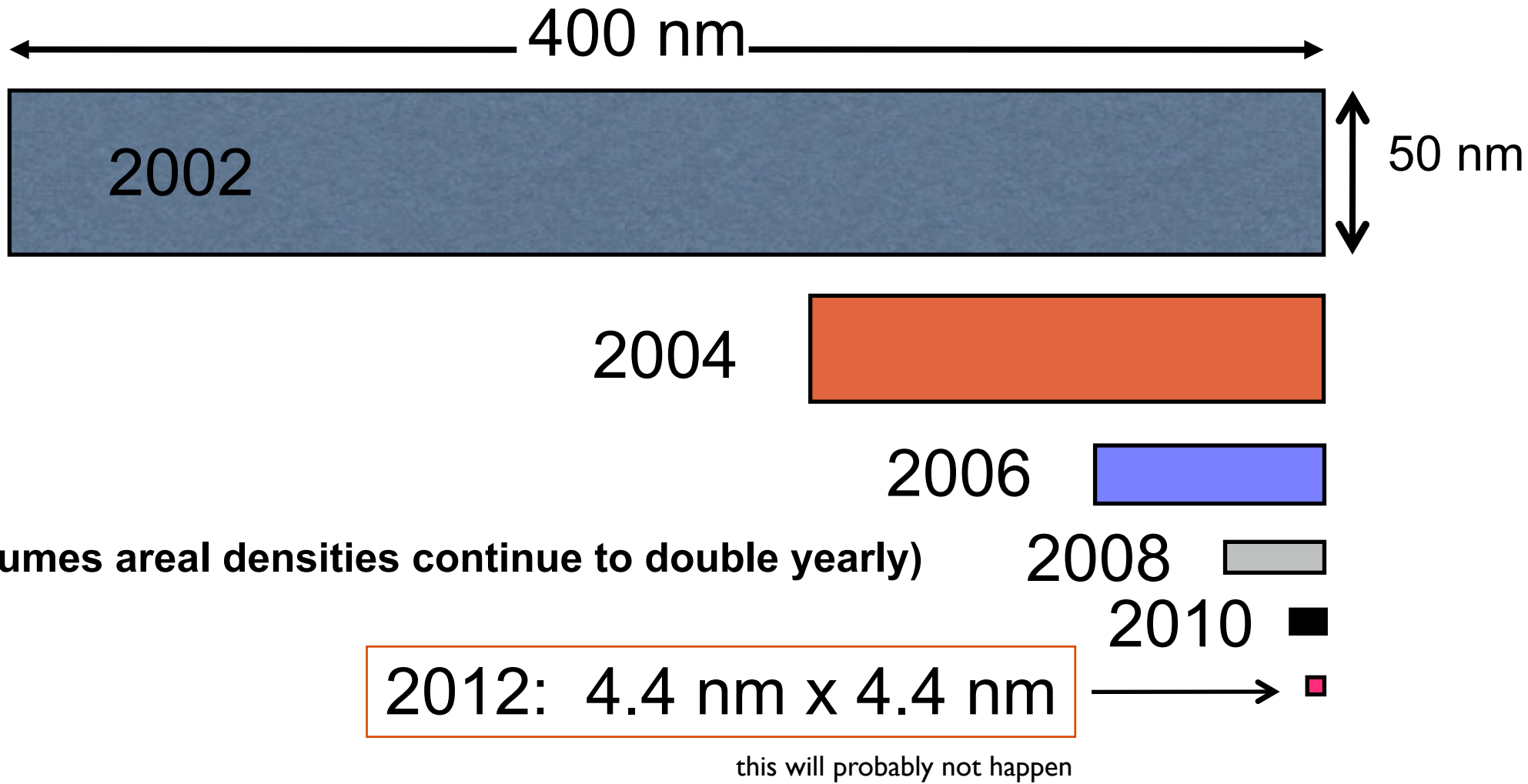
# The incredible shrinking bit!

## Predicted relative sizes of HDD storage bits



# The incredible shrinking bit!

## Predicted relative sizes of HDD storage bits



# 50 TB per square inch on a quarter ...

---

- over 3.4 million high-resolution photos, or ...
- 2,800 audio CDs, or...
- 1,600 hours of television, or ...

# 50 TB per square inch on a quarter ...

---

- over 3.4 million high-resolution photos, or ...
- 2,800 audio CDs, or...
- 1,600 hours of television, or ...
  
- the entire printed collection of the U.S. Library of Congress



Library of Congress,  
Jefferson building

# *so what's the problem?*

---

at some point, they are no longer stable

heat makes them 'wiggle'

like drops of water on a griddle

bits are no longer reliable

so we need stronger magnets ...

... which need more field to magnetize

... which needs more power

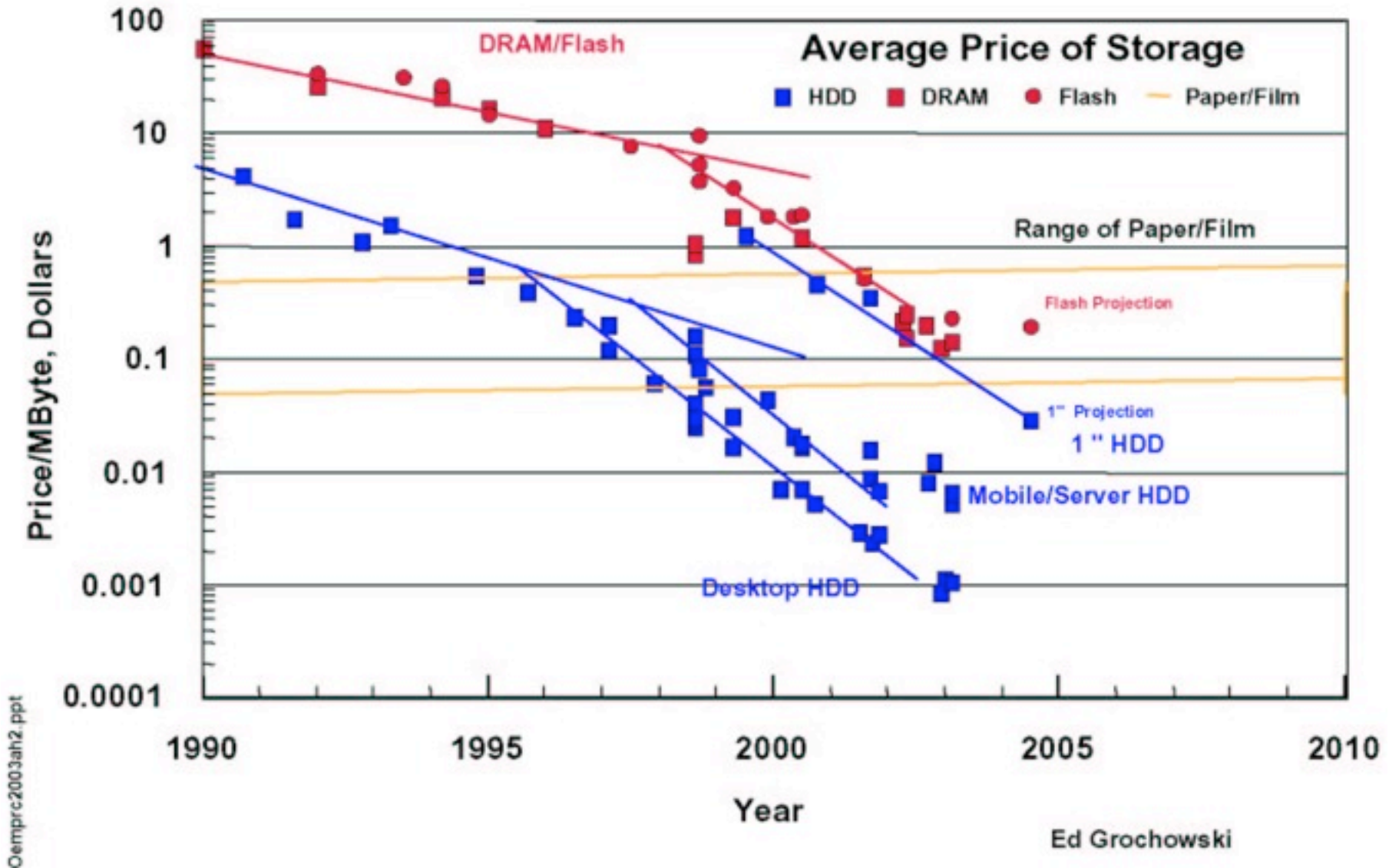


**HUGE challenge in nanoscale materials science!**

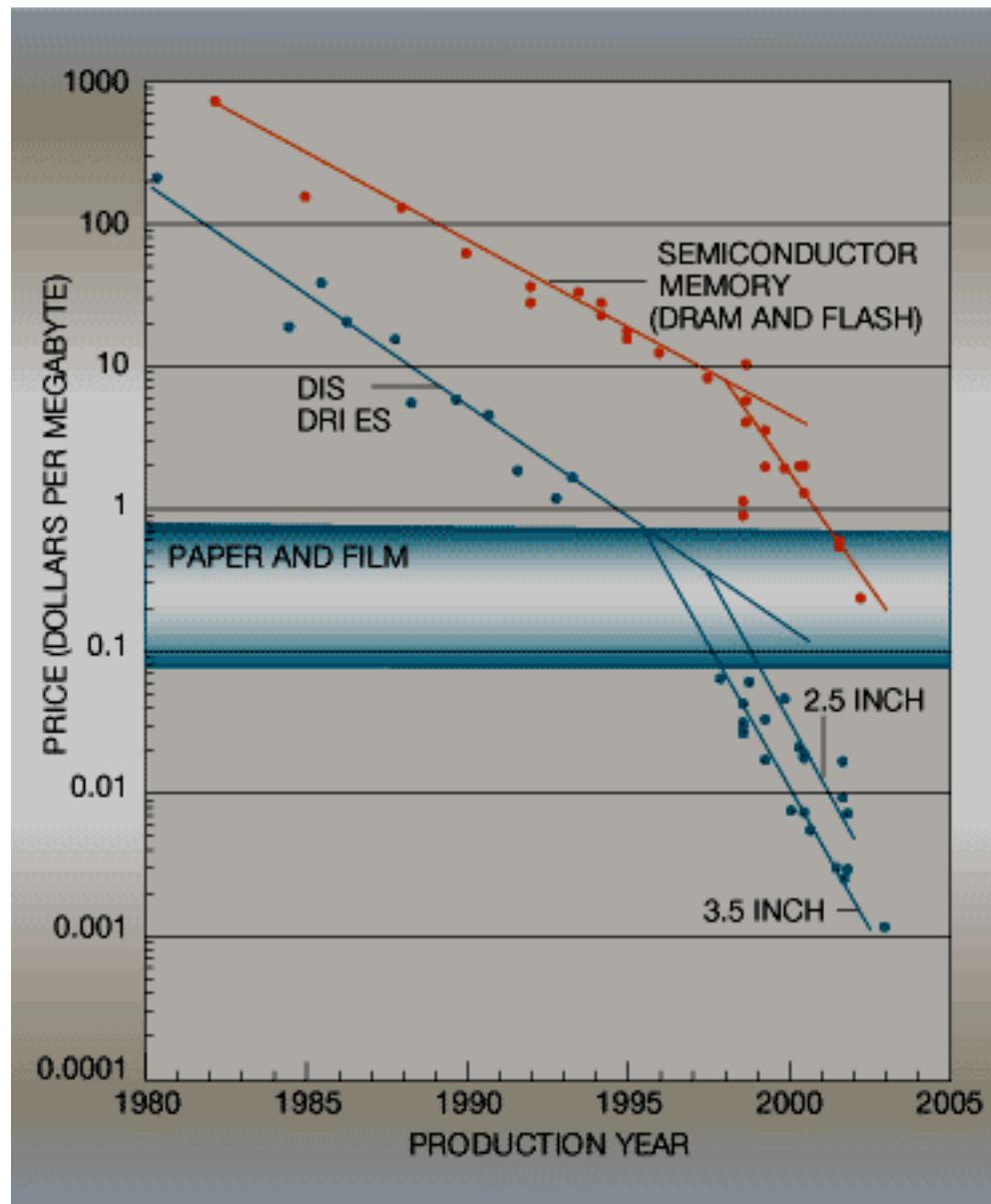
**1 bit needs  $k_B T$  ...**

---

# \$\$\$ vs flash and DRAM



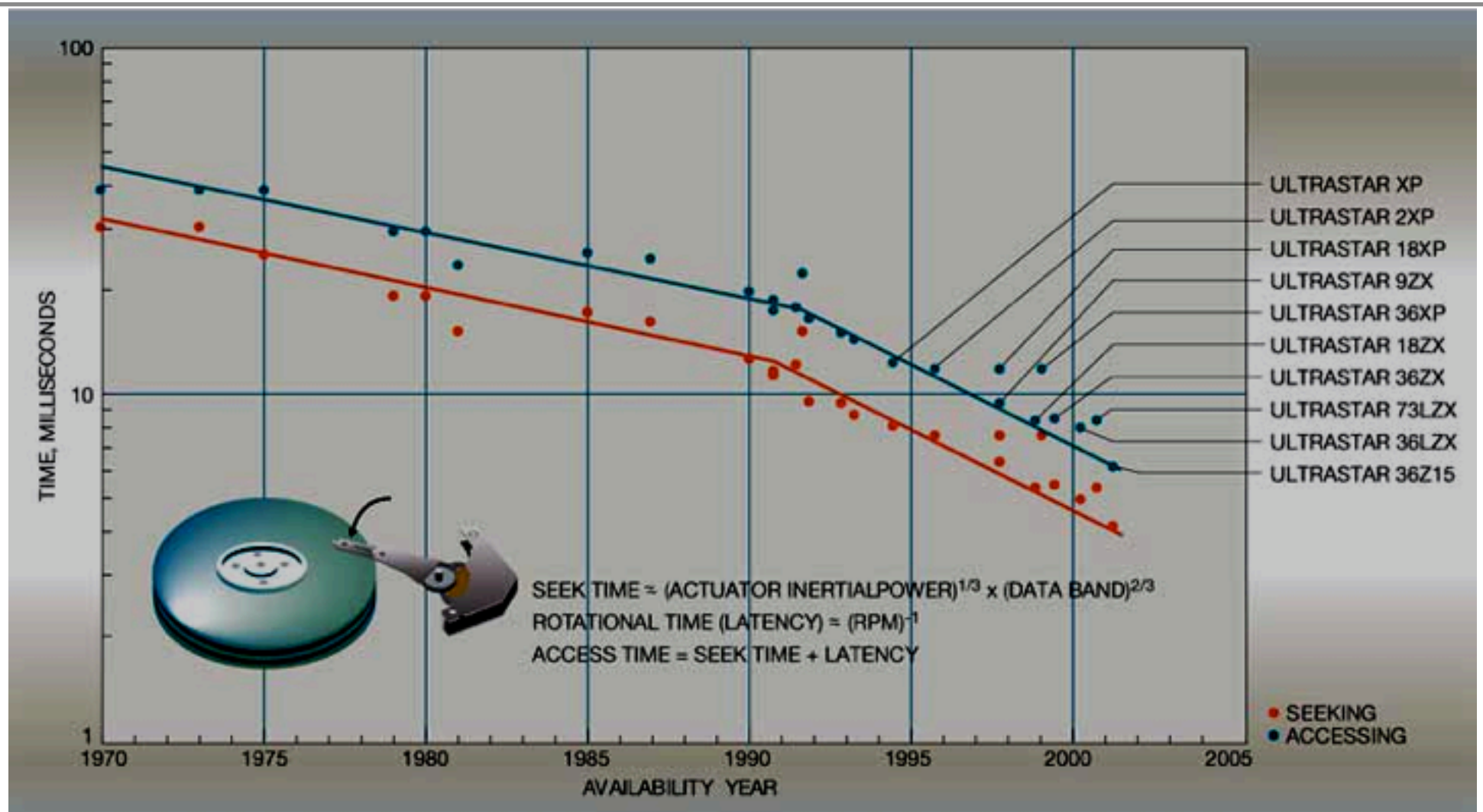
# \$\$\$ vs flash and DRAM



E. Grochowski and R.D. Halem  
*IBM Systems Journal*, **42** (2), 2003

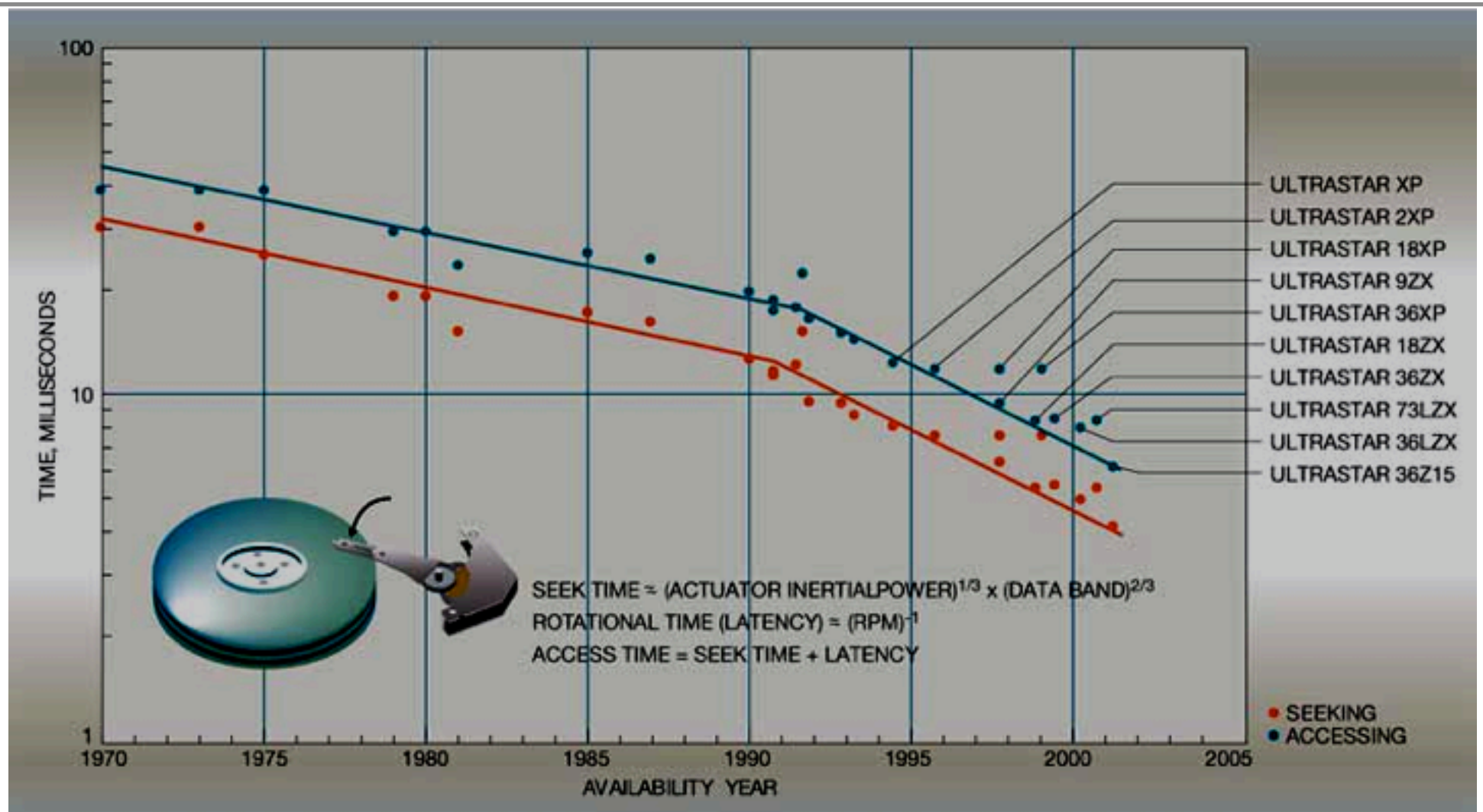


# seek time



E. Grochowski and R.D. Halem  
*IBM Systems Journal*, **42** (2), 2003

# seek time

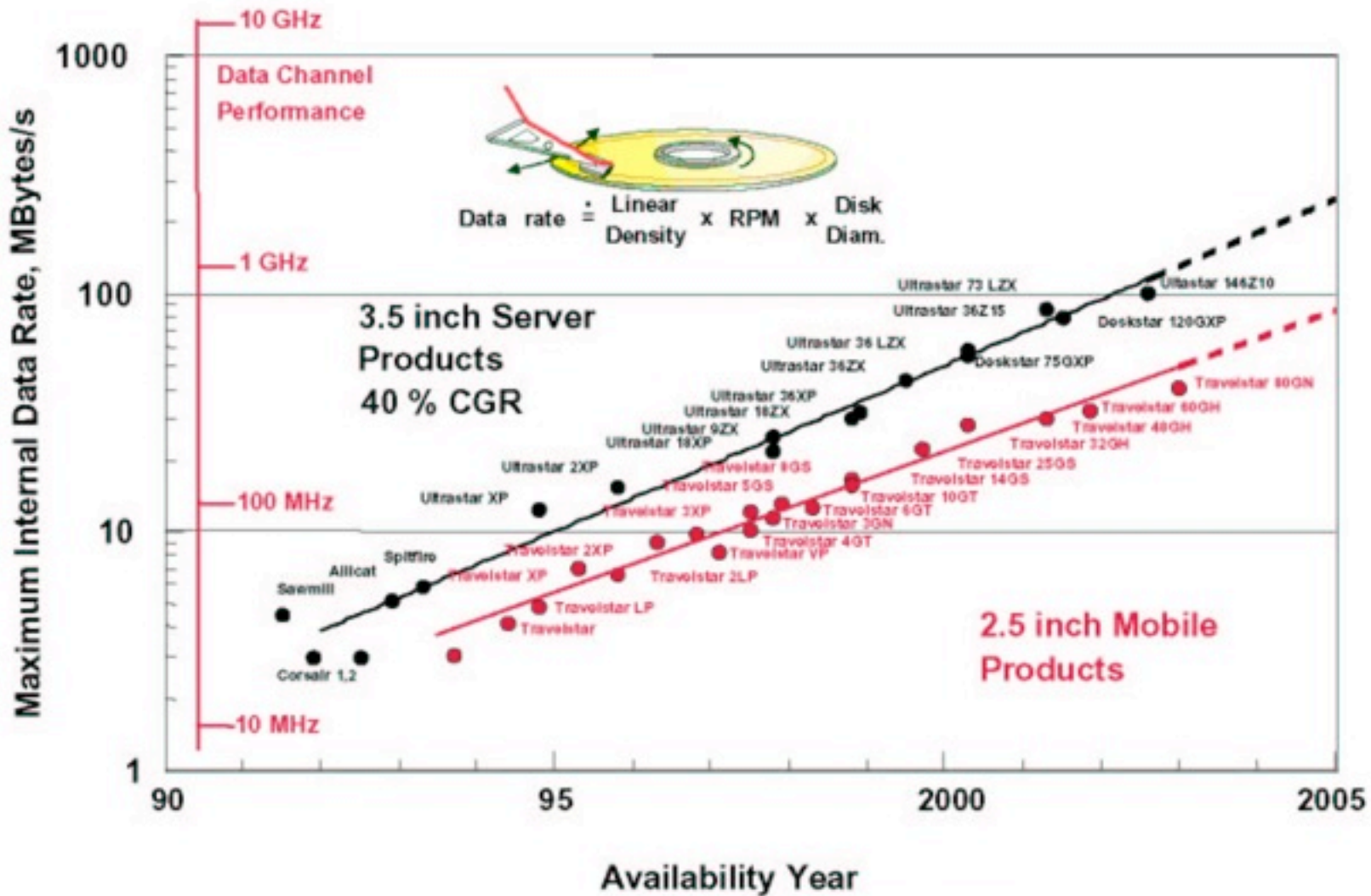


*far* higher than DRAM/SRAM (~nsec)  
reduction limited by mechanics!

E. Grochowski and R.D. Halem  
*IBM Systems Journal*, **42** (2), 2003

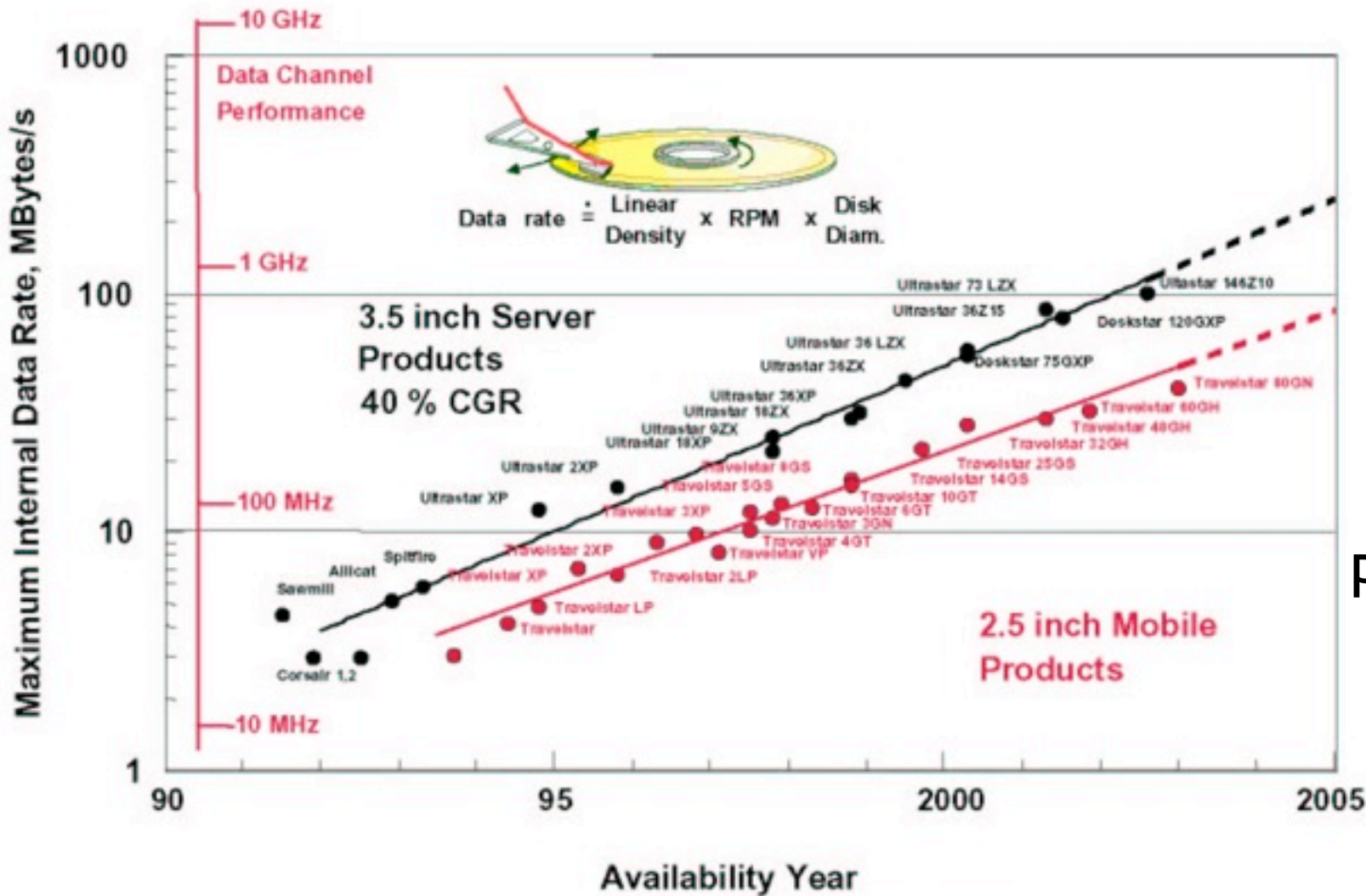
# throughput

Magnetic Hard Disk Drive Internal Data Rate



# throughput

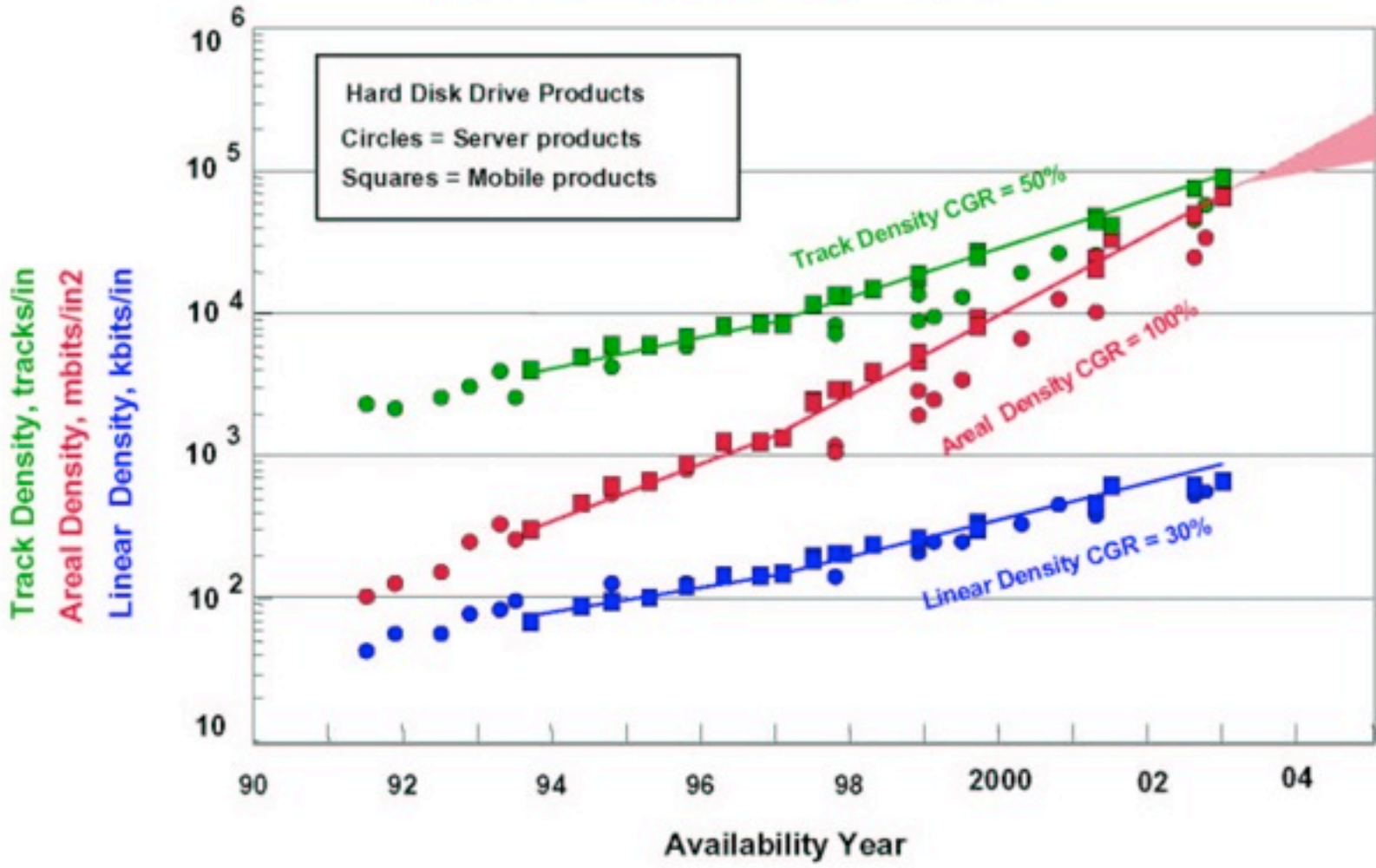
Magnetic Hard Disk Drive Internal Data Rate





# density metrics

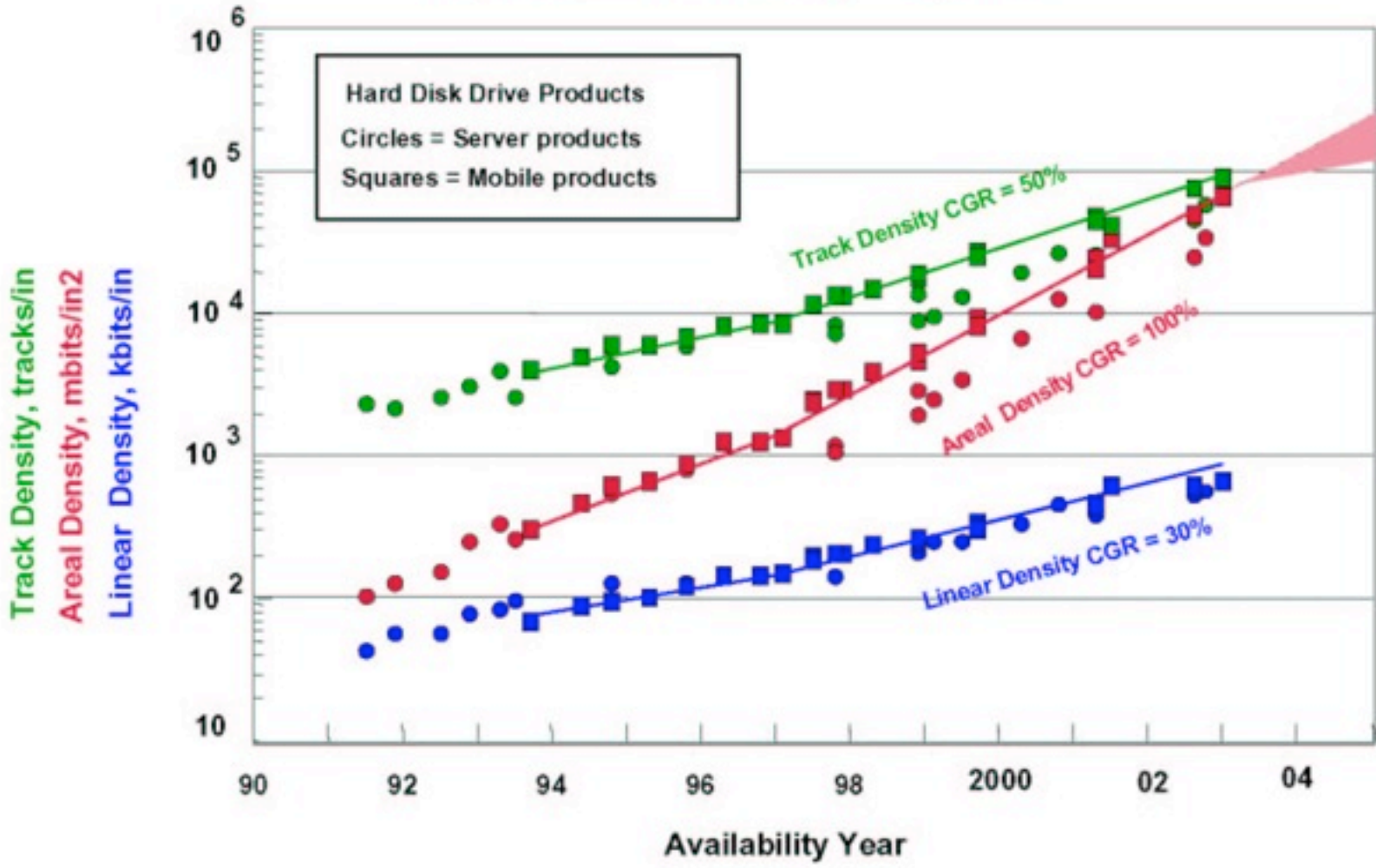
Track, Areal, Linear Density Perspective



Ed Grochowski

# density metrics

Track, Areal, Linear Density Perspective

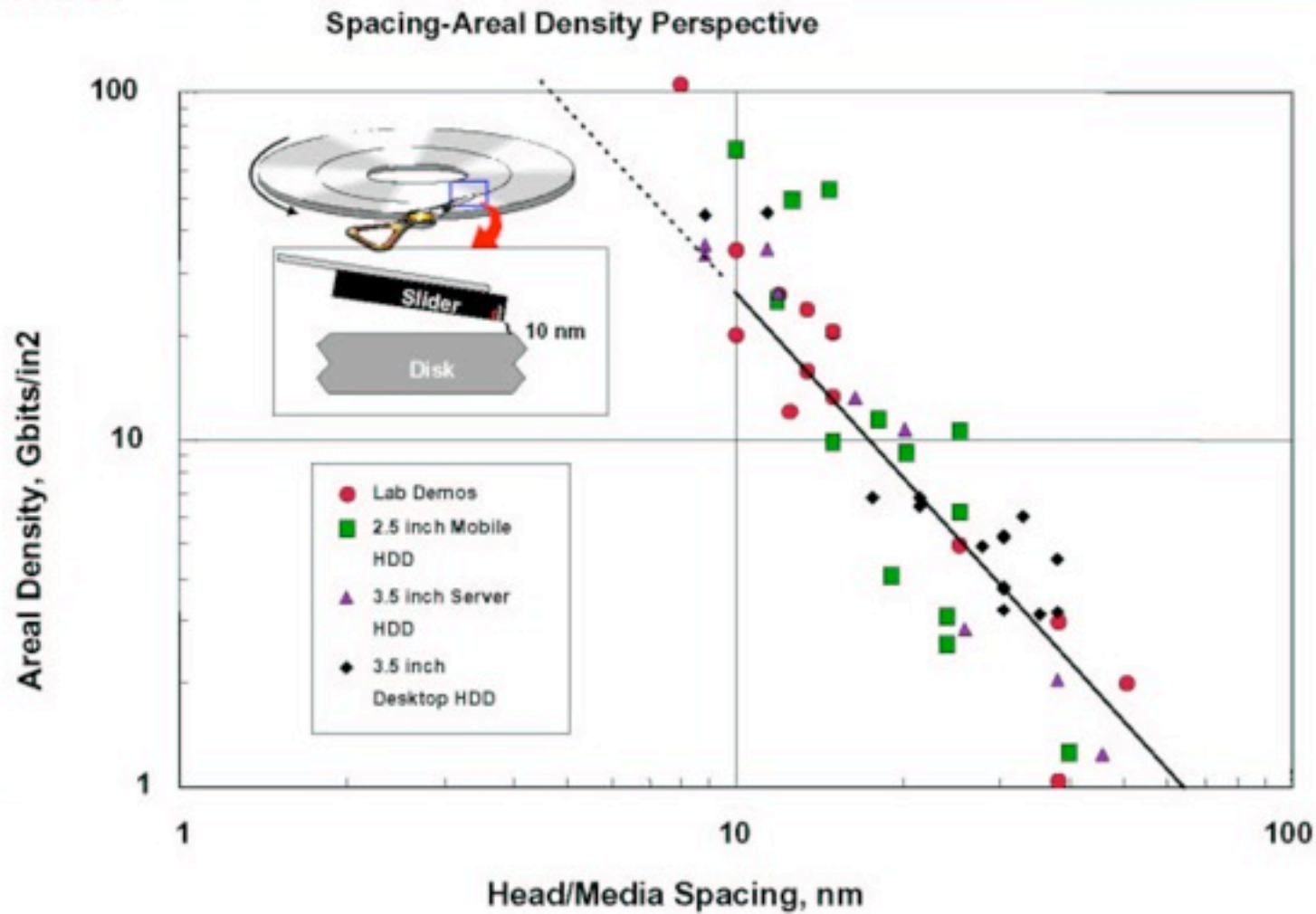


this is why we quote areal density.

Ed Grochowski

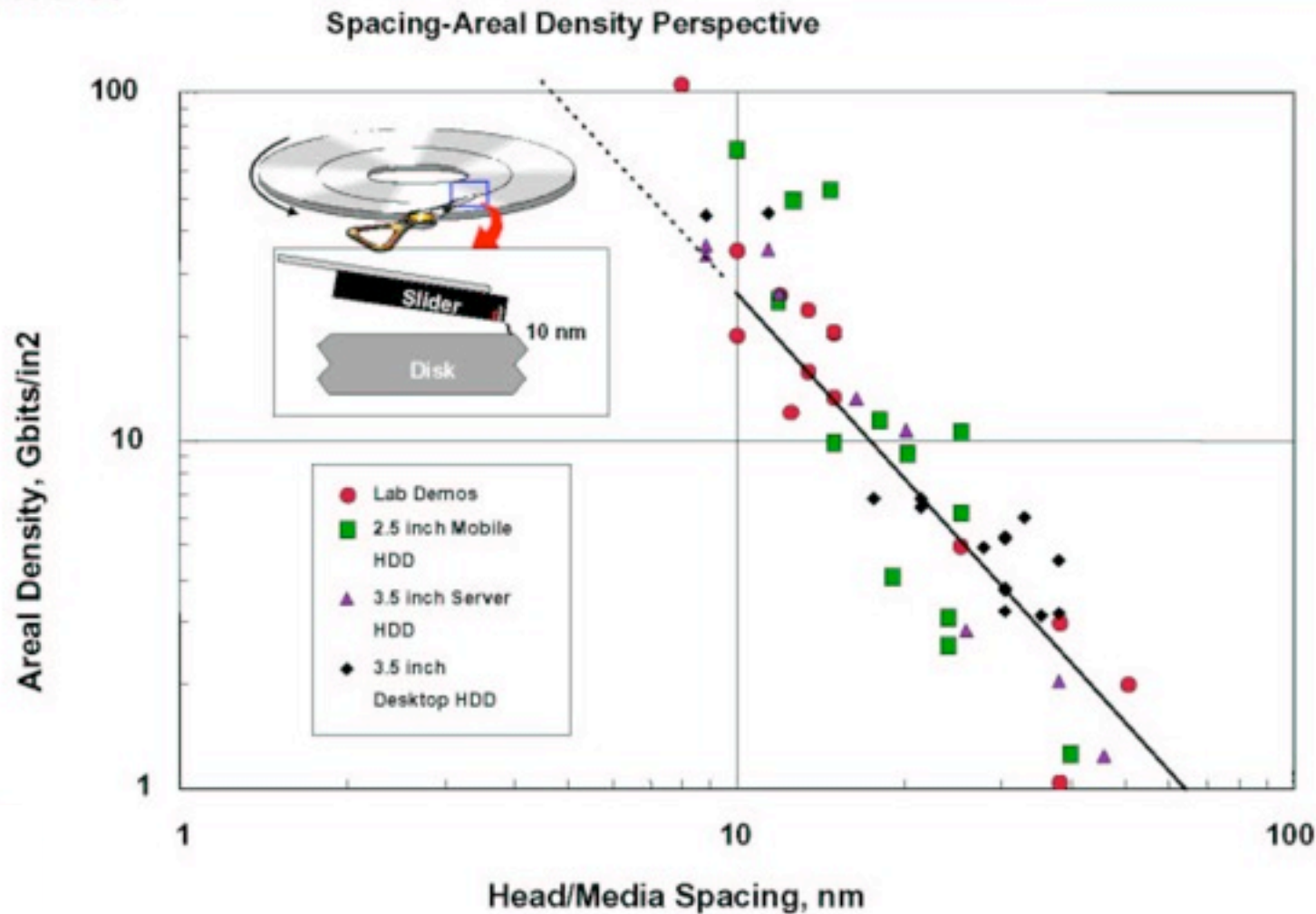


# head-media spacing



Ed Grochowski

# head-media spacing

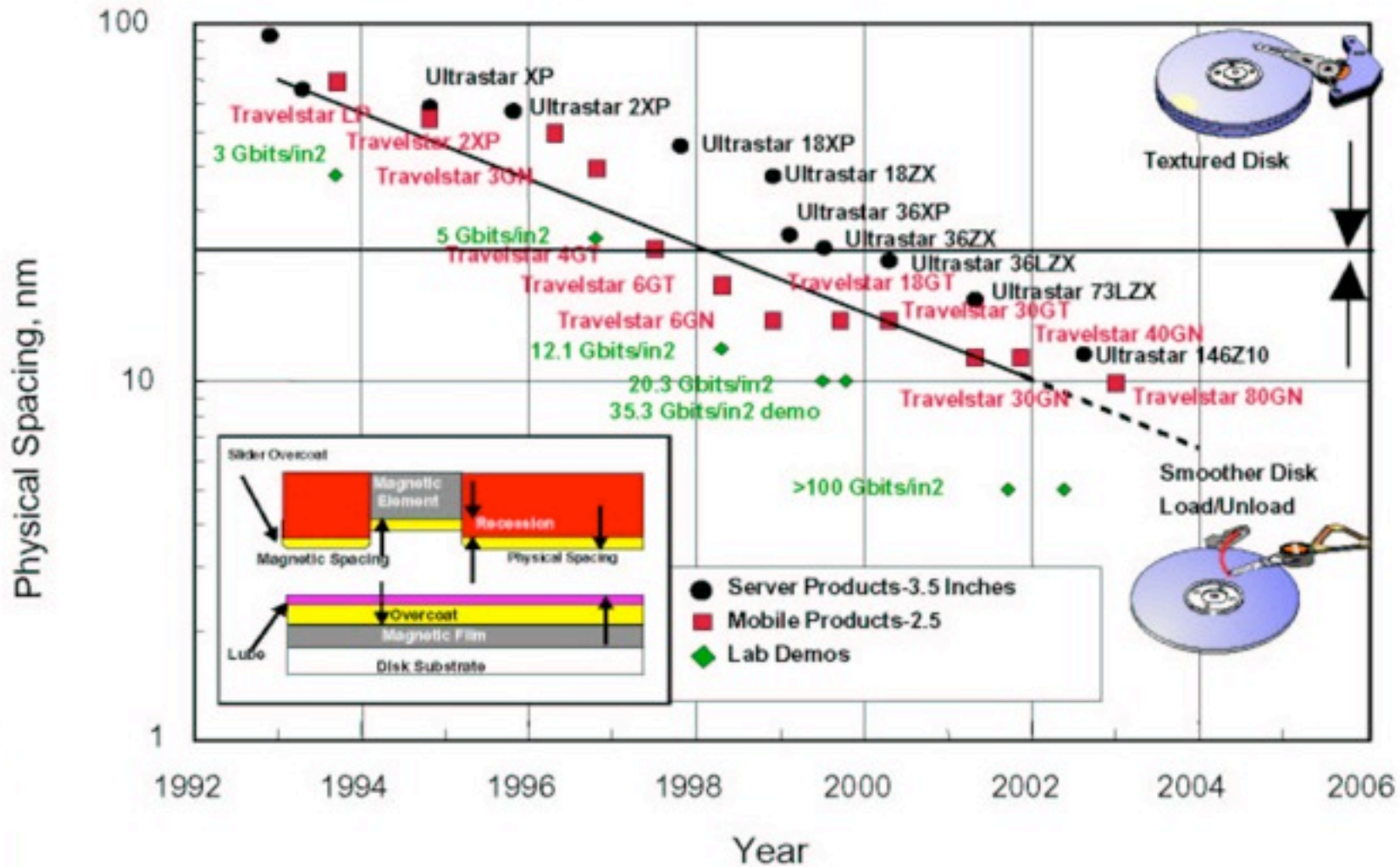


Ed Grochowski

tribology ...  
we are basically  
in contact

# physical spacing

Physical spacing and disk surface evolution



Ed Grochowski

# competition?

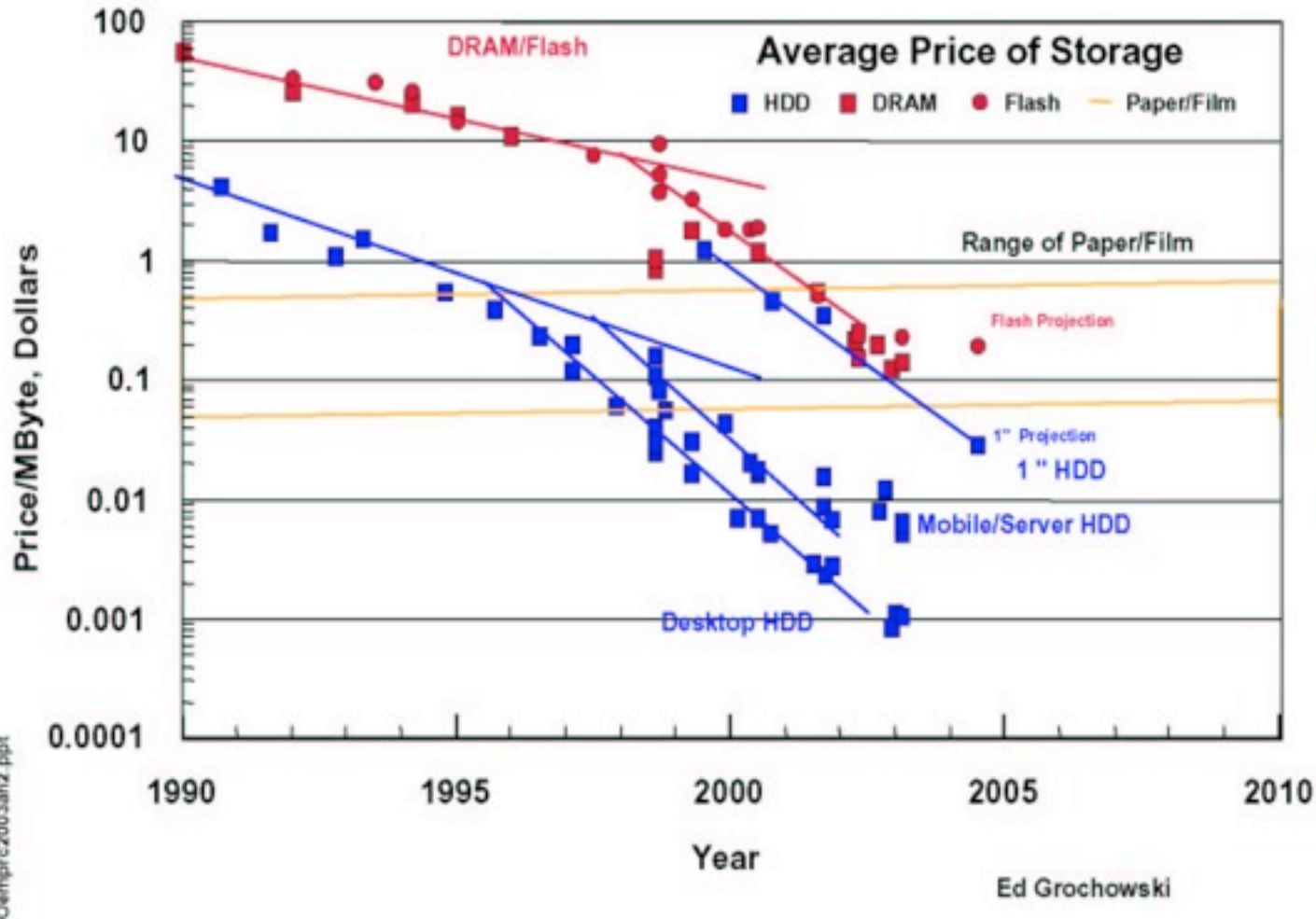
	SRAM	DRAM	Flash	FeRAM	MRAM	PCRAM
Read speed	Fastest	Medium	Fast	Fast	Fast	Fast
Write speed	Fastest	Medium	Slow	Medium	Fast	<b>Medium</b>
Array efficiency	High	High	Medium/low	Medium	Medium/high	Medium/high
Future scalability	Good	Limited	Limited	Limited	Good	Good
Cell density	Low	High	High	Medium	Medium/high	Medium/high
<b>Nonvolatility</b>	No	No	<b>Yes</b>	<b>Yes</b>	<b>Yes</b>	<b>Yes</b>
Endurance	Infinite	Infinite	Limited	Limited	Infinite	Infinite
Cell leakage	Increasing	High	Low	Low	Low	Low
Low voltage	Yes	Limited	Limited	Limited	Yes	Yes
Complexity	Low	Medium	Medium	Medium	Medium	Medium



# competition?

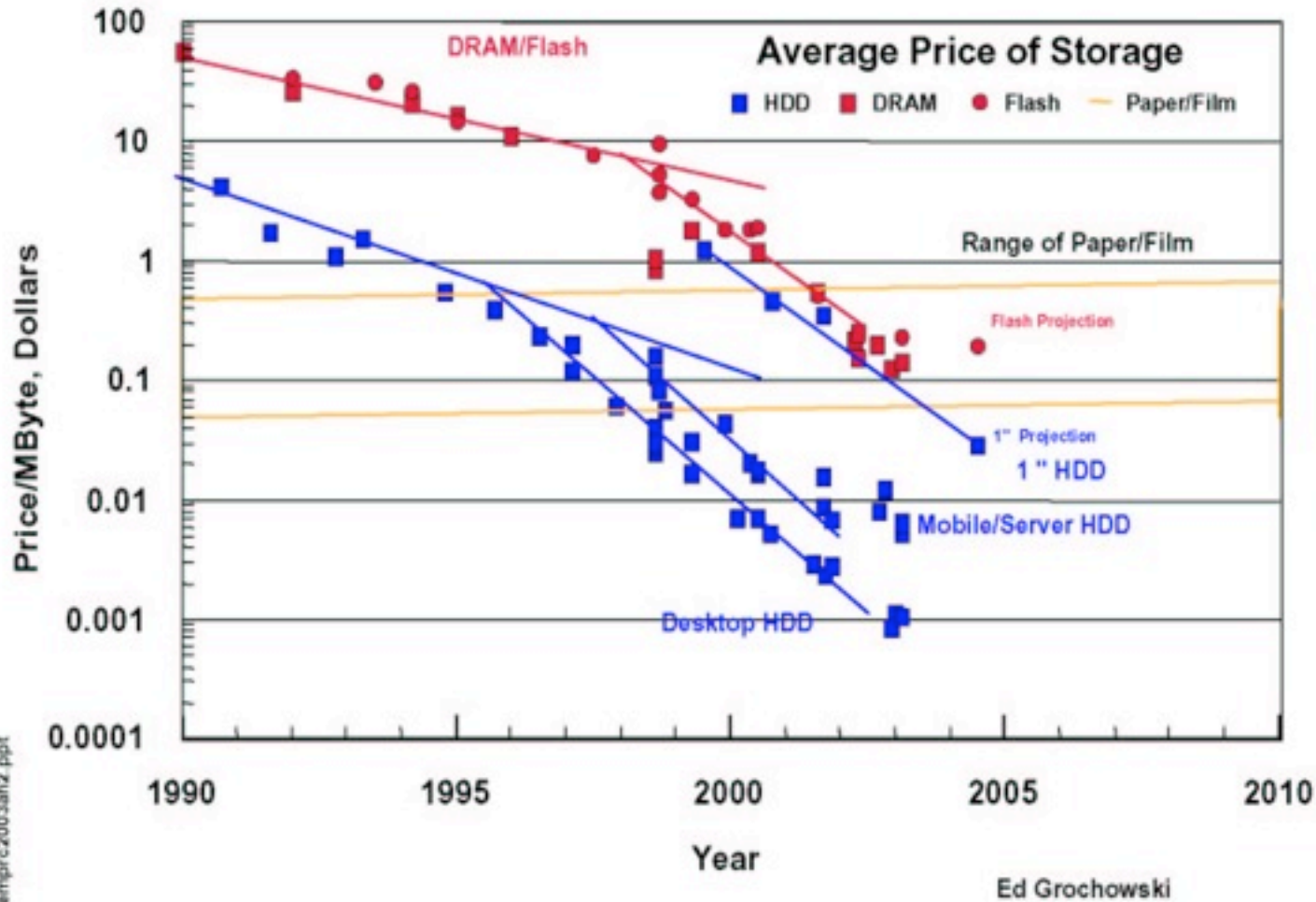
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# price is the real advantage.



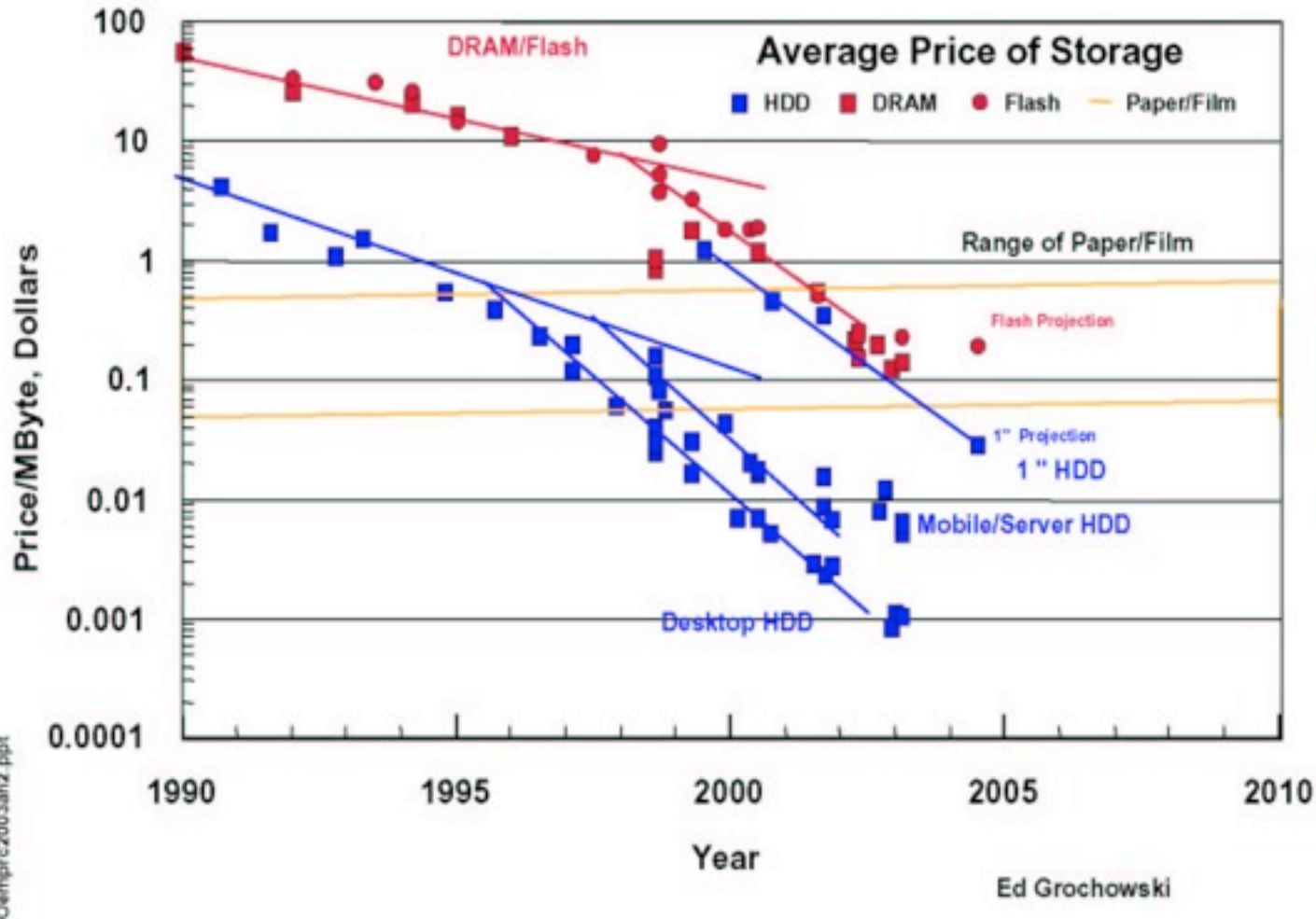


# price is the real advantage.



flash is beating the 1" HDD in some apps  
e.g., mp3, camera

# price is the real advantage.



flash is beating the 1" HDD in some apps

e.g., mp3, camera

*power consumption may be the larger issue*

---

power consumption is not an advantage

latency ...

fundamental limits of magnetism?

---

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more importantly ...

---

power consumption is not an advantage

latency ...

fundamental limits of magnetism?

more importantly ...

will we get “scooped” like bubbles?

---

**SO!**

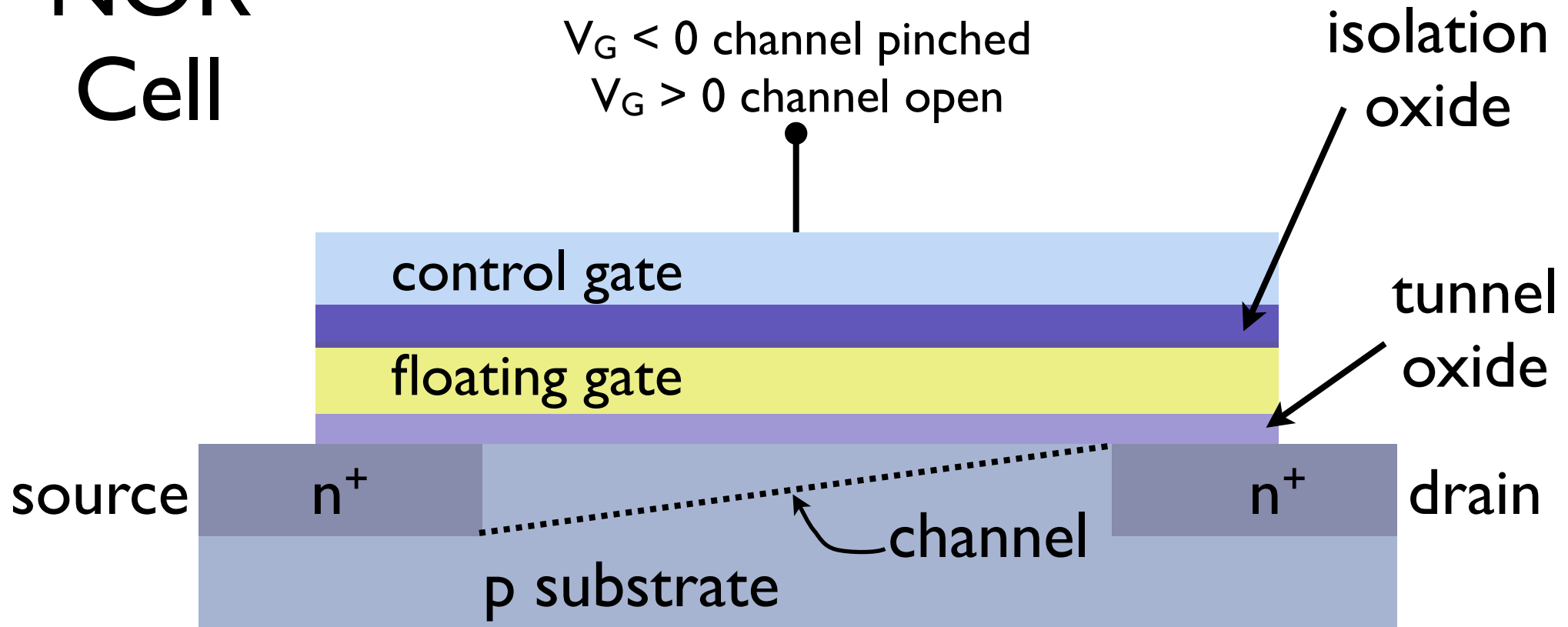
**what about the competition?**

**how does flash work?**



# the basics of Flash

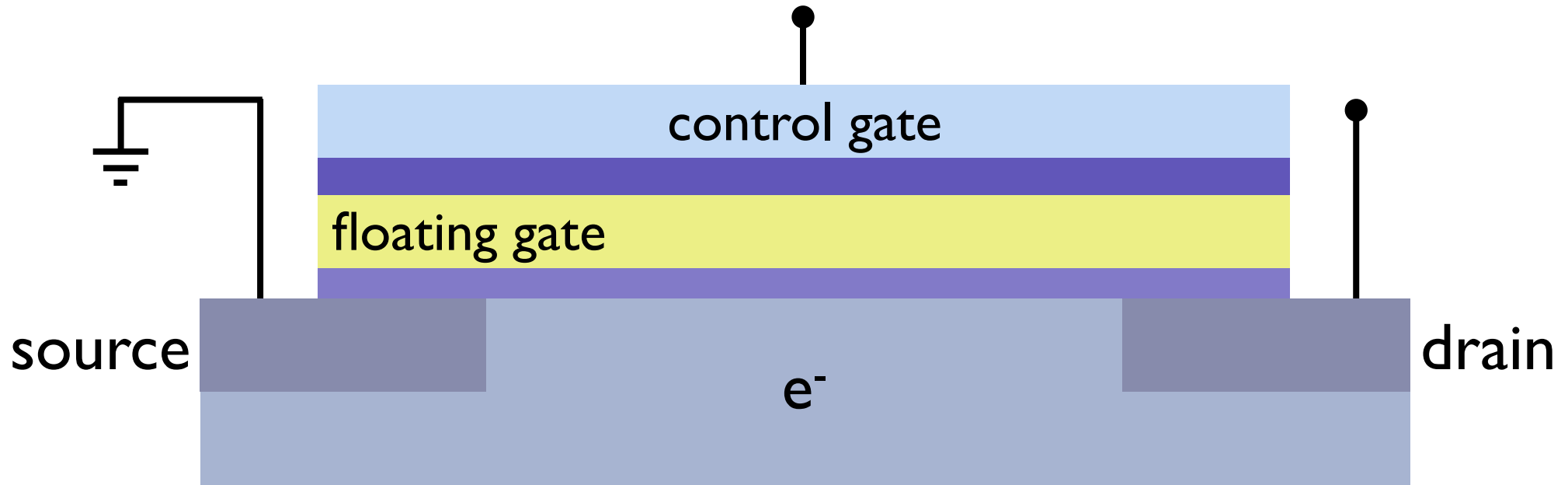
## NOR Cell



- like a MOSFET
- uses 2 gates

# writing

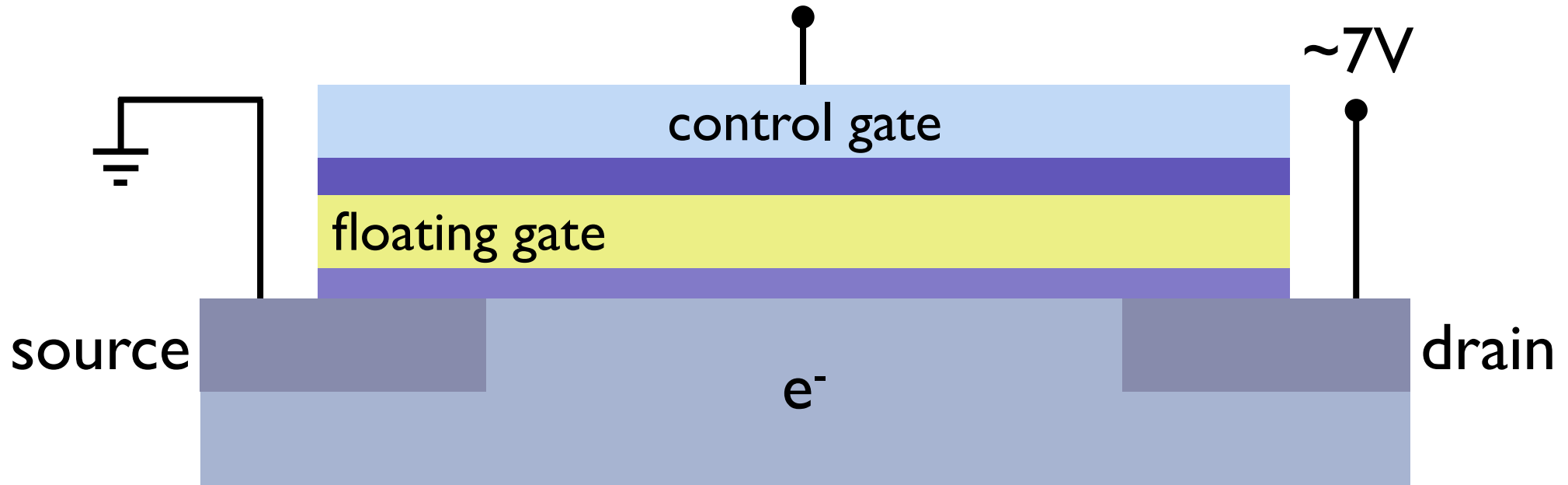
“hot electron injection”



- ~7V to drain  
pull  $e^-$  through channel
- ~12V to control gate / open channel  
injects  $e^-$  into floating gate through tunnel oxide
- floating gate now charged

# writing

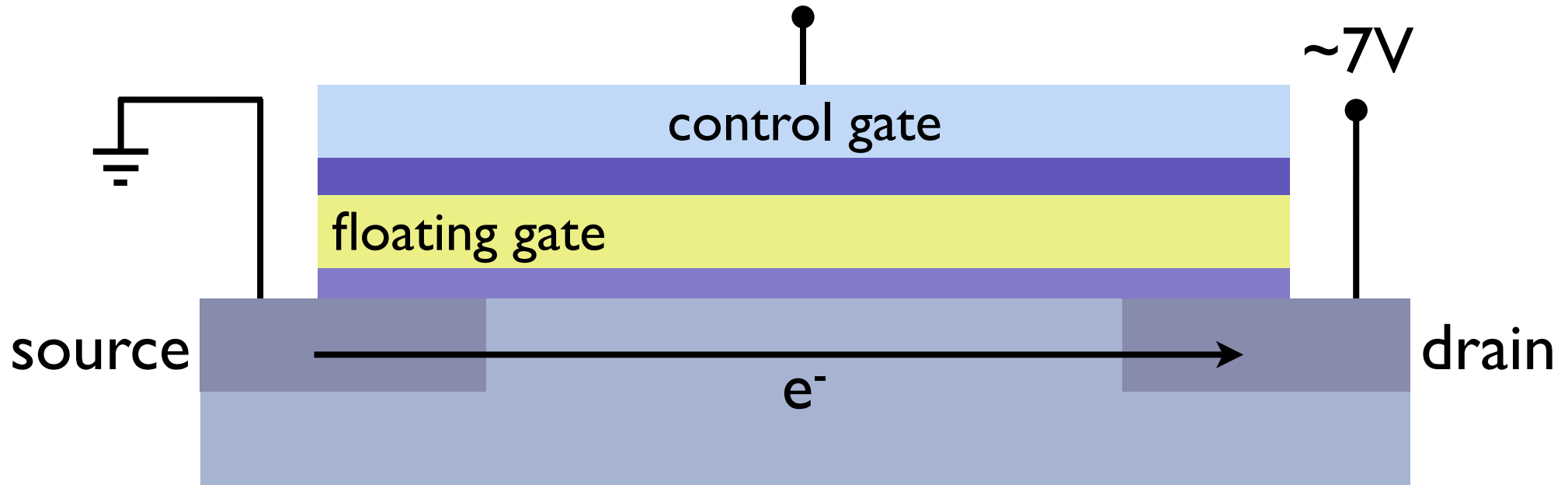
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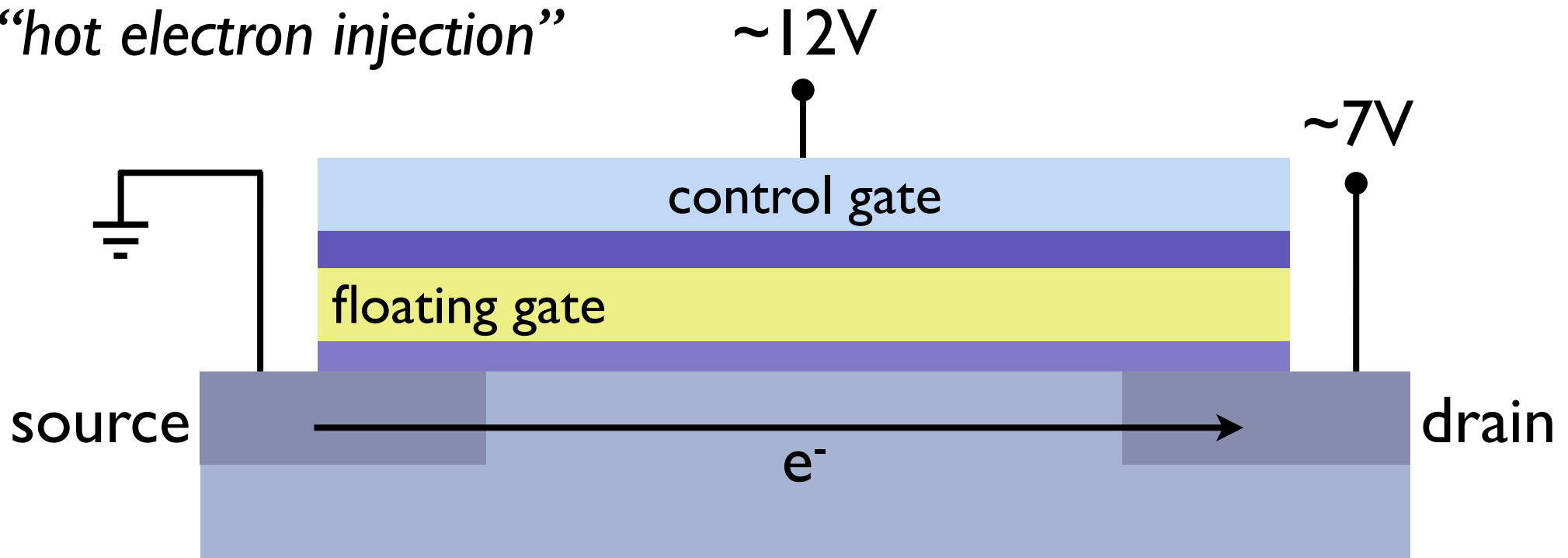
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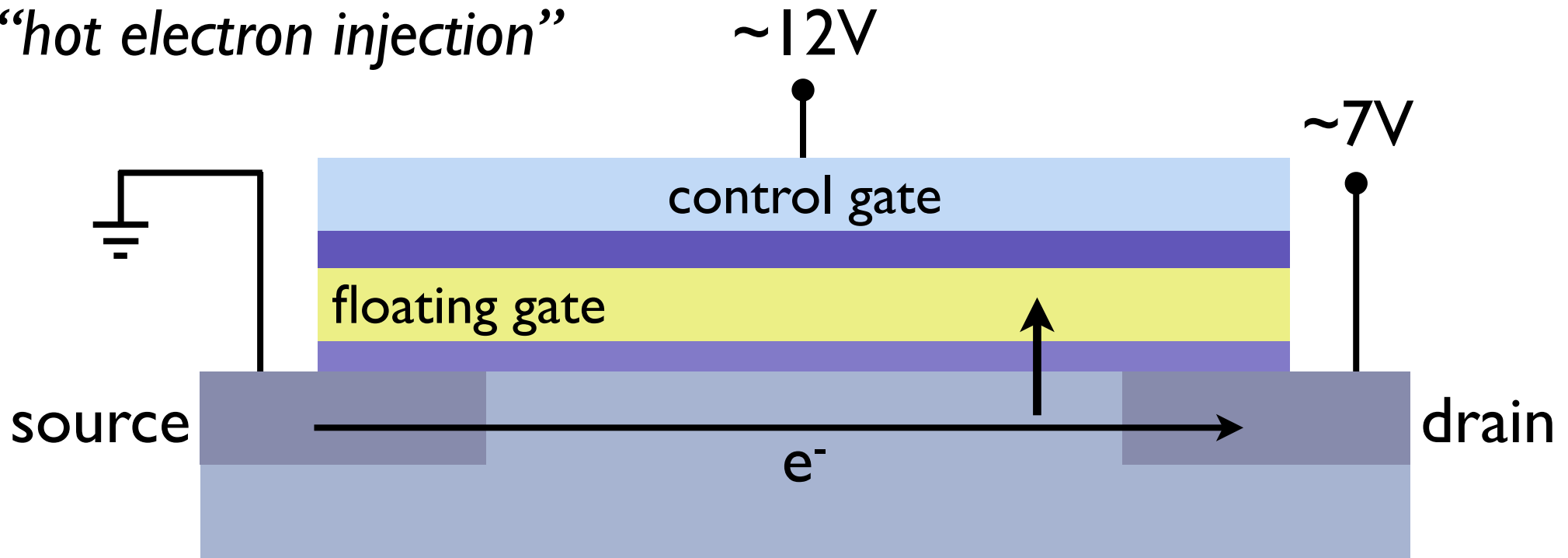
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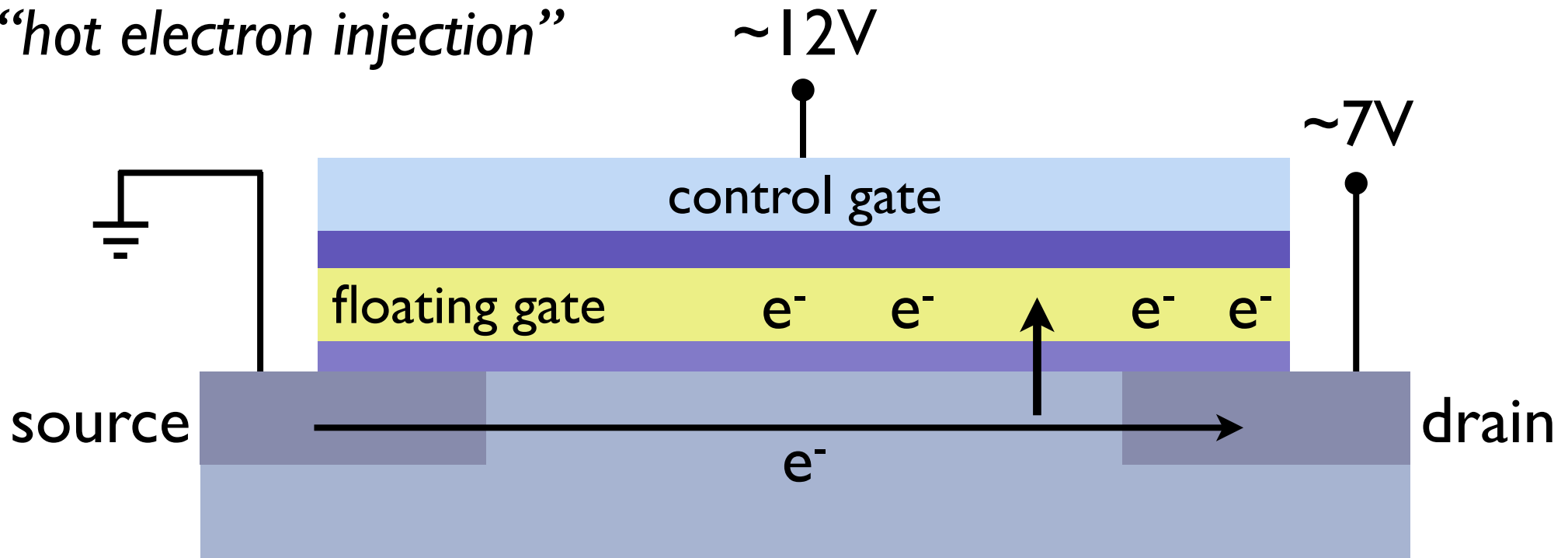


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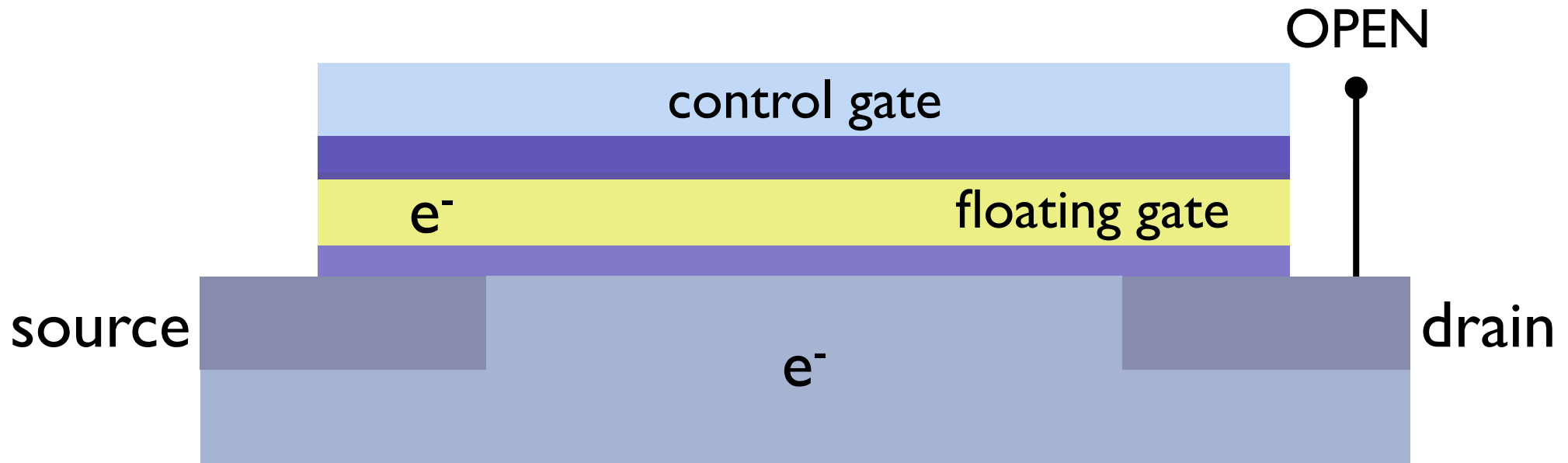
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# erasing

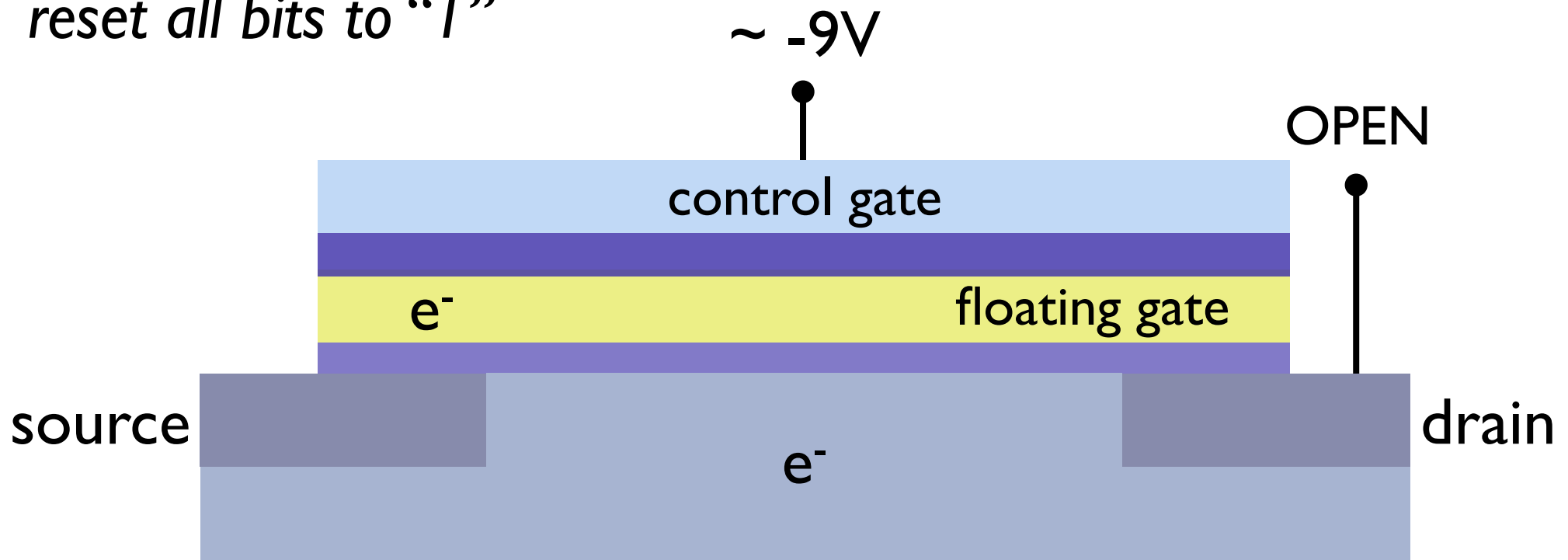
*reset all bits to "1"*



- -9V to control  
pinch off channel
- ~6V to source
- suck electrons out of floating gate into source  
Fowler-Nordheim tunneling

# erasing

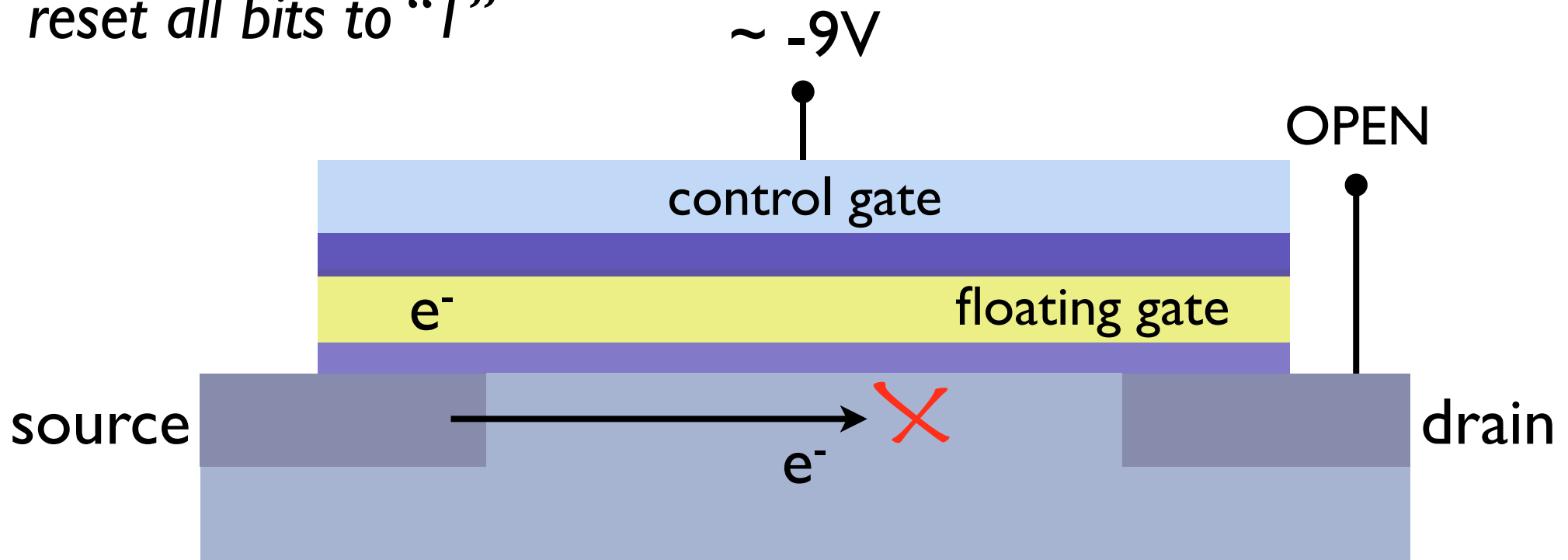
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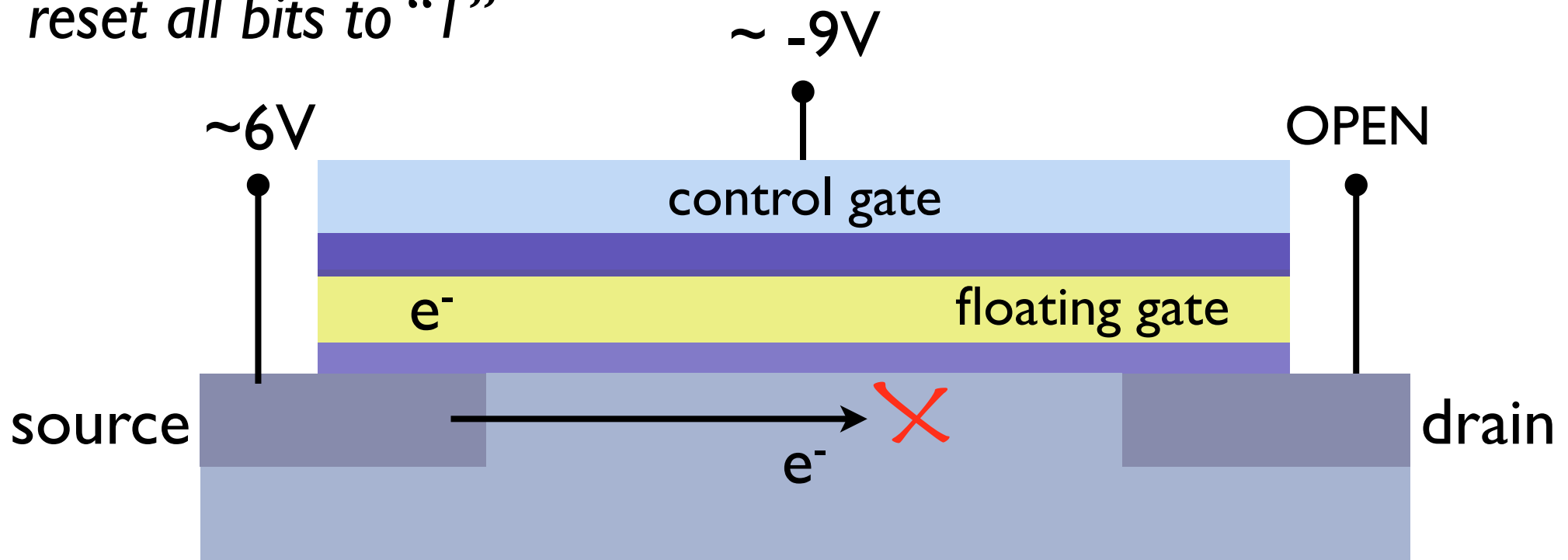
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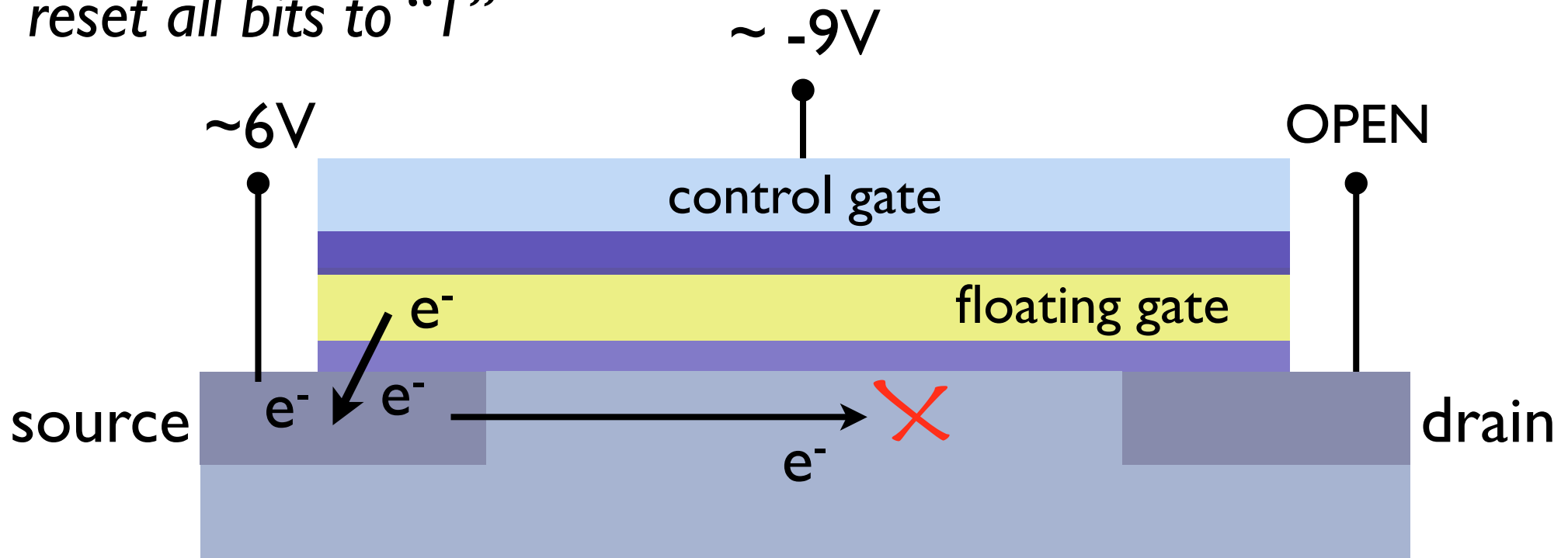
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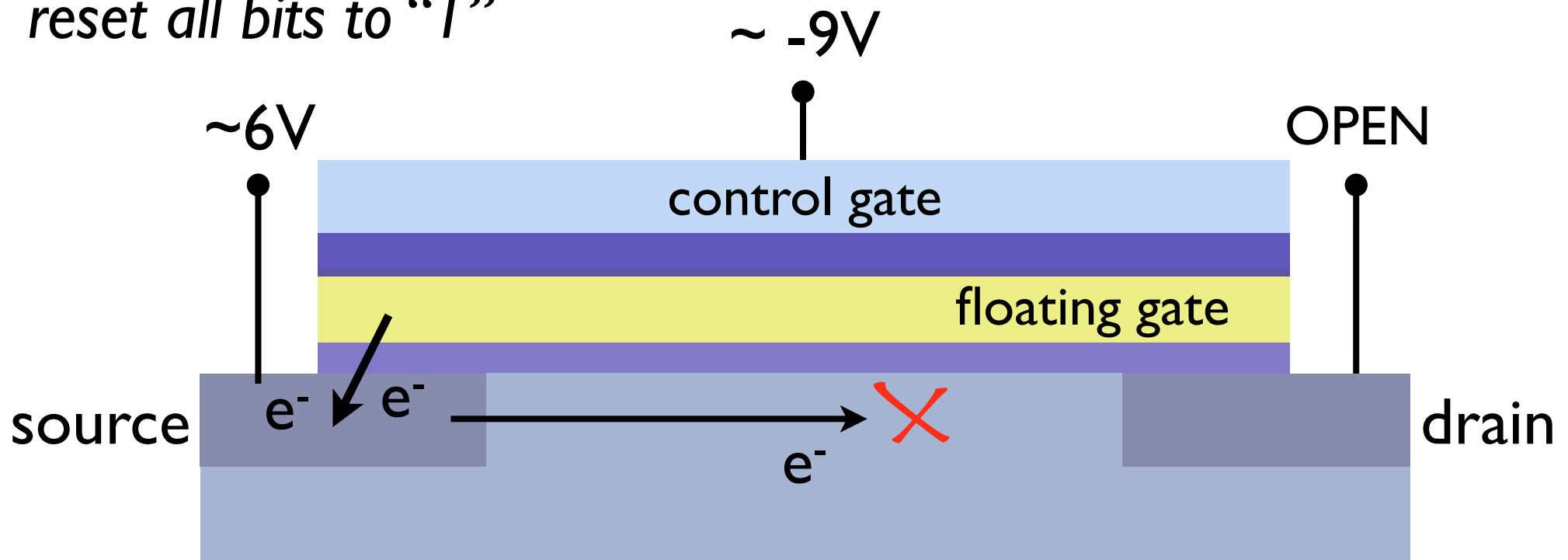


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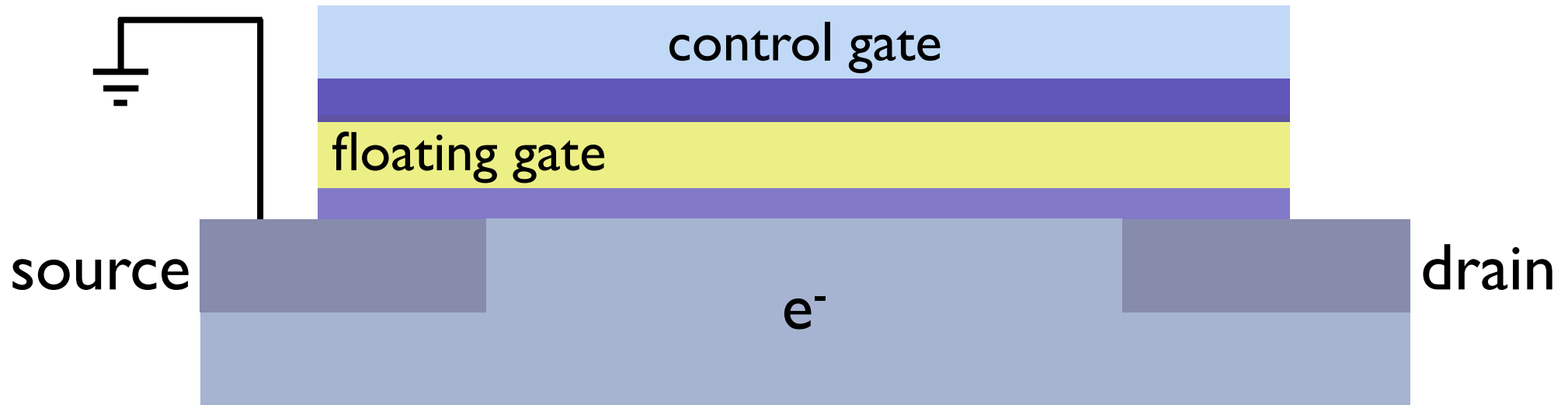
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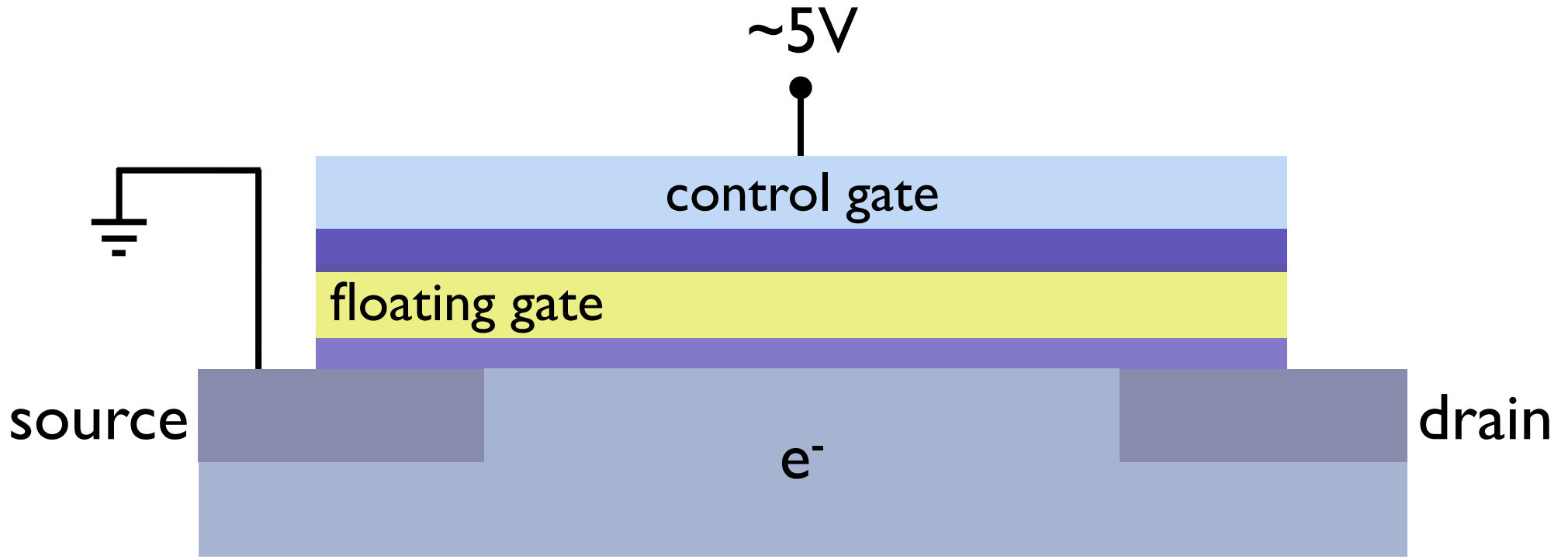
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presence of charge modulates  $I_{SD}$  !

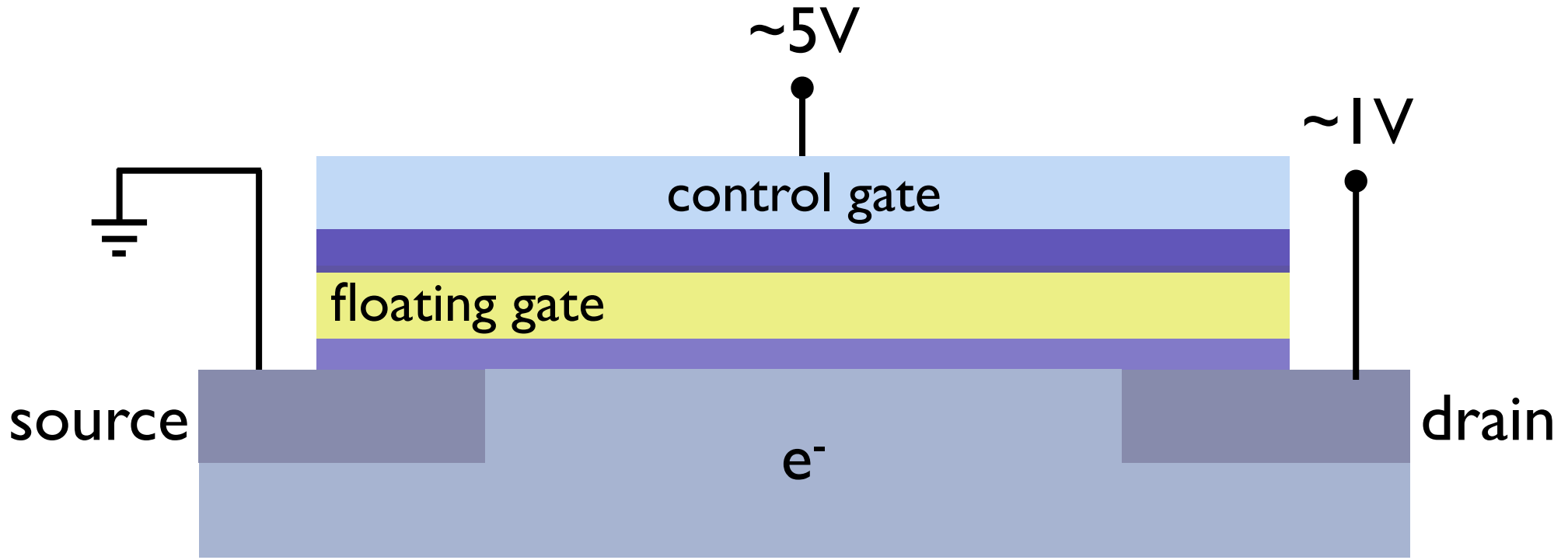
# reading

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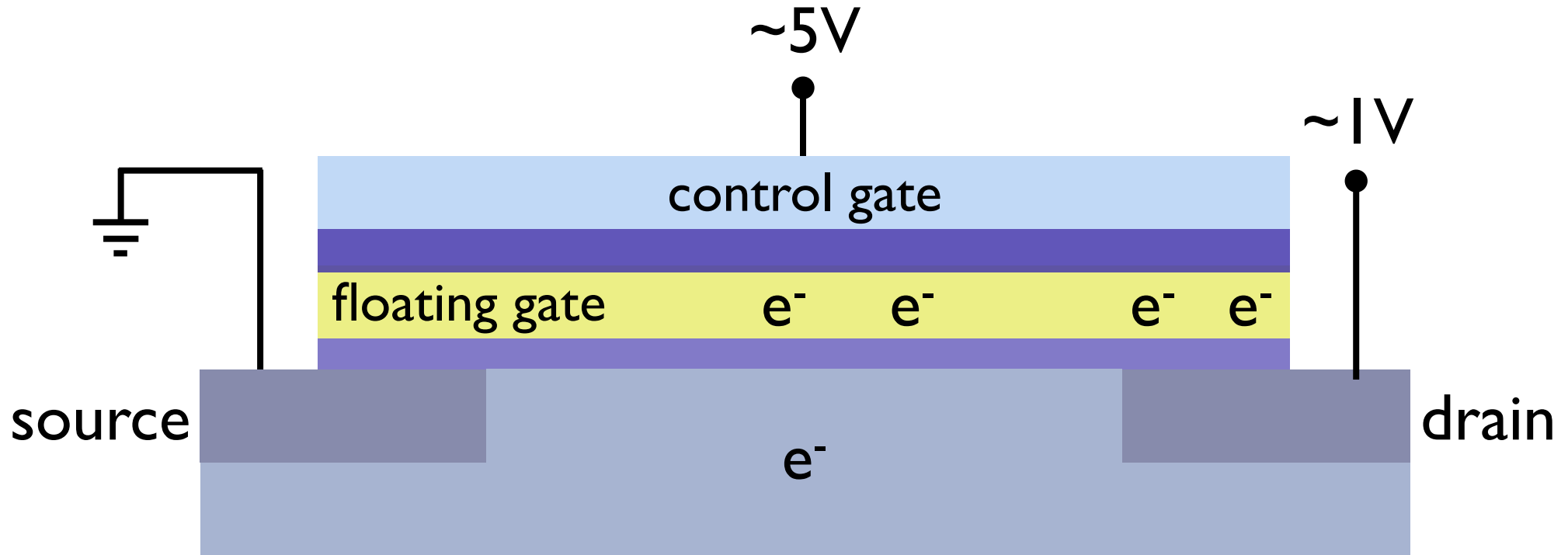
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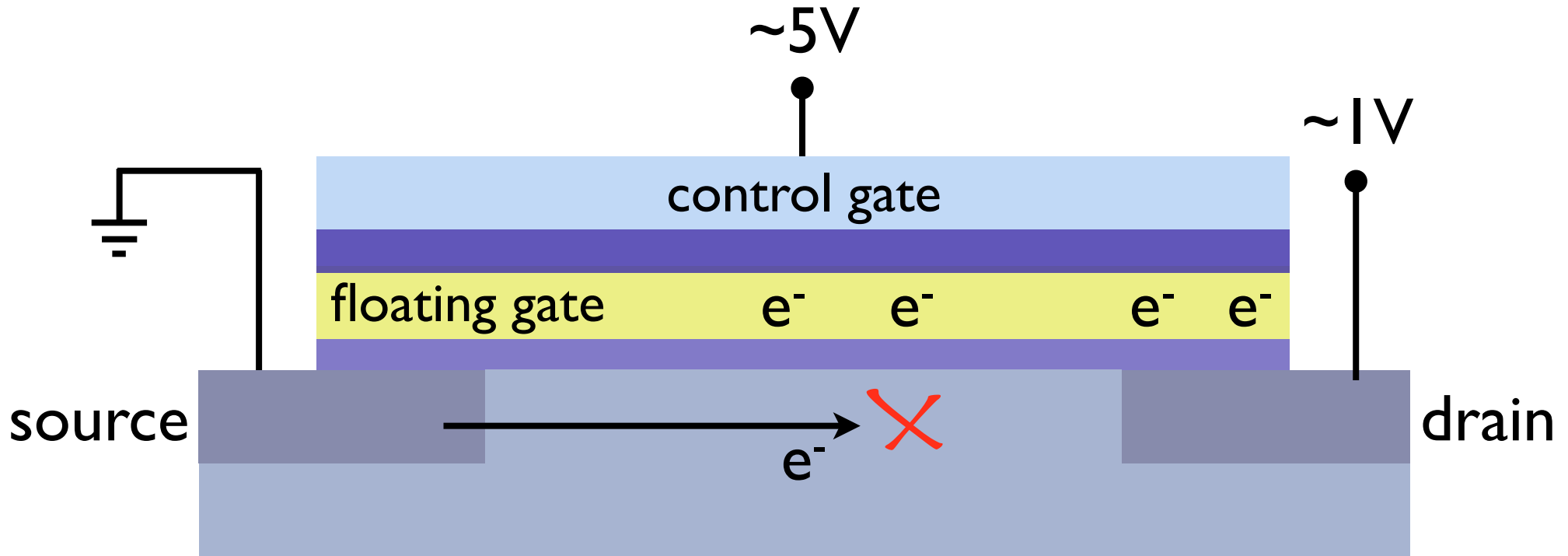
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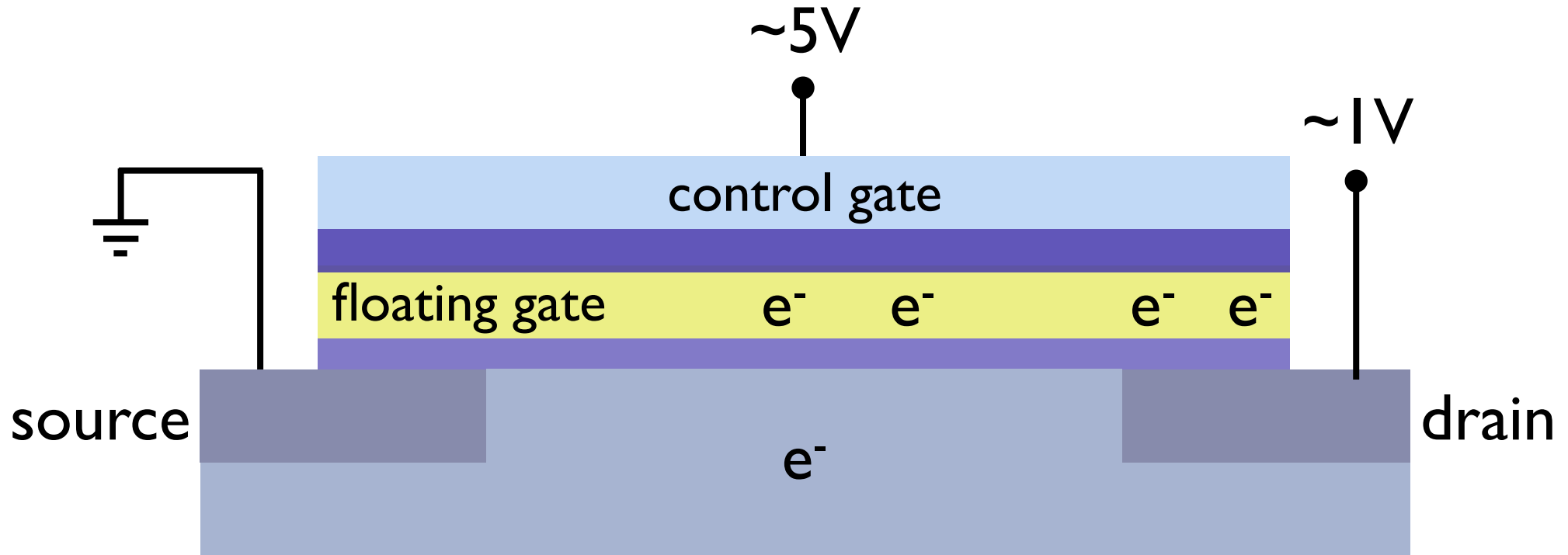
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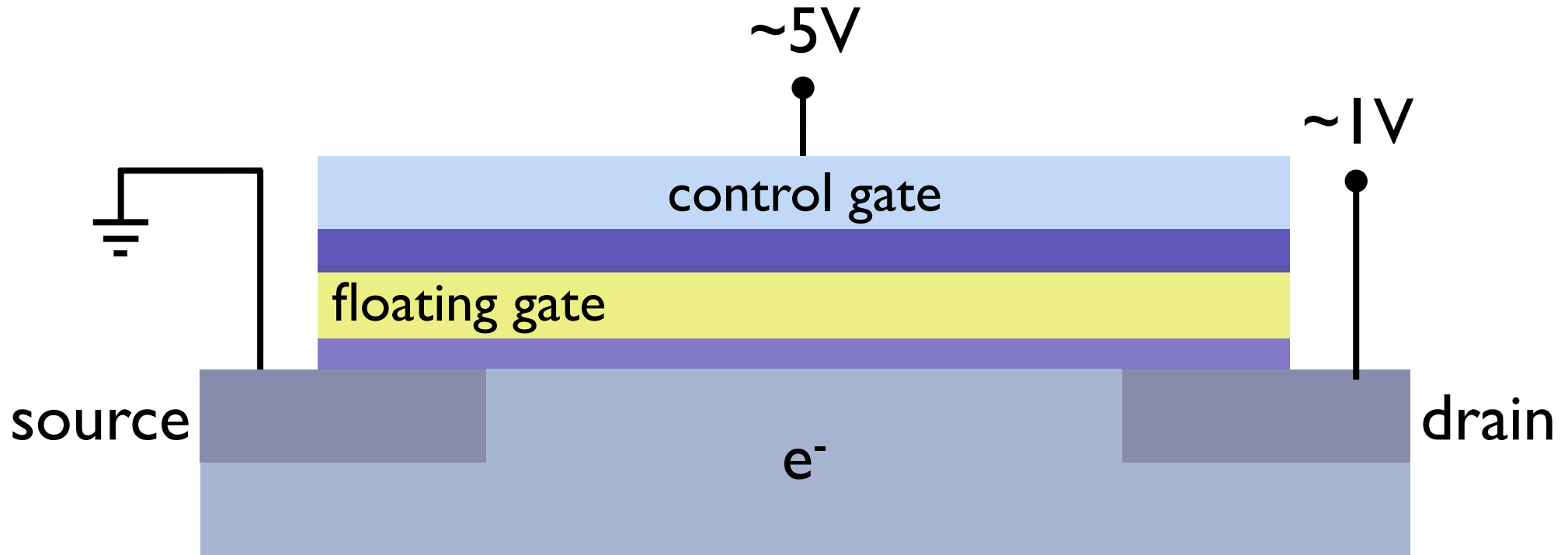


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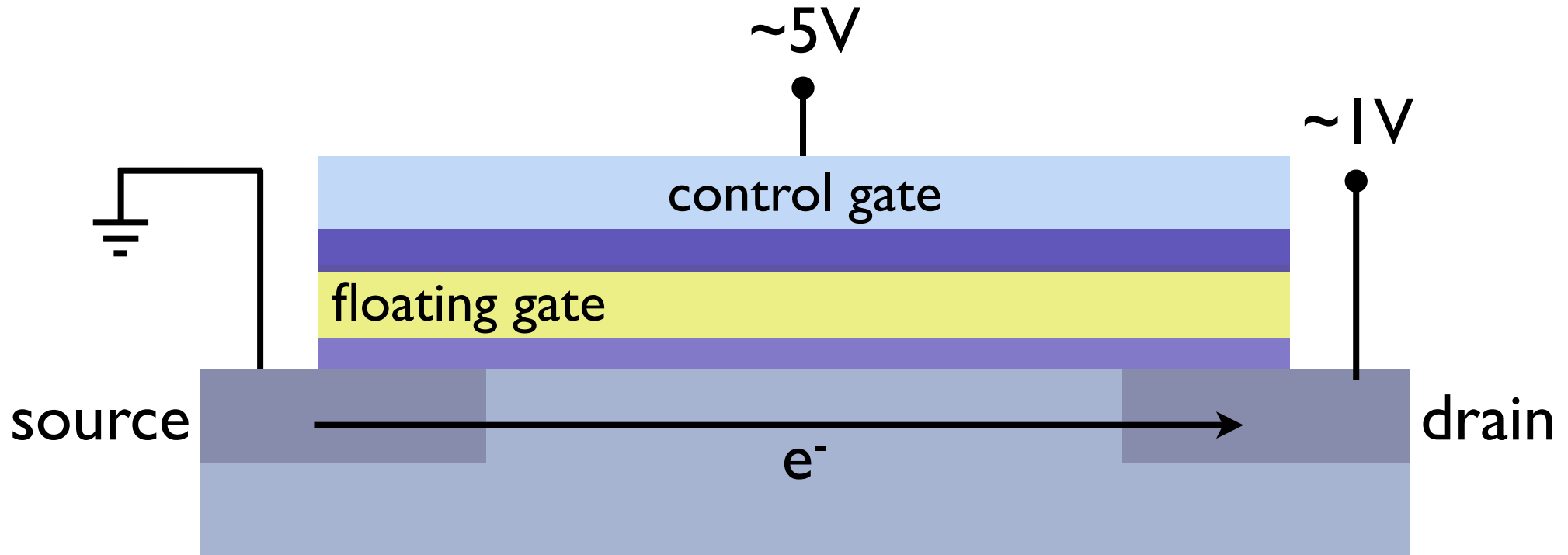
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- + no mechanical limitations
- + lower latency
  - = attractive for speed, noise, power consumption, reliability.

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- + no mechanical limitations
- + lower latency
  - = attractive for speed, noise, power consumption, reliability.
- cost/GB still significantly higher (but decreasing rapidly!)
- finite number of erase/write (typically  $10^6$  cycles guaranteed)
  - unable to support an OS (swap!)
  - warranties on flash-based disks trending  $\geq$  HDD*



# Transcript

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<http://bama.ua.edu/~pleclair/PH587/>

PDF version of these slides